ETSITS 138 101-2 V16.15.0 (2023-04)



5G; NR;

User Equipment (UE) radio transmission and reception; Part 2: Range 2 Standalone (3GPP TS 38.101-2 version 16.15.0 Release 16)



Reference
RTS/TSGR-0438101-2vgf0

Keywords
5G

ETSI

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Foreword

This Technical Specification has been produced by the 3rd Generation Partnership Project (3GPP).

The contents of the present document are subject to continuing work within the TSG and may change following formal TSG approval. Should the TSG modify the contents of the present document, it will be re-released by the TSG with an identifying change of release date and an increase in version number as follows:

Version x.y.z

where:

- x the first digit:
 - 1 presented to TSG for information;
 - 2 presented to TSG for approval;
 - 3 or greater indicates TSG approved document under change control.
- y the second digit is incremented for all changes of substance, i.e. technical enhancements, corrections, updates, etc.
- z the third digit is incremented when editorial only changes have been incorporated in the document.

In the present document, modal verbs have the following meanings:

shall indicates a mandatory requirement to do somethingshall not indicates an interdiction (prohibition) to do something

The constructions "shall" and "shall not" are confined to the context of normative provisions, and do not appear in Technical Reports.

The constructions "must" and "must not" are not used as substitutes for "shall" and "shall not". Their use is avoided insofar as possible, and they are not used in a normative context except in a direct citation from an external, referenced, non-3GPP document, or so as to maintain continuity of style when extending or modifying the provisions of such a referenced document.

should indicates a recommendation to do something

should not indicates a recommendation not to do something

may indicates permission to do something

need not indicates permission not to do something

The construction "may not" is ambiguous and is not used in normative elements. The unambiguous constructions "might not" or "shall not" are used instead, depending upon the meaning intended.

can indicates that something is possiblecannot indicates that something is impossible

The constructions "can" and "cannot" are not substitutes for "may" and "need not".

will indicates that something is certain or expected to happen as a result of action taken by an agency

the behaviour of which is outside the scope of the present document

will not indicates that something is certain or expected not to happen as a result of action taken by an

agency the behaviour of which is outside the scope of the present document

might indicates a likelihood that something will happen as a result of action taken by some agency the

behaviour of which is outside the scope of the present document

might not indicates a likelihood that something will not happen as a result of action taken by some agency

the behaviour of which is outside the scope of the present document

In addition:

is (or any other verb in the indicative mood) indicates a statement of fact

is not (or any other negative verb in the indicative mood) indicates a statement of fact

The constructions "is" and "is not" do not indicate requirements.

1 Scope

[14]

[15]

The present document establishes the minimum RF requirements for NR User Equipment (UE) operating on frequency Range 2.

2 References

The following documents contain provisions which, through reference in this text, constitute provisions of the present document.

- References are either specific (identified by date of publication, edition number, version number, etc.) or non-specific.
- For a specific reference, subsequent revisions do not apply.
- For a non-specific reference, the latest version applies. In the case of a reference to a 3GPP document (including a GSM document), a non-specific reference implicitly refers to the latest version of that document *in the same Release as the present document*.
- [1] 3GPP TR 21.905: "Vocabulary for 3GPP Specifications". [2] 3GPP TS 38.101-1: "NR; User Equipment (UE) radio transmission and reception; Part 1: Range 1 Standalone" 3GPP TS 38.101-3: "NR; User Equipment (UE) radio transmission and reception; Part 3: Range 1 [3] and Range 2 Interworking operation with other radios" [4] Void 3GPP TS 38.521-2: "NR; User Equipment (UE) conformance specification; Radio transmission [5] and reception; Part 2: Range 2 Standalone" Recommendation ITU-R M.1545: "Measurement uncertainty as it applies to test limits for the [6] terrestrial component of International Mobile Telecommunications-2000" ITU-R Recommendation SM.329-10, "Unwanted emissions in the spurious domain" [7] 47 CFR Part 30, "UPPER MICROWAVE FLEXIBLE USE SERVICE, §30.202 Power limits", [8] FCC. 3GPP TS 38.211: "NR; Physical channels and modulation". [9] 3GPP TS 38.213: "NR; Physical layer procedures for control". [10] 3GPP TS 38.215: "NR; Physical layer measurements". [11] [12] 3GPP TS 38.133: "NR; Requirements for support of radio resource management". 3GPP TS 38.331: "NR; Radio Resource Control (RRC); Protocol specification". [13]

3GPP TS 38.306: "NR; User Equipment (UE) radio access capabilities".

IEEE Std 149: "IEEE Standard Test Procedures for Antennas", IEEE.

3 Definitions, symbols and abbreviations

3.1 Definitions

For the purposes of the present document, the terms and definitions given in 3GPP TR 21.905 [1] and the following apply. A term defined in the present document takes precedence over the definition of the same term, if any, in 3GPP TR 21.905 [1].

Aggregated Channel Bandwidth: The RF bandwidth in which a UE is configured to transmit and receive multiple contiguously aggregated carriers.

Bidirectional spectrum: UL/DL common spectrum in which the UE supports the configuration of uplink or downlink CCs

Beam correspondence: the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping.

Carrier aggregation: Aggregation of two or more component carriers in order to support wider transmission bandwidths.

Carrier aggregation band: A set of one or more operating bands across which multiple carriers are aggregated with a specific set of technical requirements.

Carrier aggregation bandwidth class: A class defined by the aggregated transmission bandwidth configuration and maximum number of component carriers supported by a UE.

Carrier aggregation configuration: A combination of CA operating band(s) and CA bandwidth class(es) supported by a UE.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

Cumulative aggregated channel bandwidth: The cumulative aggregated channel bandwidth is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs inside the bidirectional spectrum of the UE.

EIRP(Link=Link angle, Meas=Link angle): measurement of the UE such that the link angle is aligned with the measurement angle. EIRP (indicator to be measured) can be replaced by EIS, Frequency, EVM, carrier Leakage, Inband eission and OBW.

EIRP(Link=TX beam peak direction, Meas=Link angle): measurement of the EIRP of the UE such that the measurement angle is aligned with the beam peak direction within an acceptable measurement error uncertainty. EIRP (indicator to be measured) can be replaced by Frequency, EVM, carrier Leakage, In-band eission and OBW

EIRP(Link=Spherical coverage grid, Meas=Link angle): measurement of the EIRP spherical coverage of the UE such that the EIRP link and measurement angles are aligned with the directions along the spherical coverage grid within an acceptable measurement error uncertainty. Alternatively, the spherical coverage grid can be replaced by the beam peak search grid as the results from the beam peak search can be re-used for spherical coverage.

EIS (effective isotropic sensitivity): sensitivity for an isotropic directivity device equivalent to the sensitivity of the discussed device exposed to an incoming wave from a defined AoA

EIS(Link=RX beam peak direction, Meas=Link angle): measurement of the EIS of the UE such that the measurement angle is aligned with the RX beam peak direction within an acceptable measurement error uncertainty.

NOTE 1: The sensitivity is the minimum received power level at which specific requirement is met.

NOTE 2: Isotropic directivity is equal in all directions (i.e. 0 dBi).

Fallback group: Group of carrier aggregation bandwidth classes for which it is mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration. It is not mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration that belong to a different fallback group.

FWA UE: A UE intended to be used in fixed wireless access scenario.

Handheld UE: A UE intended to be used in hand held scenario.

IBM (**Independent Beam Management**): A UE that supports inter-band CA with IBM selects its DL Rx beam(s) for all CCs in each configured band based on DL reference signals measurements made in that band.

Inter-band carrier aggregation: Carrier aggregation of component carriers in different operating bands.

NOTE: Carriers aggregated in each band can be contiguous or non-contiguous.

Intra-band contiguous carrier aggregation: Contiguous carriers aggregated in the same operating band.

Intra-band non-contiguous carrier aggregation: Non-contiguous carriers aggregated in the same operating band.

Link angle: a DL-signal AoA from the view point of the UE, as described in Annex J. If the beam lock function is used to lock the UE beam(s), the link angle can become any arbitrary AoA once the beam lock has been activated.

Measurement angle: the angle of measurement of the desired metric from the view point of the UE, as described in Annex J

radiated interface boundary: operating band specific radiated requirements reference point where the radiated requirements apply

radiated requirements reference point: for the RF measurement setup, the radiated requirements reference point is located at the centre of the quiet zone. From the UE perspective the reference point is the input of the UE antenna array

RX beam peak direction: direction where the maximum total component of RSRP and thus best total component of EIS is found

Sub-block: This is one contiguous allocated block of spectrum for transmission and reception by the same UE. There may be multiple instances of sub-blocks within an RF bandwidth.

TX beam peak direction: direction where the maximum total component of EIRP is found

TRP(Link=TX beam peak direction, Meas=TRP grid): measurement of the TRP of the UE such that the measurement angles are aligned with the directions of the TRP grid points within an acceptable measurement uncertainty while the link angle is aligned with the TX beam peak direction

NOTE: For requirements based on EIRP/EIS, the radiated interface boundary is associated to the far-field region

UE transmission bandwidth configuration: Set of resource blocks located within the UE channel bandwidth which may be used for transmitting or receiving by the UE.

Vehicular UE: A UE embedded in a vehicle

3.2 Symbols

For the purposes of the present document, the following symbols apply:

 $\Delta EIRP_{BC}$ The beam correspondence tolerance, where $\Delta EIRP_{BC} = EIRP_2 - EIRP_1$

 $\begin{array}{ll} \Delta F_{Global} & Granularity \ of \ the \ global \ frequency \ raster \\ \Delta F_{Raster} & Band \ dependent \ channel \ raster \ granularity \\ \Delta f_{OOB} & \Delta \ Frequency \ of \ Out \ Of \ Band \ emission \end{array}$

 Δ_{RB} The starting frequency offset between the allocated RB and the measured non-allocated RB

 ΔR_{IB} Allowed reference sensitivity relaxation due to support for inter-band CA operation

 ΔR_{IBC} Allowed reference sensitivity relaxation due to support for intra-band contiguous CA operation ΔR_{IBNC} Allowed reference sensitivity relaxation due to support for intra-band non-contiguous CA

operation

ΔR_{IB,P,n} Allowed relaxation to each, minimum peak EIRP and reference sensitivity due to support for inter-

band CA operation, per band in a combination of supported bands

 $\Delta R_{IB,S,n}$ Allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to support

for inter-band CA operation, per band in a combination of supported bands

ΔMB_{P,n} Allowed relaxation to minimum peak EIRP and reference sensitivity due to support for multi-band

operation, per supported band in a combination.

ΔMB_{S,n} Allowed relaxation to EIRP spherical coverage and EIS spherical coverage due to support for

multi-band operation, per supported band in a combination

\(\sum_{MBP} \) Total allowed relaxation to minimum peak EIRP and reference sensitivity due to support for multi-

band operation, for all supported bands in a combination

∑MB_s Total allowed relaxation to each, EIRP spherical coverage and EIS spherical coverage due to

support for multi-band operation, for all supported bands in a combination

BW_{Channel} Channel bandwidth

BW_{Channel_CA} Aggregated channel bandwidth, expressed in MHz

BW_{GB} max(BWGB,Channel(k))

BW_{GB,Channel(k)} Minimum guard band defined in sub-clause 5.3A.2 of carrier k

BW_{interferer} Bandwidth of the interferer

Ceil(x) Rounding upwards; ceil(x) is the smallest integer such that $ceil(x) \ge x$

EIRP₁ The measured total EIRP based on the beam the UE chooses autonomously (corresponding beam)

to transmit in the direction of the incoming DL signal, which is based on beam correspondence

without relying on UL beam sweeping

EIRP₂ The measured total EIRP based on the beam yielding highest EIRP in a given direction, which is

based on beam correspondence with relying on UL beam sweeping

EIRP_{max} The applicable maximum EIRP as specified in sub-clause 6.2.1

Floor(x) Rounding downwards; floor(x) is the greatest integer such that floor(x) \leq x

F center The center frequency of an allocated block of PRBs

F_C RF reference frequency for the carrier center on the channel raster, given in table 5.4.2.2-1

 $\begin{array}{ll} F_{C,block,\;high} & Fc\;\; of\; the\;\; highest\;\; transmitted/received\;\; carrier\;in\; a\;\; sub-block. \\ F_{C,block,\;low} & Fc\;\; of\;\; the\;\; lowest\;\; transmitted/received\;\; carrier\;in\;\; a\;\; sub-block. \end{array}$

 $\begin{array}{ll} F_{C,\;low} & \text{The Fc of the lowest carrier, expressed in MHz.} \\ F_{C,\;high} & \text{The Fc of the highest carrier, expressed in MHz.} \\ F_{DL_low} & \text{The lowest frequency of the downlink } \textit{operating band} \\ F_{DL_high} & \text{The highest frequency of the downlink } \textit{operating band} \\ \end{array}$

 $F_{\text{edge, low}} \qquad \qquad \text{The lower edge of } \textit{Aggregated Channel Bandwidth}, \text{ expressed in MHz. } F_{\text{edge, low}} = F_{\text{C, low}} - F_{\text{offset, low}}.$ $F_{\text{edge, high}} \qquad \qquad \text{The upper edge of } \textit{Aggregated Channel Bandwidth}, \text{ expressed in MHz. } F_{\text{edge, high}} = F_{\text{C, high}} + F_{\text{offset, low}}.$

high.

F_{Interferer} Frequency of the interferer

F_{Interferer} (offset) Frequency offset of the interferer (between the center frequency of the interferer and the carrier

frequency of the carrier measured)

F_{loffset} Frequency offset of the interferer (between the center frequency of the interferer and the closest

edge of the carrier measured)

Floor(x) Rounding downwards; floor(x) is the greatest integer such that floor(x) \leq x

F_{OOB} The boundary between the NR out of band emission and spurious emission domains

 $\begin{array}{ll} F_{REF} & RF \ reference \ frequency \\ F_{REF-Offs} & Offset \ used \ for \ calculating \ F_{REF} \end{array}$

 F_{UL_low} The lowest frequency of the uplink *operating band* F_{UL_high} The highest frequency of the uplink *operating band*

 F_{UL_Meas} The sub-carrier frequency for which the equalizer coefficient is evaluated

GB_{Channel} Minimum guard band defined in sub-clause 5.3.3

L_{CRB} Transmission bandwidth which represents the length of a contiguous resource block allocation

expressed in units of resources blocks

L_{CRB,Max} Maximum number of RB for a given Channel bandwidth and sub-carrier spacing

Max() The largest of given numbers
Min() The smallest of given numbers

 $\begin{array}{ll} \text{MPR}_{\text{f,c}} & \text{Maximum output power reduction for carrier } f \text{ of serving cell } c \\ \text{MPR}_{\text{narrow}} & \text{Maximum output power reduction due to narrow PRB allocation} \end{array}$

MPR_{WT} Maximum power reduction due to modulation orders, transmit bandwidth configurations,

waveform types

 n_{PRB} Physical resource block number

NR_{ACLR} NR ACLR

N_{RB} Transmission bandwidth configuration, expressed in units of resource blocks

N_{RB,low} Transmission bandwidth configurations according to Table 5.3.2-1 for the lowest assigned

component carrier in clause 5.3A.1

N_{RB,high} Transmission bandwidth configurations according to Table 5.3.2-1 for the highest assigned

component carrier in clause 5.3A.1

NR Absolute Radio Frequency Channel Number (NR-ARFCN)

 $N_{REF-Offs}$ Offset used for calculating N_{REF}

P_{CMAX} The configured maximum UE output power

 $P_{CMAX, f, c}$ The configured maximum UE output power for carrier f of serving cell c

P_{int} The intermediate power point as defined in table 6.3.4.2-2

P_{Interferer} Modulated mean power of the interferer

 P_{max} The maximum UE output power as specified in sub-clause 6.2.1 P_{min} The minimum UE output power as specified in sub-clause 6.3.1

P-MPR_{f,c} The Power Management UE Maximum Power Reduction for carrier f of serving cell c

P_{PowerClass} Nominal UE power class (i.e., no tolerance) as specified in sub-clause 6.2.1

 $\begin{array}{ll} P_{RB} & \text{The transmitted power per allocated RB, measured in dBm} \\ P_{TMAX,f,c} & \text{The measured total radiated power for carrier } f \text{ of serving cell } c \end{array}$

 P_{UMAX} The measured configured maximum UE output power

Pw Power of a wanted DL signal

RB_{start} Indicates the lowest RB index of transmitted resource blocks SCS_{low} SCS for the lowest assigned component carrier in clause 5.3A.1 SCS_{high} SCS for the highest assigned component carrier in clause 5.3A.1

SS_{REF} SS block reference frequency position

 $T(\Delta P)$ The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB)

TRP_{max} The maximum TRP for the UE power class as specified in sub-clause 6.2.1

3.3 Abbreviations

For the purposes of the present document, the abbreviations given in 3GPP TR 21.905 [1] and the following apply. An abbreviation defined in the present document takes precedence over the definition of the same abbreviation, if any, in 3GPP TR 21.905 [1].

ACLR Adjacent Channel Leakage Ratio
ACS Adjacent Channel Selectivity

A-MPR Additional Maximum Power Reduction

AoA Angle of Arrival

BCS Bandwidth Combination Set BPSK Binary Phase-Shift Keying

BS Base Station
BW Bandwidth
BWP Bandwidth Part
CA Carrier aggregation

CABW Cumulative Aggregated Channel Bandwidth

CA nX-nY Inter-band CA of component carrier(s) in one sub-block within Band X and component carrier(s)

in one sub-block within Band Y where X and Y are the applicable NR operating band

CC Component carrier

CDF Cumulative Distribution Function

CP-OFDM Cyclic Prefix-OFDM CW Continuous Wave

DFT-s-OFDM Discrete Fourier Transform-spread-OFDM

DM-RS
Demodulation Reference Signal
DTX
Discontinuous Transmission
EIRP
Effective Isotropic Radiated Power
EIS
Effective Isotropic Sensitivity
EVM
Error Vector Magnitude
FR
Frequency Range

FR Frequency Range FWA Fixed Wireless Access

GSCN Global Synchronization Channel Number

IBB In-band Blocking

IBM Independent Beam Management
IDFT Inverse Discrete Fourier Transformation

ITU-R Radiocommunication Sector of the International Telecommunication Union

MBW Measurement bandwidth defined for the protected band

MPR Allowed maximum power reduction

NR New Radio

NR-ARFCN NR Absolute Radio Frequency Channel Number

OCNG OFDMA Channel Noise Generator

OOB Out-of-band OTA Over The Air

P-MPR Power Management Maximum Power Reduction

PRB Physical Resource Block

QAM Quadrature Amplitude Modulation

RF Radio Frequency
REFSENS Reference Sensitivity
RIB Radiated Interface Boundary
RMS Root Mean Square (value)
RSRP Reference Signal Receiving Power

Rx Receiver

SCS Subcarrier spacing
SEM Spectrum Emission Mask
SRS Sounding Reference Symbol
SS Synchronization Symbol
TPC Transimission Power Control
TRP Total Radiated Power

Tx Transmitter

UE User Equipment
UL MIMO Unlink Multiple An

UL MIMO Uplink Multiple Antenna transmission ULFPTx Uplink Full Power Transmission

4 General

4.1 Relationship between minimum requirements and test requirements

The present document is a Single-RAT specification for NR UE, covering RF characteristics and minimum performance requirements. Conformance to the present specification is demonstrated by fulfilling the test requirements specified in the conformance specification 3GPP TS 38.521-2 [5].

The Minimum Requirements given in this specification make no allowance for measurement uncertainty. The test specification TS 38.521-2 [5] defines test tolerances. These test tolerances are individually calculated for each test. The test tolerances are used to relax the minimum requirements in this specification to create test requirements. For some requirements, including regulatory requirements, the test tolerance is set to zero.

The measurement results returned by the test system are compared - without any modification - against the test requirements as defined in 3GPP TS 38.521-2 [5].

4.2 Applicability of minimum requirements

- a) In this specification the Minimum Requirements are specified as general requirements and additional requirements. Where the Requirement is specified as a general requirement, the requirement is mandated to be met in all scenarios
- b) For specific scenarios for which an additional requirement is specified, in addition to meeting the general requirement, the UE is mandated to meet the additional requirements.
- c) The spurious emissions power requirements are for the long-term average of the power. For the purpose of reducing measurement uncertainty it is acceptable to average the measured power over a period of time sufficient to reduce the uncertainty due to the statistical nature of the signal
- d) All the requirements for intra-band contiguous and non-contiguous CA apply under the assumption of the same slot format indicated by *TDD-UL-DL-ConfigurationCommon and TDD-UL-DL-ConfigurationDedicated* in the PCell and SCells for NR SA.

For FR2 intra-band CA configurations with multiple FR2 sub-blocks, where at least one of the sub-blocks is a contiguous CA configuration:

- if the field *partialFR2-FallbackRX-Req* is not present, the UE shall meet all applicable UE RF requirements for the highest order CA configuration and all associated fallback CA configurations;
- if the field *partialFR2-FallbackRX-Req* is present, for each FR2 intra-band CA configuration with multiple subblocks that the UE indicates support for explicitly in UE capability signalling: the in-gap UE RF requirements in clauses 7.5A, 7.5D, 7.6A, 7.6D apply as the equivalent requirements for the associated fallback CA configurations with the same number of sub-blocks, where at least one of the sub-blocks consists of a contiguous CA configuration. The UE shall meet all applicable UE RF requirements for fallback CA configurations with a lesser number of sub-blocks;
- regardless of the field *partialFR2-FallbackRX-Req*, the UE shall meet all DL out-of-gap requirements for all lower order fallback CA configurations.

4.3 Specification suffix information

Unless stated otherwise the following suffixes are used for indicating at 2nd level clause, shown in Table 4.3-1.

Table 4.3-1: Definition of suffixes

С	lause suffix	Variant
	None	Single Carrier
	Α	Carrier Aggregation (CA)
	В	Dual-Connectivity (DC)
С		Supplement Uplink (SUL)
D		UL MIMO
NOTE:	NOTE: Suffix D in this specification represents either polarized UL MIMO or spatial UL MIMO. RF requirements are same. If UE supports both kinds of UL MIMO, then RF requirements only need to be verified under either polarized or spatial UL MIMO.	

5 Operating bands and channel arrangement

5.1 General

The channel arrangements presented in this clause are based on the operating bands and channel bandwidths defined in the present release of specifications.

NOTE: Other operating bands and channel bandwidths may be considered in future releases.

Requirements throughout the RF specifications are in many cases defined separately for different frequency ranges (FR). The frequency ranges in which NR can operate according to this version of the specification are identified as described in Table 5.1-1.

Table 5.1-1: Definition of frequency ranges

Frequency range designation	Corresponding frequency range
FR1	410 MHz – 7125 MHz
FR2	24250 MHz – 52600 MHz

The present specification covers FR2 operating bands.

5.2 Operating bands

NR is designed to operate in the FR2 operating bands defined in Table 5.2-1.

Table 5.2-1: NR operating bands in FR2

Operating Band	Uplink (UL) operating band BS receive UE transmit	Downlink (DL) operating band BS transmit UE receive	Duplex Mode
	Ful_low - Ful_high	F _{DL_low} - F _{DL_high}	
n257	26500 MHz - 29500 MHz	26500 MHz - 29500 MHz	TDD
n258	24250 MHz - 27500 MHz	24250 MHz - 27500 MHz	TDD
n259	39500 MHz - 43500 MHz	39500 MHz - 43500 MHz	TDD
n260	37000 MHz - 40000 MHz	37000 MHz - 40000 MHz	TDD
n261	27500 MHz - 28350 MHz	27500 MHz - 28350 MHz	TDD

5.2A Operating bands for CA

5.2A.1 Intra-band CA

NR intra-band contiguous and non-contiguous carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.1-1, where all operating bands are within FR2.

Table 5.2A.1-1: Intra-band contiguous and non-contiguous CA operating bands in FR2

NR CA Band	NR Band (Table 5.2-1)
CA_n257	n257
CA_n258	n258
CA_n259	n259
CA_n260	n260
CA_n261	n261

5.2A.2 Inter-band CA

NR inter-band carrier aggregation is designed to operate in the operating bands defined in Table 5.2A.2-1, where all operating bands are within FR2.

Beam management type is according to UE capability declaration *IE beamManagementType-r16*. The requirements in the following clauses are only applicable to inter-band CA with IBM type.

Table 5.2A.2-1: Inter-band CA operating bands in FR2

NR CA Band	NR Band (Table 5.2-1)
CA_n260-n261	n260, n261
NOTE 1: The minimum requirements apply only when there is non-simultaneous Rx/Tx operation between inter-band NR carriers in the current version of this specification.	

5.2D Operating bands for UL MIMO

NR UL MIMO is designed to operate in the operating bands defined in Table 5.2D-1.

Table 5.2D-1: NR UL MIMO operating bands

UL MIMO operating band (Table 5.2-1)
n257
n258
n259
n260
n261

5.3 UE Channel bandwidth

5.3.1 General

The UE channel bandwidth supports a single NR RF carrier in the uplink or downlink at the UE. From a BS perspective, different UE channel bandwidths may be supported within the same spectrum for transmitting to and receiving from UEs connected to the BS. Transmission of multiple carriers to the same UE (CA) or multiple carriers to different UEs within the BS channel bandwidth can be supported.

From a UE perspective, the UE is configured with one or more BWP / carriers, each with its own UE channel bandwidth. The UE does not need to be aware of the BS channel bandwidth or how the BS allocates bandwidth to different UEs.

The placement of the UE channel bandwidth for each UE carrier is flexible but can only be completely within the BS channel bandwidth.

The relationship between the channel bandwidth, the guardband and the transmission bandwidth configuration is shown in Figure 5.3.1-1.

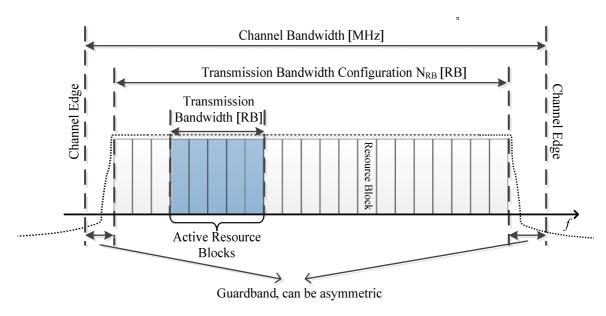


Figure 5.3.1-1: Definition of channel bandwidth and transmission bandwidth configuration for one NR channel

5.3.2 Maximum transmission bandwidth configuration

The maximum transmission bandwidth configuration N_{RB} for each UE channel bandwidth and subcarrier spacing is specified in Table 5.3.2-1

Table 5.3.2-1: Maximum transmission bandwidth configuration N_{RB}

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz
	N _{RB}	N _{RB}	N _{RB}	N _{RB}
60	66	132	264	N.A
120	32	66	132	264

5.3.3 Minimum guardband and transmission bandwidth configuration

The minimum guardband for each UE channel bandwidth and SCS is specified in Table 5.3.3-1

Table 5.3.3-1: Minimum guardband for each UE channel bandwidth and SCS (kHz)

SCS (kHz)	50 MHz	100 MHz	200 MHz	400 MHz
60	1210	2450	4930	N. A
120	1900	2420	4900	9860

NOTE: The minimum guardbands have been calculated using the following equation: $(BW_{Channel} \times 1000 \text{ (kHz)} - N_{RB} \times SCS \times 12) / 2 - SCS/2$, where N_{RB} are from Table 5.3.2-1.

The minimum guardband of receiving BS SCS 240 kHz SS/PBCH block for each UE channel bandwidth is specified in table 5.3.3-2 for FR2.

Table: 5.3.3-2: Minimum guardband (kHz) of SCS 240 kHz SS/PBCH block

SCS (kHz)	100 MHz	200 MHz	400 MHz
240	3800	7720	15560

NOTE: The minimum guardband in Table 5.3.3-2 is applicable only when the SCS 240 kHz SS/PBCH block is received adjacent to the edge of the UE channel bandwidth within which the SS/PBCH block is located.

Figure 5.3.3-1: Void

The number of RBs configured in any channel bandwidth shall ensure that the minimum guardband specified in this clause is met.

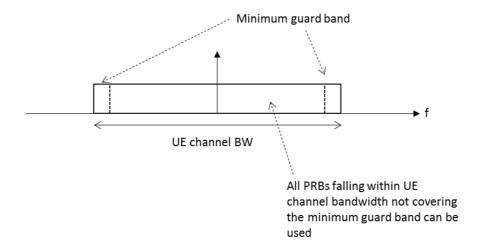


Figure 5.3.3-2 UE PRB utilization

In the case that multiple numerologies are multiplexed in the same symbol due to BS transmission of SSB, the minimum guardband on each side of the carrier is the guardband applied at the configured channel bandwidth for the numerology that is transmitted immediately adjacent to the guard band.

If multiple numerologies are multiplexed in the same symbol and the UE channel bandwidth is > 200 MHz, the minimum guardband applied adjacent to 60 kHz SCS shall be the same as the minimum guardband defined for 120 kHz SCS for the same UE channel bandwidth.

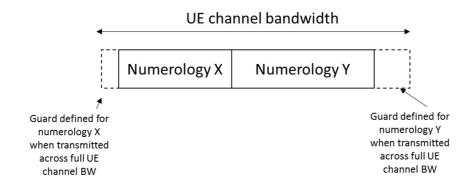


Figure 5.3.3-3 Guard band definition when transmitting multiple numerologies

Note: Figure 5.3.3-3 is not intended to imply the size of any guard between the two numerologies. Internumerology guard band within the carrier is implementation dependent.

5.3.4 RB alignment

For each numerology, its common resource blocks are specified in Clause 4.4.4.3 in [9], and the starting point of its transmission bandwidth configuration on the common resource block grid for a given channel bandwidth is indicated by an offset to "Reference point A" in the unit of the numerology. The *UE transmission bandwidth configuration* is indicated by the higher layer parameter *carrierBandwidth* [13] and will fulfil the minimum UE guardband requirement specified in Clause 5.3.3.

5.3.5 Channel bandwidth per operating band

The requirements in this specification apply to the combination of channel bandwidths, SCS and operating bands shown in Table 5.3.5-1. The transmission bandwidth configuration in Table 5.3.2-1 shall be supported for each of the specified channel bandwidths. The channel bandwidths are specified for both the Tx and Rx path.

Operating band / SCS / UE channel bandwidth					
Operating band	SCS kHz	50 MHz	100 MHz	200 MHz	400 ¹ MHz
n257	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n258	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n259	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n260	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes
n261	60	Yes	Yes	Yes	
	120	Yes	Yes	Yes	Yes

Table 5.3.5-1: Channel bandwidths for each NR band

NOTE 1: This UE channel bandwidth is optional in this release of the specification.

5.3A UE channel bandwidth for CA

5.3A.1 General

5.3A.2 Minimum guardband and transmission bandwidth configuration for CA

For intra-band contiguous carrier aggregation, *Aggregated Channel Bandwidth* and *Guard Bands* are defined as follows, see Figure 5.3A.2-1.

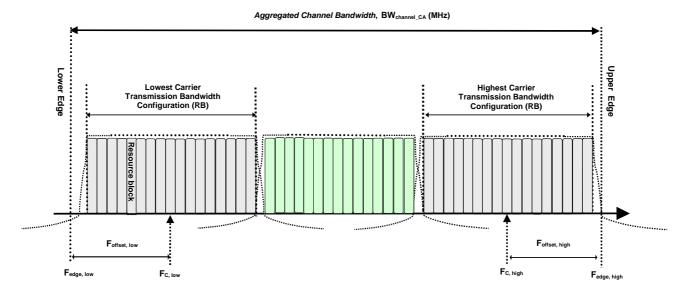


Figure 5.3A.2-1: Definition of Aggregated Channel Bandwidth for intra-band carrier aggregation

The aggregated channel bandwidth, BWChannel_CA, is defined as

 $BW_{Channel_CA} = F_{edge,high} - F_{edge,low}$ (MHz).

The lower bandwidth edge $F_{\text{edge, low}}$ and the upper bandwidth edge $F_{\text{edge, high}}$ of the aggregated channel bandwidth are used as frequency reference points for transmitter and receiver requirements and are defined by

$$F_{edge,low} = F_{C,low} - F_{offset,low}$$

$$F_{edge,high} = F_{C,high} + F_{offset,high}$$

The lower and upper frequency offsets depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carrier and are defined as

$$\begin{split} F_{offset,low} &= (N_{RB,low}*12 + 1)*SCS_{low}/2 + BW_{GB} \, (MHz) \\ F_{offset,high} &= (N_{RB,high}*12 - 1)*SCS_{high}/2 + BW_{GB} \, (MHz) \\ BW_{GB} &= max(BW_{GB,Channel(k)}) \end{split}$$

 $N_{RB,low}$ and $N_{RB,high}$ are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier, SCS_{low} and SCS_{high} are the sub-carrier spacing for the lowest and highest assigned component carrier respectively. SCS_{low} , SCS_{high} , $N_{RB,low}$, $N_{RB,high}$, and $BW_{GB,Channel(k)}$ use the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1 and $BW_{GB,Channel(k)}$ is the minimum guard band for carrier k according to Table 5.3.3-1 for the said μ value.

For intra-band non-contiguous carrier aggregation *Sub-block Bandwidth* and *Sub-block edges* are defined as follows, see Figure 5.3A.2-2.

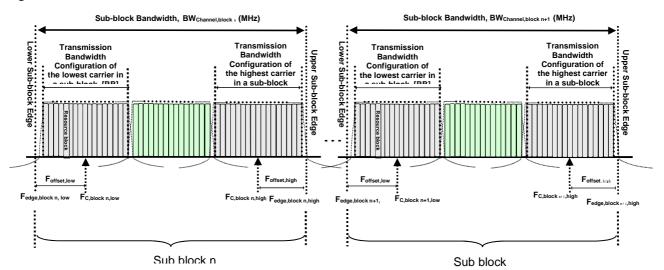


Figure 5.3A.2-2: Definition of sub-block bandwidth for intra-band non-contiguous spectrum

The lower sub-block edge of the Sub-block Bandwidth (BW_{Channel,block}) is defined as

$$F_{\text{edge,block, low}} = F_{\text{C,block,low}} - F_{\text{offset, low}}$$

The upper sub-block edge of the Sub-block Bandwidth is defined as

$$F_{\text{edge,block,high}} = F_{\text{C,block,high}} + F_{\text{offset, high.}}$$

The Sub-block Bandwidth, BW_{Channel,block}, is defined as follows:

$$BW_{Channel,block} = F_{edge,block,high} - F_{edge,block,low} (MHz)$$

The lower and upper frequency offsets F_{offset,block,low} and F_{offset,block,high} depend on the transmission bandwidth configurations of the lowest and highest assigned edge component carriers within a sub-block and are defined as

$$\begin{split} F_{offset,block,low} = & \ (N_{RB,low}*12+1)*SCS_{low}/2 + BW_{GB} \, (MHz) \\ F_{offset,block,high} = & \ (N_{RB,high}*12-1)*SCS_{high}/2 + BW_{GB} \, (MHz) \\ BW_{GB} = & \ max(BW_{GB,Channel(k)}) \end{split}$$

where $N_{RB,low}$ and $N_{RB,high}$ are the transmission bandwidth configurations according to Table 5.3.2-1 for the lowest and highest assigned component carrier within a sub-block, respectively. SCS_{low} and SCS_{high} are the sub-carrier spacing for the lowest and highest assigned component carrier within a sub-block, respectively. SCS_{low} , SCS_{high} , $N_{RB,low}$, $N_{RB,high}$, and $BW_{GB,Channel(k)}$ use the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1 and $BW_{GB,Channel(k)}$ is the minimum guard band for carrier k according to Table 5.3.3-1 for the said μ value.

The sub-block gap size between two consecutive sub-blocks W_{gap} is defined as

 $W_{gap} = F_{edge,block n+1,low} - F_{edge,block n,high} (MHz)$

5.3A.3 RB alignment with different numerologies for CA

5.3A.4 UE channel bandwidth per operating band for CA

For intra-band contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting a carrier aggregation bandwidth class with associated bandwidth combination sets specified in clause 5.5A.1. For each carrier aggregation configuration, requirements are specified for all aggregated channel bandwidths contained in a bandwidth combination set, UE can indicate support of several bandwidth combination sets per carrier aggregation configuration. The requirements are applicable only when Uplink CCs are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier.

For intra-band non-contiguous carrier aggregation, a carrier aggregation configuration is a single operating band supporting two or more sub-blocks, each supporting a carrier aggregation bandwidth class. The requirements are applicable only when Uplink CCs in each UL sub-block are configured within the frequency range between lower edge of lowest downlink component carrier and upper edge of highest downlink component carrier of a DL sub-block.

Frequency separation class (Fs) specified in Table 5.3A.4-2 indicates the maximum frequency span between lower edge of lowest component carrier and upper edge of highest component carrier that UE can support per band in downlink or uplink (DL Fs or UL Fs) respectively in non-contiguous intra-band operation within the bidirectional spectrum.

The DL-only frequency spectrum is the width of UE frequency spectrum available to network to configure DL CCs only, and it extends on one-side of the bidirectional spectrum in contiguous manner with no frequency gap between the two. Frequency separation class for DL-only spectrum (Fsd) specified in Table 5.3A.4-3 and is declared per band. The frequency separation class for DL-only spectrum (Fsd) can be equal but not larger than the frequency separation (DL Fs). The combined downlink spectrum (DL Fs + Fsd) cannot exceed 2400 MHz. A UE may configure DL-only spectrum only if the combined downlink spectrum (DL Fs + Fsd) exceeds 1400 MHz. When a UE configures DL-only spectrum, it shall not expect a CC to be configured across the boundary between bidirectional spectrum and DL-only spectrum UE can support respectively.

For inter-band carrier aggregation, a carrier aggregation configuration is a combination of operating bands, each supporting a carrier aggregation bandwidth class.

Table 5.3A.4-1: CA bandwidth classes

NR CA bandwidth class	Aggregated channel bandwidth	Number of contiguous CC	Fallback group
А	BW _{Channel} ≤ 400 MHz	1	1,2,3,4
В	400 MHz < BW _{Channel_CA} ≤ 800 MHz	2	1
С	800 MHz < BW _{Channel_CA} ≤ 1200 MHz	3	
D	200 MHz < BW _{Channel_CA} ≤ 400 MHz	2	2
Е	400 MHz < BW _{Channel_CA} ≤ 600 MHz	3	
F	600 MHz < BW _{Channel_CA} ≤ 800 MHz	4	
G	100 MHz < BW _{Channel_CA} ≤ 200 MHz	2	3
Н	200 MHz < BW _{Channel_CA} ≤ 300 MHz	3	
I	300 MHz < BW _{Channel_CA} ≤ 400 MHz	4	
J	400 MHz < BW _{Channel_CA} ≤ 500 MHz	5	
K	500 MHz < BW _{Channel_CA} ≤ 600 MHz	6	
L	600 MHz < BW _{Channel_CA} ≤ 700 MHz	7	
М	700 MHz < BW _{Channel_CA} ≤ 800 MHz	8	
0	100 MHz ≤ BW _{Channel_CA} ≤ 200 MHz	2	4
Р	150 MHz ≤ BW _{Channel_CA} ≤ 300 MHz	3	
Q	200 MHz ≤ BW _{Channel_CA} ≤ 400 MHz	4	

NOTE 1: Maximum supported component carrier bandwidths for fallback groups 1, 2, 3 and 4 are 400 MHz, 200 MHz, 100 MHz and 100 MHz respectively except for CA bandwidth class A.

NOTE 2: It is mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration within a fallback group. It is not mandatory for a UE to be able to fallback to lower order CA bandwidth class configuration that belong to a different fallback group.

Table 5.3A.4-2: Frequency separation classes for non-contiguous intra-band operation

Frequency separation class	Max. allowed frequency separation (Fs)
I	800 MHz
II	1200 MHz
III	1400 MHz
IV	1000 MHz
V	1600 MHz
VI	1800 MHz
VII	2000 MHz
VIII	2200 MHz
IX	2400 MHz
X	400 MHz
XI	600 MHz
NOTE 1: En values larger than 1	400 MHz apply aply to

NOTE 1: Fs values larger than 1400 MHz apply only to downlink frequency separation.

Table 5.3A.4-3: Frequency separation classes for DL-only spectrum

Frequency separation class	Max. allowed frequency separation (Fsd)
I	200 MHz
II	400 MHz
III	600 MHz
IV	800 MHz
V	1000 MHz
VI	1200 MHz

5.3D Channel bandwidth for UL MIMO

The requirements specified in clause 5.3 are applicable to UE supporting UL MIMO.

5.4 Channel arrangement

5.4.1 Channel spacing

5.4.1.1 Channel spacing for adjacent NR carriers

The spacing between carriers will depend on the deployment scenario, the size of the frequency block available and the channel bandwidths. The nominal channel spacing between two adjacent NR carriers is defined as following:

For NR operating bands with 60 kHz channel raster,

Nominal Channel spacing = $(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-20 \text{ kHz}, 0 \text{ kHz}, 20 \text{ kHz}\}$ for ΔF_{Raster} equals to 60 kHz

Nominal Channel spacing = $(BW_{Channel(1)} + BW_{Channel(2)})/2 + \{-40 \text{ kHz}, 0 \text{ kHz}, 40 \text{ kHz}\}\$ for ΔF_{Raster} equals to 120 kHz.

where BW_{Channel(1)} and BW_{Channel(2)} are the channel bandwidths of the two respective NR carriers. The channel spacing can be adjusted depending on the channel raster to optimize performance in a particular deployment scenario.

5.4.2 Channel raster

5.4.2.1 NR-ARFCN and channel raster

The global frequency raster defines a set of RF reference frequencies F_{REF} . The RF reference frequency is used in signalling to identify the position of RF channels, SS blocks and other elements.

The global frequency raster is defined for all frequencies from 0 to 100 GHz. The granularity of the global frequency raster is ΔF_{Global} .

RF reference frequency is designated by an NR Absolute Radio Frequency Channel Number (NR-ARFCN) in the range [2016667...3279165] on the global frequency raster. The relation between the NR-ARFCN and the RF reference frequency F_{REF} in MHz is given by the following equation, where $F_{REF-Offs}$ and $N_{Ref-Offs}$ are given in table 5.4.2.1-1 and N_{REF} is the NR-ARFCN

 $F_{REF} = F_{REF\text{-}Offs} + \Delta F_{Global} \; (N_{REF} - N_{REF\text{-}Offs})$

Table 5.4.2.1-1: NR-ARFCN parameters for the global frequency raster

Frequency range (MHz)	ΔF _{Global} (kHz)	Free-Offs [MHz]	NREF-Offs	Range of N _{REF}
24250 - 100000	60	24250.08	2016667	2016667 - 3279165

The *channel raster* defines a subset of *RF reference frequencies* that can be used to identify the RF channel position in the uplink and downlink. The *RF reference frequency* for an RF channel maps to a resource element on the carrier. For each operating band, a subset of frequencies from the global frequency raster are applicable for that band and forms a channel raster with a granularity ΔF_{Raster} , which may be equal to or larger than ΔF_{Global} .

The mapping between the channel raster and corresponding resource element is given in Clause 5.4.2.2. The applicable entries for each operating band are defined in clause 5.4.2.3

5.4.2.2 Channel raster to resource element mapping

The mapping between the RF reference frequency on channel raster and the corresponding resource element is given in Table 5.4.2.2-1 and can be used to identify the RF channel position. The mapping depends on the total number of RBs that are allocated in the channel and applies to both UL and DL. The mapping must apply to at least one numerology supported by the UE.

Table 5.4.2.2-1: Channel raster to resource element mapping

	$N_{RB} \mod 2 = 0$	N_{RB} mod 2 = 1
Resource element index k	0	6
Physical resource block number n _{PRB}	$n_{\text{PRB}} = \left\lfloor \frac{N_{\text{RB}}}{2} \right\rfloor$	$n_{\text{PRB}} = \left\lfloor \frac{N_{\text{RB}}}{2} \right\rfloor$

k, n_{RB} , N_{RB} are as defined in TS 38.211 [9].

5.4.2.3 Channel raster entries for each operating band

The RF channel positions on the channel raster in each NR operating band are given through the applicable NR-ARFCN in Table 5.4.2.3-1, using the channel raster to resource element mapping in clause 5.4.2.2.

- For NR operating bands with 60 kHz channel raster above 24 GHz, $\Delta F_{Raster} = I \times \Delta F_{Global}$, where $I \in \{1,2\}$. Every I^{th} NR-ARFCN within the operating band are applicable for the channel raster within the operating band and the step size for the channel raster in table 5.4.2.3-1 is given as < I >.
- In frequency bands with two ΔF_{Raster} , the higher ΔF_{Raster} applies to channels using only the SCS that equals the higher ΔF_{Raster} and the SSB SCS that is equal to or larger than the higher ΔF_{Raster} .

Table 5.4.2.3-1: Applicable NR-ARFCN per operating band

Operating Band	ΔF _{Raster} (kHz)	Uplink and Downlink Range of N _{REF}
		(First – <step size=""> – Last)</step>
n257	60	2054166 - <1> - 2104165
	120	2054167 - <2> - 2104165
n258	60	2016667 - <1> - 2070832
	120	2016667 - <2> - 2070831
n259	60	2270833 - <1> - 2337499
	120	2270833- <2> - 2337499
n260	60	2229166 - <1> - 2279165
	120	2229167 - <2> - 2279165
n261	60	2070833 - <1> - 2084999
	120	2070833 - <2> - 2084999

5.4.3 Synchronization raster

5.4.3.1 Synchronization raster and numbering

The synchronization raster indicates the frequency positions of the synchronization block that can be used by the UE for system acquisition when explicit signalling of the synchronization block position is not present.

A global synchronization raster is defined for all frequencies. The frequency position of the SS block is defined as SS_{REF} with corresponding number GSCN. The parameters defining the SS_{REF} and GSCN for all the frequency ranges are in Table 5.4.3.1-1.

The resource element corresponding to the SS block reference frequency SS_{REF} is given in clause 5.4.3.2. The synchronization raster and the subcarrier spacing of the synchronization block is defined separately for each band.

Table 5.4.3.1-1: GSCN parameters for the global frequency raster

Frequency range	SS block frequency position SS _{REF}	GSCN	Range of GSCN
24250 – 100000 MHz	24250.08 MHz + N * 17.28 MHz,	22256 + N	22256 – 26639
	N = 0:4383		

5.4.3.2 Synchronization raster to synchronization block resource element mapping

The mapping between the synchronization raster and the corresponding resource element of the SS block is given in Table 5.4.3.2-1.

Table 5.4.3.2-1: Synchronization raster to SS block resource element mapping

Resource element index k	120

k is the subcarrier number of SS/PBCH block defined in TS 38.211 clause 7.4.3.1 [9].

5.4.3.3 Synchronization raster entries for each operating band

The synchronization raster for each band is give in Table 5.4.3.3-1. The distance between applicable GSCN entries is given by the <Step size> indicated in Table 5.4.3.3-1.

Table 5.4.3.3-1: Applicable SS raster entries per operating band

NR Operating Band	SS Block SCS	SS Block pattern ¹	Range of GSCN							
			(First – <step size=""> – Last)</step>							
n257	120 kHz	Case D	22388 - <1> - 22558							
	240 kHz	Case E	22390 - <2> - 22556							
n258	120 kHz	Case D	22257 - <1> - 22443							
	240 kHz	Case E	22258 - <2> - 22442							
n259	120 kHz	Case D	23140 - <1> - 23369							
	240 kHz	Case E	23142 - <2> - 23368							
n260	120 kHz	Case D	22995 - <1> - 23166							
	240 kHz	Case E	22996 - <2> - 23164							
n261	120 kHz	Case D	22446 - <1> - 22492							
	240 kHz	Case E	22446 - <2> - 22490							
NOTE 1: SS Block pattern is defined in clause 4.1 in TS 38.213 [10].										

5.4A Channel arrangement for CA

5.4A.1 Channel spacing for CA

For intra-band contiguous carrier aggregation with two or more component carriers, the nominal channel spacing between two adjacent NR component carriers is defined as the following unless stated otherwise:

For NR operating bands with 60kHz channel raster:

Nominal channel spacing =
$$\left[\frac{BW_{Channel (1)} + BW_{Channel (2)} - 2 \left| GB_{Channel (1)} - GB_{Channel (2)} \right|}{0.06 * 2^{n+1}} \right] 0.06 * 2^{n} [MHz]$$

with

$$n=\mu_0-2$$

where BW_{Channel(1)} and BW_{Channel(2)} are the channel bandwidths of the two respective NR component carriers according to Table 5.3.2-1 with values in MHz, μ_0 is the largest μ value among the subcarrier spacing configurations supported in the operating band for both of the channel bandwidths according to Table 5.3.5-1, and $GB_{Channel(i)}$ is the minimum guard band for channel bandwidth i according to Table 5.3.3-1 for the said μ value, with μ as defined in TS 38.211 [9].

The channel spacing for intra-band contiguous carrier aggregation can be adjusted to any multiple of least common multiple of channel raster and sub-carrier spacing less than the nominal channel spacing to optimize performance in a particular deployment scenario.

For intra-band non-contiguous carrier aggregation, the channel spacing between two NR component carriers in different sub-blocks shall be larger than the nominal channel spacing defined in this clause.

- 5.5 Configurations
- 5.5A Configurations for CA
- 5.5A.1 Configurations for intra-band contiguous CA

Table 5.5A.1-1: NR CA configurations, bandwidth combination sets, and fallback group defined for intra-band contiguous CA

	NR CA configuration / Bandwidth combination set / Fallback group										1	
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group				
CA_n257B	CA_n257B	50, 100, 200, 400	400							800	0	1
CA_n257C	CA_n257B	50, 100, 200, 400	400	400						1200	0	
CA_n257D	CA_n257D	50, 100, 200	200							400	0	2
CA_n257E	CA_n257D CA_n257E	50, 100, 200	200	200						600	0	
CA_n257F	CA_n257D CA_n257E CA_n257F	50, 100, 200	200	200	200					800	0	
CA_n257G	CA_n257G	50, 100	100							200	0	3
CA_n257H	CA_n257G CA_n257H	50, 100	100	100						300	0	
CA_n257I	CA_n257G CA_n257H CA_n257I	50, 100	100	100	100					400	0	
CA_n257J	CA_n257G CA_n257H CA_n257I CA_n257J	50, 100	100	100	100	100				500	0	
CA_n257K	CA_n257G CA_n257H CA_n257I CA_n257J CA_n257K	50, 100	100	100	100	100	100			600	0	
CA_n257L	CA_n257G CA_n257H CA_n257I CA_n257J CA_n257K CA_n257L	50, 100	100	100	100	100	100	100		700	0	
CA_n257M	CA_n257G CA_n257H CA_n257I CA_n257J CA_n257K CA_n257L CA_n257M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n258B	CA_n258B	50, 100, 200, 400	400							800	0	1

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group
CA_n258C	CA_n258B	50, 100, 200, 400	400	400						1200	0	
CA_n258D	CA_n258D	50, 100, 200	200							400	0	2
CA_n258E	CA_n258D CA_n258E	50, 100, 200	200	200						600	0	
CA_n258F	CA_n258D CA_n258E CA_n258F	50, 100, 200	200	200	200					800	0	
CA_n258G	CA_n258G	50, 100	100							200	0	3
CA_n258H	CA_n258G CA_n258H	50, 100	100	100						300	0	
CA_n258I	CA_n258G CA_n258H CA_n258I	50, 100	100	100	100					400	0	
CA_n258J	CA_n258G CA_n258H CA_n258I CA_n258J	50, 100	100	100	100	100				500	0	
CA_n258K	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258K	50, 100	100	100	100	100	100			600	0	
CA_n258L	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258K CA_n258L	50, 100	100	100	100	100	100	100		700	0	
CA_n258M	CA_n258G CA_n258H CA_n258I CA_n258J CA_n258K CA_n258L CA_n258M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n259B	CA_n259B	50, 100, 200, 400	400							800	0	1
CA_n259C	CA_n259B	50, 100, 200, 400	400	400						1200	0	
CA_n259G	CA_n259G	50, 100	100							200	0	3

NR CA	Holini- CA	DW.		figuration /					DW-	Maxim	DCC	Fallback
configuration	Uplink CA configurations	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	group							
CA_n259H	CA_n259G CA_n259H	50, 100	100	100						300	0	
CA_n259I	CA_n259G CA_n259H CA_n259I	50, 100	100	100	100					400	0	
CA_n259J	CA_n259G CA_n259H CA_n259I CA_n259J	50, 100	100	100	100	100				500	0	
CA_n259K	CA_n259G CA_n259H CA_n259I CA_n259J CA_n259K	50, 100	100	100	100	100	100			600	0	
CA_n259L	CA_n259G CA_n259H CA_n259I CA_n259J CA_n259K CA_n259L	50, 100	100	100	100	100	100	100		700	0	
CA_n259M	CA_n259G CA_n259H CA_n259I CA_n259J CA_n259K CA_n259L CA_n259M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n260B	CA_n260B	50, 100, 200, 400	400							800	0	1
CA_n260C	CA_n260B	50, 100, 200, 400	400	400						1200	0	
CA_n260D	CA_n260D	50, 100, 200	200							400	0	2
CA_n260E	CA_n260D CA_n260E	50, 100, 200	200	200						600	0	
CA_n260F	CA_n260D CA_n260E CA_n260F	50, 100, 200	200	200	200					800	0	
CA_n260G	CA_n260G	50, 100	100							200	0	3
CA_n260H	CA_n260G CA_n260H	50, 100	100	100						300	0	

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group					
CA_n260I	CA_n260G CA_n260H CA_n260I	50, 100	100	100	100					400	0	
CA_n260J	CA_n260G CA_n260H CA_n260I CA_n260J	50, 100	100	100	100	100				500	0	
CA_n260K	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K	50, 100	100	100	100	100	100			600	0	
CA_n260L	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K CA_n260L	50, 100	100	100	100	100	100	100		700	0	
CA_n260M	CA_n260G CA_n260H CA_n260I CA_n260J CA_n260K CA_n260L CA_n260M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n260O	CA_n260O	50, 100	50, 100							200	0	4
CA_n260P	CA_n260O CA_n260P	50, 100	50, 100	50, 100						300	0	
CA_n260Q	CA_n260O CA_n260P CA_n260Q	50, 100	50, 100	50, 100	50, 100					400	0	
CA_n261B	CA_n261B	50, 100, 200, 400	400							800	0	1
CA_n261C	CA_n261B	50	400	400						850	0	
CA_n261D	CA_n261D	50, 100, 200	200							400	0	2
CA_n261E	CA_n261D CA_n261E	50, 100, 200	200	200						600	0	
CA_n261F	CA_n261D CA_n261E CA_n261F	50, 100, 200	200	200	200					800	0	
CA_n261G	CA_n261G	50, 100	100							200	0	3

			NR CA con	figuration /	Bandwidth	combinatio	n set / Fallba	ack group				
NR CA configuration	Uplink CA configurations	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	BW _{Channel} (MHz)	Maximum aggregated BW (MHz)	BCS	Fallback group
CA_n261H	CA_n261G CA_n261H	50, 100	100	100						300	0	
CA_n261I	CA_n261G CA_n261H CA_n261I	50, 100	100	100	100					400	0	
CA_n261J	CA_n261G CA_n261H CA_n261I CA_n261J	50, 100	100	100	100	100				500	0	
CA_n261K	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261K	50, 100	100	100	100	100	100			600	0	
CA_n261L	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261K CA_n261L	50, 100	100	100	100	100	100	100		700	0	
CA_n261M	CA_n261G CA_n261H CA_n261I CA_n261J CA_n261K CA_n261L CA_n261M	50, 100	100	100	100	100	100	100	100	800	0	
CA_n261O	CA_n261O	50, 100	50, 100							200	0	4
CA_n261P	CA_n261O CA_n261P	50, 100	50, 100	50, 100						300	0	
CA_n261Q	CA_n261O CA_n261P CA_n261Q	50, 100	50, 100	50, 100	50, 100					400	0	

NOTE 1: Void

NOTE 2: For the NR CA configuration with more than two component carries, the bandwidths in a BCS which may introduce combinations more than requested unintentionally should be listed in a row separately.

Configurations for intra-band non-contiguous CA 5.5A.2

Configurations listed in this clause apply to downlink carrier aggregation only.

NOTE: Sub-blocks belonging to a CA configuration can be in any order. In other words certain CA configuration acronym includes all sub-block arrangements which have exactly the same sub-block set. As an example, CA_n260(2G-3O) denotes CA_n260(2O-2G-O), CA_n260(G-3O-G) etc. but these are not listed in tables separately.

Table 5.5A.2-1: NR CA configurations with single CA bandwidth class defined for intra-band non-contiguous CA

				NR	CA confi	guration /	Bandwidt	h combii	nation se	et							
NR	Uplink CA	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub	Sub	Sub	Sub	Σ(BW _{Chann}	BCS
configuration	configurati	block	block	block	block	block	block	block	block	block	block	-	-	-	-	el,block)	
	ons											blo	blo	blo	blo	(MHz)	
												ck	ck	ck	ck	, ,	

CA_n257(2A)	I -	n257A	n257A										800	0
CA n258(2A)	_	n258A	n258A										800	0
CA_n258(3A)	_	n258A	n258A	n258A									1200	0
CA_n258(4A)	_	n258A	n258A	n258A	n258A								1600	0
CA_n258(5A)	_	n258A	n258A	n258A	n258A	n258A							2000	0
CA_n260(2A)	CA_n260(2 A)	n260A	n260A	1120071	1120071	1120071							800	0
CA_n260(3A)	CA_n260(3 A)	n260A	n260A	n260A									1200	0
CA_n260(4A)	-	n260A	n260A	n260A	n260A								1600	0
CA_n260(5A)	-	n260A	n260A	n260A	n260A	n260A							2000	0
CA_n260(6A)	_	n260A	n260A	n260A	n260A	n260A	n260A						2400	0
CA_n260(7A)	_	n260A	n260A	n260A	n260A	n260A	n260A	n260A					2800	0
CA_n260(8A)	_	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A				2900	0
CA_n260(9A)	_	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A			2950	0
CA_n260(10A)	1-	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A	n260A		2950	0
CA_n260(2D)	-	CA_n26 0D	CA_n26 0D	1120071	1120071	1120071	1120071	1120071	1120071	1120071	1120071		800	0
CA_n260(2G)	CA_n260G	CA_n26 0G	CA_n26 0G										400	0
CA_n260(3G)	-	CA_n26 0G	CA_n26 0G	CA_n26 0G									600	0
CA_n260(4G)	-	CA_n26 0G	CA_n26 0G	CA_n26 0G	CA_n26 0G								800	0
CA_n260(2H)	CA_n260G CA_n260H	CA_n26 0H	CA_n26 0H										600	0
CA_n260(2O)	-	CA_n26 0O	CA_n26 0O										400	0
CA_n260(3O)	-	CA_n26 0O	CA_n26 0O	CA_n26 0O									600	0
CA_n260(4O)	-	CA_n26 0O	CA_n26 0O	CA_n26 0O	CA_n26 0O								800	0
CA_n260(2P)	-	CA_n26 0P	CA_n26 0P										600	0
CA_n260(3P)	-	CA_n26 0P	CA_n26 0P	CA_n26 0P									900	0
CA_n260(4P)	-	CA_n26 0P	CA_n26 0P	CA_n26 0P	CA_n26 0P								1200	0
CA_n260(2Q)	-	CA_n26 0Q	CA_n26 0Q										800	0
CA_n261(2A)	-	n261A	n261A										800	0
CA_n261(3A)	-	n261A	n261A	n261A									800	0
CA_n261(4A)	-	n261A	n261A	n261A	n261A								800	0
CA_n261(2D)	-	CA_n26 1D	CA_n26 1D										800	0

CA_n261(2G)	CA_n261G	CA_n26 1G	CA_n26 1G									400	0
CA_n261(3G)	-	CA_n26 1G	CA_n26 1G	CA_n26 1G								600	0
CA_n261(4G)	-	CA_n26 1G	CA_n26 1G	CA_n26 1G	CA_n26 1G							800	0
CA_n261(2H)	CA_n261G CA_n261H	CA_n26 1H	CA_n26 1H									600	0
CA_n261(2I)	CA_n261G CA_n261H CA_n261I	CA_n26 1I	CA_n26 1I									800	0
CA_n261(2O)	-	CA_n26 10	CA_n26 1O									400	0
CA_n261(3O)	-	CA_n26 1O	CA_n26 1O	CA_n26 1O								600	0
CA_n261(4O)	-	CA_n26 1O	CA_n26 1O	CA_n26 1O	CA_n26 1O							800	0
CA_n261(5O)	-	CA_n26 10	CA_n26 1O	CA_n26 1O	CA_n26 1O	CA_n26 1O						800	0
CA_n261(6O)	-	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10					800	0
CA_n261(7O)	-	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n26 10	CA_n2 610				800	0
CA_n261(2P)	-	CA_n26 1P	CA_n26 1P									600	0
CA_n261(2Q)	-	CA_n26 1Q	CA_n26 1Q									800	0

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NOTE 1: Void NOTE 2: Void NOTE 3: Void

NOTE 4: Void

NOTE 5: Channel bandwidth per operating band defined in Table 5.3.5-1

NOTE 6: Unless otherwise stated, BCS0 is referred in each constituent CA configuration

NOTE 7: $\Sigma(BW_{Channel,block})$ denotes the maximum total bandwidth from the summation of the sub-block bandwidths and shall be less than the bandwidth of the operating bànd.

Table 5.5A.2-2: NR CA configurations with multiple CA bandwidth classes defined for intra-band non-contiguous CA

CA configuration	Uplink CA	Sub-block	Sub-	Sub-	Sub-	ation / Band Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Sub-	Σ(BW _{Chann}	BCS
o, comigaranon	configurations	Cus sicon	block	block	block	block	block	block	block	block	block	block	block	el,block) (MHz)	
CA_n260(A-D)	-	n260A	CA_n2 60D											800	0
CA_n260(2A-D)	-	CA_n260)(2A)	CA_n260 D										1200	0
CA_n260(A-2D)	-	n260A	CA r	1260(2D)										1200	0
CA_n260(2A-2D)	-	CA_n260)(2A)	CA_n20	60(2D)									1600	0
CA_n260(A-D-O)	-	n260A	CA_n2 60D	CA_n260 O										1000	0
CA_n260(2A-D-O)	-	CA_n260)(2A)	CA_n260 D	CA_n26 0O									1400	0
CA_n260(A-D-2O)	-	n260A	CA_n2 60D	CA_n26										1200	0
CA_n260(2A-D- 2O)	-	CA_n260		CA_n260 D	CA_n	260(2O)								1600	0
CA_n260(A-G)	CA_n260G	n260A	CA_n2 60G											600	0
CA_n260(2A-G)	CA_n260G	CA_n260	, ,	CA_n260 G										1000	0
CA_n260(A-2G)	CA_n260G	n260A	CA_r	260(2G)										800	0
CA_n260(2A-2G)	CA_n260G	CA_n260		CA_n26										1200	0
CA_n260(2A-2G- O)	-	CA_n260	` '	CA_n26	, ,	CA_n260 O								1400	0
CA_n260(2A-2G- 2O)	-	CA_n260)(2A)	CA_n26	,	CA_n26	50(2O)							1600	0
CA_n260(3A-2G)	-	CA	_n260(3		CA_n	260(2G)								1600	0
CA_n260(4A-G)	-			260(4A)		CA_n260 G								1800	0
CA_n260(4A-2G)	-			260(4A)		CA_n26	60(2G)							2000	0
CA_n260(A-2G- 2O)	-	n260A		1260(2G)		260(20)								1200	0
CA_n260(2A-G- 2O)	-	CA_n260	` '	CA_n260 G		260(20)								1400	0
CA_n260(3A-G)	CA_n260G	CA	_n260(3	•	CA_n26 0G									1400	0
CA_n260(A-2H)	-	n260A		n260(2H)										1000	0
CA_n260(2A-H)	-	CA_n260	` ,	CA_n260 H										1100	0
CA_n260(2A-2H)	-	CA_n260		CA_n26	60(2H)									1400	0
CA_n260(A-H)	CA_n260G CA_n260H	n260A	CA_n2 60H											700	0
CA_n260(A-O)	-	n260A	CA_n2 60O											600	0

CA_n260(A-O-P)	-	n260A	CA_n2 60O	CA_n260 P						900	0
CA_n260(A-O-2P)	-	n260A	CA_n2 60O	CA_n26	60(2P)					1200	0
CA_n260(2A-O-P)	-	CA_n26		CA_n260 O	CA_n26 0P					1300	0
CA_n260(2A-O- 2P)	-	CA_n26	0(2A)	CA_n260 O		260(2P)				1600	0
CA_n260(2A-2O- P)	-	CA_n26	0(2A)	CA_n26	60(2O)	CA_n260 P				1500	0
CA_n260(A-O-Q)	-	n260A	CA_n2 60O	CA_n260 Q						1000	0
CA_n260(A-O-2Q)	-	n260A	CA_n2 60O	CA_n26	60(2Q)					1400	0
CA_n260(2A-O-Q)	-	CA_n26		CA_n260 O	CA_n26 0Q					1400	0
CA_n260(2A-O- 2Q)	-	CA_n26	0(2A)	CA_n260 O		260(2Q)				1800	0
CA_n260(2A-2O- Q)	-	CA_n26	0(2A)	CA_n26	60(2O)	CA_n260 Q				1600	0
CA_n260(2A-O)	-	CA_n26	0(2A)	CA_n260 O						1000	0
CA_n260(A-2O)	-	n260A	CA r	1260(20)						800	0
CA_n260(A-2O-P)	-	n260A		n260(2O)	CA_n26 0P					1100	0
CA_n260(A-2O- 2P)	-	n260A		1260(20)		260(2P)				1400	0
CA_n260(A-2O-Q)	-	n260A		1260(20)	CA_n26 0Q					1200	0
CA_n260(A-2O- 2Q)	-	n260A	CA_r	1260(20)	CA_n	260(2Q)				1600	0
CA_n260(2A-2O)	-	CA_n26	0(2A)	CA_n26	0(20)					1200	0
CA_n260(2A-2O- 2P)	-	CA_n26	, ,	CA_n26	, ,	CA_n26	, ,			1800	0
CA_n260(2A-2O- 2Q)	-	CA_n26	0(2A)	CA_n26	` '	CA_n26	60(2Q)			2000	0
CA_n260(2A-3O)	-	CA_n26	0(2A)	C	A_n260(30					1400	0
CA_n260(3A-2O)	-	C	A_n260(3		CA_n	260(2O)				1600	0
CA_n260(4A-O)	-		CA_n	260(4A)		CA_n260 O				1800	0
CA_n260(4A-3O)	-		CA_n	260(4A)		CA_n260(3O)				2200	0
CA_n260(5A-O)	-			CA_n260(5/	A)	- /	CA_n26 0O			2200	0
CA_n260(6A-O)	-			CA_n2	60(6A)		•	CA_n260 O		2600	0

CA_n260(7A-O)	-			(CA_n260(7	A)			CA_n26		2950	0
CA_n260(8A-O)	-				CA_n2	260(8A)			1 00	CA_n2 60O	2950	0
CA_n260(4A-2O)	-		CA n	260(4A)		CA_n26	60(20)				2000	0
CA_n260(4A-2Q)	-			260(4A)		CA_n26					2400	0
CA_n260(3A-3O)	-	C/	A_n260(3			CA_n260(3C					1800	0
CA_n260(A-G-O)	-	n260A		CA_n260 O							800	0
CA_n260(A-G-20)	-	n260A	CA_n2 60G	CA_n26	60(20)						1000	0
CA_n260(2A-G-O)	-	CA_n26	0(2A)	CA_n260 G	CA_n26 0O						1200	0
CA_n260(A-2G-O)	-	n260A	CA_r	n260(2G)	CA_n26 0O						1000	0
CA_n260(A-3O)	-	n260A		CA_n260(30	Ö)						1000	0
CA_n260(3A-O)	-	C/	A_n260(3	A)	CA_n26 0O						1400	0
CA_n260(3A-O-P)	CA_n260O CA_n260P	C/	4_n260(3	A)	CA_n26 0O	CA_n260 P					1700	0
CA_n260(A-4O)		n260A		CA_n	260(40)						1200	0
CA_n260(2A-4O)	-	CA n26	0(2A)	_	CA_n2	60(40)					1600	0
CA_n260(3A-4O)	-	C/	A_n260(3	A)	_	ĆA n2	260(40)				2000	0
CA_n260(4A-4O)	-		CA_n	260(4A)			CÁ_n2	260(4O)			2400	0
CA_n260(5A-4O)	-			CA_n260(5/	A)			CA_n26	0(40)		2800	0
CA_n260(A-P)	-	n260A	CA_n2 60P								700	0
CA_n260(A-3P)	-	n260A		CA_n260(3	P)						1300	0
CA_n260(A-4P)	-	n260A		CA_n	260(4P)						1600	0
CA_n260(A-P-Q)	CA_n260P CA_n260Q	n260A	CA_n2 60P	CA_n260 Q							1100	0
CA_n260(2A-P)	-	CA_n26	0(2A)	CA_n260 P							1100	0
CA_n260(3A-P)	-	C/	A_n260(3	A)	CA_n26 0P						1500	0
CA_n260(4A-P)	-		CA_n	260(4A)		CA_n260 P					1900	0
CA_n260(5A-P)	-			CA_n260(5/	A)		CA_n26 0P				2300	0
CA_n260(6A-P)	-			CA_n2	260(6A)			CA_n260 P			2700	0
CA_n260(A-2P)	-	n260A	CA, r	n260(2P)							1000	0
CA_n260(2A-2P)	-	CA_n26		CA_n2	60(2P)						1400	0
CA_n260(2A-3P)	-	CA_n26			CA_n260(3F	P)					1700	0
CA_n260(2A-4P)	-	CA_n26			CA_n2	60(4P)	•				2000	0
CA_n260(3A-2P)	-	C/	A_n260(3	A)	CA_n	260(2P)					1800	0

CA_n260(4A-2P)	-		CA_n	260(4A)		CA_n26	0(2P)					2200	0
CA_n260(5A-2P)	-			CA_n260(5/	A)		ĆA n2	260(2P)				2600	0
CA_n260(5A-2O)	-			CA_n260(5/				260(20)				2400	0
CA_n260(6A-2O)	-				260(6A)	L			60(20)			2800	0
CA_n260(5A-3O)	-			CA_n260(5/				CA_n260(30				2600	0
CA_n260(6A-3O)	-				260(6A)	L			A_n260(30))		2950	0
CA_n260(7A-2O)	-				CA_n260(7	(A)	l			260(20)		2950	0
CA_n260(7A-3O)	-				CA_n260(7					A_n260(3	0)	2950	0
CA_n260(6A-2P)	-				260(6A)	, ,,		CA_n2		<u> </u>	Ĭ	2950	0
CA_n260(8A-2O)	-			<u> </u>		260(8A)		<u> </u>	(L1)	CA n	260(20)	2550	0
CA_n260(A-Q)	-	n260A	CA_n2							<u> </u>		800	0
0/1_11200(/ t Q)		1120071	60Q										
CA_n260(A-2Q)	_	n260A		n260(2Q)								1200	0
CA_n260(2A-Q)	-	CA_n260		CA_n260								1200	0
0/1_1/200(Z/(Q)		0/1_11200	(271)	Q Q								1200	
CA_n260(2A-2Q)	-	CA_n260	(2A)	CA_n26	60(2Q)							1600	0
CA_n260(3A-Q)	-		_n260(3		CA_n26							1600	0
0/ (_/\200(0/ \ \a)			00(0		0Q							1000	
CA_n260(3A-2Q)	-	CA	_n260(3	3A)	CA n	260(2Q)						2000	0
CA_n260(4A-Q)	-	5 7 (260(4A)		CA_n260						2000	0
0/1_11200(1/1 Q)			O/ (_I)	200(17 1)		Q Q						2000	
CA_n260(D-2G)	-	CA_n260 D	CA_ı	n260(2G)								800	0
CA_n260(2D-O)	-	CA_n260	(2D)	CA_n260 O								1000	0
CA_n260(D-2O)	-	CA_n260 D	CA_ı	n260(2O)								800	0
CA_n260(A-I)	CA_n260I		CA_n2 60I									800	0
CA_n260(D-G)	CA_n260D CA_n260G	CA_n260 D	CA_n2 60G									600	0
CA_n260(D-H)	CA_n260D CA_n260H	CA_n260 D	CA_n2 60H									700	0
CA_n260(D-I)	CA_n260D CA_n260I		CA_n2 60I									800	0
CA_n260(D-O)	CA_n260D CA_n260O		CA_n2 60O									600	0
CA_n260(D-P)	CA_n260D CA_n260P		CA_n2 60P									700	0
CA_n260(D-Q)	CA_n260D CA_n260Q	CA_n260 D	CA_n2 60Q									800	0
CA_n260(E-O)	CA_n260E CA_n260O	CA_n260 O	CA_n2 60E									800	0
CA_n260(E-P)		CA_n260E										800	0

	CA_n260E CA_n260P	CA_r							ĺ	
CA_n260(E-Q)	CA_n260E	CA_n260E CA_r						10	00	0
, ,	CA_n260Q	600	Q							U
CA_n260(G-H)	CA_n260G CA_n260H	CA_n260 CA_r G 60H						50	00	0
CA_n260(G-I)	CA_n260G CA_n260I	CA_n260 CA_r G 60I	n2					60	00	0
CA_n260(G-O)	-	CA_n260 CA_r G 600						40	00	0
CA_n260(G-2O)	-	CA_n260 CA	A_n260(2O)					60	00	0
CA_n260(2G-O)	-	CA_n260(2G)	CA_n260 O					60	00	0
CA_n260(2G-2O)	-	CA_n260(2G)	CA_n2	60(2O)				80	00	0
CA_n260(G-3O)	-	CA_n260 G	CA_n260(3	O)				80	00	0
CA_n260(3G-O)	-	CA_n260	O(3G)	CA_n26 0O				80	00	0
CA_n260(2G-3O)	-	CA_n260(2G)		CA_n260(3	BO)			10	00	0
CA_n260(G-4O)	-	CA_n260 G	CA_n	260(40)				10	00	0
CA_n260(2G-4O)	-	CA_n260(2G)		CA_n	260(4O)			12	00	0
CA_n260(4G-O)	-	CA	_n260(4G)		CA_n260 O			10	00	0
CA_n260(H-O)	-	CA_n260 CA_r H 600	n2					50	00	0
CA_n260(2H-O)	-	CA_n260(2H)	CA_n260 O					80	00	0
CA_n260(O-2P)	-	CA_n260 C/	A_n260(2P)					80	00	0
CA_n260(O-2Q)	-	CA_n260 CA	A_n260(2Q)					10	00	0
CA_n260(O-P)	-	CA_n260 CA_r O 60F	n2			<u>.</u>		50	00	0
CA_n260(2O-P)	-	CA_n260(2O)	CA_n					70		0
CA_n260(2O-2P)	-	CA_n260(2P)	CA_n2	60(2O)				10		0
CA_n260(O-Q)	-	CA_n260 CA_r O 600						60	00	0
CA_n260(2O-Q)	-	CA_n260(2O)	CA_n260 Q					80	00	0
CA_n260(2O-2Q)	-	CA_n260(2O)	CA_n2	60(2Q)				12	00	0
CA_n260(P-Q)	-	CA_n260P CA_r 600	12					70		0
CA_n261(A-D)	-	n261A CA_r 610						80	00	0

CA_n261(A-2D)	-	n261A	CA_n2	61(2D)	1	1				800	0
CA_n261(A-D-H)	-	n261A	CA_n2 61D	CA_n261 H						800	0
CA_n261(A-D-O)	-	n261A		CA_n261 O						800	0
CA_n261(A-D-2O)	-	n261A	CA_n2 61D	CA_n26	61(20)					800	0
CA_n261(A-G)	CA_n261G	n261A	CA_n2 61G							600	0
CA_n261(A-G-H)	CA_n261G CA_n261H	n261A		CA_n261 H						800	0
CA_n261(A-G-I)	CA_n261G CA_n261H CA_n261I	n261A		CA_n261I						800	0
CA_n261(A-G-O)	-	n261A	CA_n2 61G	CA_n261 O						800	0
CA_n261(A-G-2O)	-	n261A	CA_n2 61G	CA_n26	61(20)					800	0
CA_n261(A-2G-O)	-	n261A	CA_n2	61(2G)	CA_n26 10					800	0
CA_n261(A-2G- 2O)	-	n261A	CA_n2	61(2G)		261(20)				800	0
CA_n261(A-3G)	-	n261A	С	A_n261(30	G)					800	0
CA_n261(À-3G-Ó)	-	n261A		A_n261(3		CA_n261 O				800	0
CA_n261(A-2G)	CA_n261G	n261A	CA_n2	61(2G)						800	
CA_n261(A-4G)	-	n261A			261(4G)	•				800	0
CA_n261(A-H)	CA_n261G CA_n261H	n261A	CA_n2 61H							700	0
CA_n261(A-2H)	-	n261A	CA_n2	61(2H)						800	0
CA_n261(A-H-I)	-	n261A	CA_n2 (61H	CA_n261I						800	0
CA_n261(A-I)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61I							800	0
CA_n261(A-2I)	-	n261A	CA_n2	261(21)						800	0
CA_n261(A-J)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61J							700	0
CA_n261(A-K)	CA_n261G CA_n261H CA_n261I	n261A	CA_n2 61K							800	0
CA_n261(A-O)	-	n261A	CA_n2 610							600	0
CA_n261(A-2O)	-	n261A	CA_n2							800	0
CA_n261(A-3O)	-	n261A	С	A_n261(30	O)					800	0

CA_n261(A-4O)	-	n261A		CA_n	261(4O)					800	0
CA_n261(A-50)	-	n261A		CA_n261						800	0
CA_n261(A-6O)	-	n261A		CA_n261(6O)		800	0				
CA_n261(A-70)	-	n261A				CA_n261(70)			800	0
CA_n261(A-P)	-	n261A	CA_n2 61P							700	0
CA_n261(A-2P)	-	n261A	CA_	n261(2P)						800	0
CA_n261(A-Q)	-	n261A	CA_n2 61Q							800	0
CA_n261(A-2Q)	-	n261A	CA ı	n261(2Q)						800	0
CA_n261(2A-G)	CA_n261G	CA_n26	1(2A)	CA_n261 G						800	0
CA_n261(2A-H)	CA_n261G CA_n261H	CA_n26	1(2A)	CA_n261 H						800	0
CA_n261(2A-I)	CA_n261G CA_n261H CA_n261I	CA_n26	1(2A)	CA_n261I						800	0
CA_n261(3A-G)	CA_n261G	C	A_n261(3	A)	CA_n26 1G					800	0
CA_n261(D-G)	CA_n261D CA_n261G	CA_n261 D	CA_n2 61G							600	0
CA_n261(D-H)	CA_n261D CA_n261H	CA_n261 D	CA_n2 61H							700	0
CA_n261(D-I)	CA_n261D CA_n261I	CA_n261 D	CA_n2 61I							800	0
CA_n261(D-O)	CA_n261D CA_n261O	CA_n261 D	CA_n2 610							600	0
CA_n261(D-2O)	-	CA_n261 D	CA_i	n261(2O)						800	0
CA_n261(D-P)	CA_n261D CA_n261P	CA_n261 D	CA_n2 61P							700	0
CA_n261(D-Q)	CA_n261D CA_n261Q	CA_n261 D	CA_n2 61Q							800	0
CA_n261(E-O)	CA_n261E CA_n261O	CA_n261E	CA_n2 610							800	0
CA_n261(E-P)	CA_n261E CA_n261P	CA_n261E	CA_n2 61P							800	0
CA_n261(E-Q)	CA_n261E CA_n261Q	CA_n261E	CA_n2 61Q							800	0
CA_n261(G-I)	CA_n261G CA_n261H CA_n261I	CA_n261 G	CA_n2 61I							600	0
CA_n261(G-H)	CA_n261G CA_n261H	CA_n261 G	CA_n2 61H							500	0

CA_n261(2G-2O)	-	CA_n261(2G)	n261(2O)					800	0
CA_n261(G-O)	-	CA_n261						400	0
CA =261(C 2O)		G 610 CA n361(30)						600	0
CA_n261(G-2O)	-	CA_n261						600	0
CA_n261(2G-O)	-	CA_n261(2G)	51					600	0
CA_n261(3G-O)	-	CA_n261(3G)	CA_n26 10					800	0
CA_n261(H-I)	CA_n261G CA_n261H CA_n261I	CA_n261						700	0

NOTE 1: Void

NOTE 2: Void

NOTE 3: Channel bandwidth per operating band defined in Table 5.3.5-1

NOTE 4: Configurations for intra-band contiguous CA defined in Table 5.5A.1-1

NOTE 5: Configurations for intra-band non-contiguous CA defined in Table 5.5A.2-1

NOTE 6: Void

NOTE 7: Unless otherwise stated, BCS0 is referred in each constituent CA configuration.

NOTE 8: $\Sigma(BW_{Channel,block})$ denotes the maximum total bandwidth from the summation of the sub-block bandwidths and shall be less than the bandwidth of the operating band.

5.5A.3 Configurations for inter-band CA

Table 5.5A.3-1: NR CA configurations for inter-band CA

NR CA configuration	Uplink CA configuration	NR Band	Char	Channel bandwidth (MHz) (NOTE 1)			Bandwidth combination set
			50	100	200	400	
CA_n260A- n261A	-	n260	50	100	200	400	0
		n261	50	100	200	400	
NOTE 1: The SCS	S of each channel	bandwic	th for N	R band r	efers to	Table 5.3	3.5-1.

5.5D Configurations for UL MIMO

The requirements specified in clause 5.5 are applicable to UE supporting UL MIMO.

6 Transmitter characteristics

6.1 General

Unless otherwise stated, the transmitter characteristics are specified over the air (OTA) with a single or multiple transmit chains

Unless otherwise stated, for power class 3 UEs, the beam correspondence side condition for SSB and CSI-RS specified in clause 6.6.4 shall apply to the transmission tests.

Transmitter requirements for CA operation apply only when the DMRS initialization parameters (including the case when the UE applies cell ID as DMRS scrambling ID) are different across all CCs. The UE may use higher MPR values outside this limitation.

For a UE that supports 'UL full power transmission' and is configured to transmit a single layer with *nrofSRS-Ports* = 2, the requirements for UL MIMO operation apply only when it is configured for any of its declared full power modes in IE *FullPowerTransmission-r16* (as defined in TS 38.331[13]).

For a UE configured to transmit 2 layers, transmitter requirements for UL MIMO operation apply when the UE transmits on 2 ports on the same CDM group. The UE may use higher MPR values outside this limitation.

6.2 Transmitter power

6.2.1 UE maximum output power

6.2.1.0 General

NOTE: Power class 1, 2, 3, and 4 are specified based on the assumption of certain UE types with specific device architectures. The UE types can be found in Table 6.2.1.0-1.

 UE Power class
 UE type

 1
 Fixed wireless access (FWA) UE

 2
 Vehicular UE

 3
 Handheld UE

 4
 High power non-handheld UE

Table 6.2.1.0-1: Assumption of UE Types

Power class 3 is default power class.

6.2.1.1 UE maximum output power for power class 1

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.1-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.1-1: UE minimum peak EIRP for power class 1

Operating band	Min peak EIRP (dBm)	
n257	40.0	
n258	40.0	
n260	38.0	
n261	40.0	
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

The maximum output power values for TRP and EIRP are found in Table 6.2.1.1-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.1-2: UE maximum output power limits for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.1-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2.1.1-3: UE spherical coverage for power class 1

Operating band		Min EIRP at 85 %-tile CDF (dBm)			
n2	:57	32.0			
n2	58	32.0			
n260		30.0			
n2	61	32.0			
NOTE 1:	Minimum EIRP at 85 %-tile CDF is defined as the lower limit without tolerance				
NOTE 2:	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.				

6.2.1.2 UE maximum output power for power class 2

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.2-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.2-1: UE minimum peak EIRP for power class 2

Operating band	Min peak EIRP (dBm)	
n257	29	
n258	29	
n261	29	
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

The maximum output power values for TRP and EIRP are found in Table 6.2.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.2-2: UE maximum output power limits for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

The minimum EIRP at the 60th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.2-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2.1.2-3: UE spherical coverage for power class 2

Operating band	Min EIRP at 60 %-tile CDF (dBm)		
n257	18.0		
n258	18.0		
n261	18.0		
	Minimum EIRP at 60 %-tile CDF is defined as the lower limit without tolerance		
under norr	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.		

6.2.1.3 UE maximum output power for power class 3

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.3-1. The requirement is verified with the test metric of total component of EIRP (Link=TX beam peak direction, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 6.2.1.3-1 and Table 6.2.1.3-4.

Table 6.2.1.3-1: UE minimum peak EIRP for power class 3

Operati	ng band	Min peak EIRP (dBm)	
n2	257	22.4	
n2	258	22.4	
n2	259	18.7	
n2	260	20.6	
n2	261	22.4	
NOTE 1:	Minimum peak EIRP is defined as the lower limit without tolerance		
NOTE 2:	Void		

The maximum output power values for TRP and EIRP are found on the Table 6.2.1.3-2. The max allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and the total component of EIRP (Link=TX beam peak direction, Meas=Link angle.

Table 6.2.1.3-2: UE maximum output power limits for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43
n260	23	43
n261	23	43

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.3-3 below. The requirement is verified with the test metric of the total component of EIRP (Link=Beam peak search grids, Meas=Link angle). The requirement for the UE which supports a single FR2 band is specified in Table 6.2.1.3-3. The requirement for the UE which supports multiple FR2 bands is specified in both Table 6.2.1.3-3 and Table 6.2.1.3-4.

Table 6.2.1.3-3: UE spherical coverage for power class 3

Operating band	Min EIRP at 50 %-tile CDF (dBm)
n257	11.5
n258	11.5
n259	5.8
n260	8
n261	11.5

NOTE 1: Minimum EIRP at 50 %-tile CDF is defined as the

lower limit without tolerance

NOTE 2: Void

NOTE 3: The requirements in this table are verified only under normal temperature conditions as defined in Annex

E.2.1.

For the UEs that support multiple FR2 bands, minimum requirement for peak EIRP and EIRP spherical coverage in Tables 6.2.1.3-1 and 6.2.1.3-3 shall be decreased per band, respectively, by the peak EIRP relaxation parameter $\Delta MB_{P,n}$ and EIRP spherical coverage relaxation parameter $\Delta MB_{S,n}$, as defined in Table 6.2.1.3-4..

Table 6.2.1.3-4: UE multi-band relaxation factors for power class 3

Band	ΔMB _{P,n} (dB)	ΔMB _{S,n} (dB)
n257	0.7^{3}	0.7^{3}
n258	0.6	0.7
n259	0.5	0.4
n260	0.5 ¹	0.4 ¹
n261	$0.5^{2,4}$	0.74

Note 1: n260 peak and spherical relaxations are 0 dB for UE that exclusively supports n261+n260

Note 2: n261 peak relaxation is 0 dB for UE that exclusively supports n261+n260

Note 3: n257 peak and spherical relaxations are 0 dB for UE that exclusively supports n261+n257

Note 4: n261 peak and spherical relaxations are 0 dB for UE that exclusively supports n261+n257

6.2.1.4 UE maximum output power for power class 4

The following requirements define the maximum output power radiated by the UE for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. The period of measurement shall be at least one sub frame (1ms). The minimum output power values for EIRP are found in Table 6.2.1.4-1. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.4-1: UE minimum peak EIRP for power class 4

Operating band	Min peak EIRP (dBm)
n257	34
n258	34
n260	31
n261	34
	34

NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance

The maximum output power values for TRP and EIRP are found in Table 6.2.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2.1.4-2: UE maximum output power limits for power class 4

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

The minimum EIRP at the 20th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2.1.4-3 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2.1.4-3: UE spherical coverage for power class 4

Operating band	Min EIRP at 20 %-tile CDF (dBm)		
n257	25		
n258	25		
n260	19		
n261	25		
	EIRP at 20 %-tile CDF is defined as imit without tolerance		
under norr	The requirements in this table are verified only under normal temperature conditions as defined in Annex E.2.1.		

6.2.2 UE maximum output power reduction

6.2.2.0 General

The requirements in clause 6.2.2 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. A UE may reduce its maximum output power due to modulation orders, transmit bandwidth configurations, waveform types and narrow allocations. This Maximum Power Reduction (MPR) is defined in clauses below. The allowed MPR for SRS, PUCCH formats 0, 1, 3 and 4, and PRACH shall be as specified for QPSK modulated DFT-s-OFDM of equivalent RB allocation. The allowed MPR for PUCCH format 2 shall be as specified for QPSK modulated CP-OFDM of equivalent RB allocation. When the maximum output power of a UE is modified by MPR, the power limits specified in clause 6.2.4 apply.

For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in clause 6.2A.2 apply.

For all power classes, the waveform defined by BW = 100 MHz, SCS = 120 kHz, DFT-S-OFDM QPSK, 20RB23 is the reference waveform with 0 dB MPR and is used for the power class definition.

6.2.2.1 UE maximum output power reduction for power class 1

For power class 1, MPR for contiguous allocations is defined as:

 $MPR = max(MPR_{WT}, MPR_{narrow})$

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$, when $BW_{alloc,RB} \le 1.44 \text{ MHz}$, $MPR_{narrow} = 10 \text{ dB}$, when $1.44 \text{ MHz} < BW_{alloc,RB} \le 10.8 \text{ MHz}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in table 5.3.2-1, and waveform types. MPR_{WT} is defined in Tables 6.2.2.1-1 and 6.2.2.1-2.

Table 6.2.2.1-1 MPR_{WT} for power class 1, BW_{channel} \leq 200 MHz

Modulation		MPRwt (dB), BW _{channel} ≤ 200 MHz			
		Outer RB allocations	Inner RB a	allocations	
			Region 1	Region 2	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0	
ĺ	QPSK	≤ 6.5	0.0	≤ 3.0	
16 QAM		≤ 6.5	≤ 4.0	≤ 4.0	
	64 QAM	≤ 6.5	≤ 5.0	≤ 5.0	
CP-OFDM	QPSK	≤ 7.0	≤ 4.5	≤ 4.5	
	16 QAM	≤ 7.0	≤ 5.5	≤ 5.5	
	64 QAM	≤ 7.5	≤ 7.5	≤ 7.5	

Table 6.2.2.1-2 MPR_{WT} for power class 1, BW_{channel} = 400 MHz

Modulation		MPR _{WT} (dB), BW _{channel} = 400 MHz			
		Outer RB allocations	Inner RB a	llocations	
			Region 1	Region 2	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5	0.0	≤ 3.0	
	QPSK	≤ 6.5	0.0	≤ 3.5	
	16 QAM	≤ 6.5	≤ 4.5	≤ 4.5	
	64 QAM	≤ 6.5	≤ 6.5	≤ 6.5	
CP-OFDM	QPSK	≤ 7.0	≤ 5.0	≤ 5.0	
16 QAM		≤ 7.0	≤ 6.5	≤ 6.5	
	64 QAM	≤ 9.0	≤ 9.0	≤ 9.0	

Where the following parameters are defined to specify valid RB allocation ranges for the RB allocations regions in Tables 6.2.2.1-1 and 6.2.2.1-2:

N_{RB} is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

$$RB_{end} = RB_{Start} + L_{CRB} - 1$$

 $RB_{Start,Low} = Max(1, Floor(L_{CRB}/2))$

$$RB_{Start, High} = N_{RB} - RB_{Start, Low} - L_{CRB}$$

An RB allocation is an Outer RB allocation if

$$RB_{Start} < RB_{Start,Low} \; OR \; RB_{Start} > RB_{Start,High} \; OR \; L_{CRB} > Ceil(N_{RB}/2)$$

An RB allocation belonging to table 6.2.2.1-1 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/3 N_{RB}) AND RB_{end} < Ceil(2/3 N_{RB})$$

An RB allocation belonging to table 6.2.2.1-2 is a Region 1 inner RB allocation if

$$RB_{\text{start}} \geq Ceil(1/4\ N_{RB})\ AND\ RB_{\text{end}} < Ceil(3/4\ N_{RB})\ AND\ L_{CRB} \leq Ceil(1/4\ N_{RB})$$

An RB allocation is a Region 2 inner allocation if it is NOT an Outer allocation AND NOT a Region 1 inner allocation For the UE maximum output power modified by MPR, the power limits specified in clause 6.2.4 apply.

6.2.2.2 UE maximum output power reduction for power class 2

For power class 2, MPR specified in clause 6.2.2.3 applies.

Table 6.2.2.2-1: Void

6.2.2.3 UE maximum output power reduction for power class 3

For power class 3, MPR for contiguous allocations is defined as:

$$MPR = max(MPR_{WT}, MPR_{narrow})$$

For transmission bandwidth configuration less than or equal to 200MHz, and $0 \le RB_{start} < Ceil(1/3\ N_{RB})$ or $Ceil((2/3N_{RB})-L_{CRB}) < RB_{start} \le N_{RB}-L_{CRB}$:

- MPR_{narrow} = 2.5 dB, when BW_{alloc,RB} is less than or equal to 1.44 MHz,
- MPR_{narrow} = 2.0 dB, when $1.44 \text{ MHz} < \text{BW}_{\text{alloc,RB}} <= 4.32 \text{ MHz}$,
- otherwise $MPR_{narrow} = 0 dB$.

 MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types. MPR_{WT} is defined in Table 6.2.2.3-1.

Modulation MPRwT, BWchannel ≤ 200 MHz Inner RB allocations, **Edge RB allocations** Region 1 DFT-s-OFDM Pi/2 BPSK 0.0 ≤ 2.0 QPSK 0.0 ≤ 2.0 **16 QAM** ≤ 3.0 ≤ 3.5 64 QAM ≤ <u>5</u>.0 ≤ 5.5 CP-OFDM QPSK ≤ 3.5 ≤ 4.0 16 QAM ≤ 5.0 ≤ 5.0 64 QAM ≤ 7.5 ≤ 7.5

Table 6.2.2.3-1 MPR_{WT} for power class 3, BWchannel ≤ 200 MHz

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Table 6.2.2.3-1:

- $RB_{Start,Low} = max(1, L_{CRB})$, where max() indicates the largest value of all arguments.
- $RB_{Start,High} = N_{RB} RB_{Start,Low} L_{CRB}$

An RB allocation belonging to table 6.2.2.3-1 is a Region 1 inner RB allocation if:

- $RB_{Start,Low} \le RB_{Start} \le RB_{Start,High}$, and $L_{CRB} \le ceil(N_{RB}/3)$, where ceil(x) is the smallest integer greater than or equal to x.

For transmission bandwidth configuration equal to 400MHz,

 $MPR_{narrow} = 2.5 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz, and $0 \le RB_{start} < Ceil(1/3 N_{RB})$ or $Ceil(2/3N_{RB}) \le RB_{start} \le N_{RB}$ -L_{CRB}, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

MPR_{WT} is the maximum power reduction due to modulation orders, transmission bandwidth configurations listed in Table 5.3.2-1, and waveform types. MPR_{WT} is defined in Table 6.2.2.3-2.

Table 6.2.2.3-2 MPR_{WT} for power class 3, BW_{channel} = 400 MHz

Modulation		MPRwt, BWchannel = 400 MHz		
		Inner RB allocations, Region 1	Edge RB allocations	
DFT-s-OFDM	Pi/2 BPSK	0.0	≤ 3.0	
	QPSK	0.0	≤ 3.0	
	16 QAM	≤ 4.5	≤ 4.5	
	64 QAM	≤ 6.5	≤ 6.5	
CP-OFDM	QPSK	≤ 5.0	≤ 5.0	
	16 QAM	≤ 6.5	≤ 6.5	
	64 QAM	≤ 9.0	≤ 9.0	

Where the following parameters are defined to specify valid RB allocation ranges for RB allocations in Table 6.2.2.3-2:

N_{RB} is the maximum number of RBs for a given Channel bandwidth and sub-carrier spacing defined in Table 5.3.2-1.

$$RB_{end} = RB_{Start} + L_{CRB} - 1$$

An RB allocation belonging to table 6.2.2.3-2 is a Region 1 inner RB allocation if

$$RB_{start} \ge Ceil(1/4 N_{RB}) AND RB_{end} < Ceil(3/4 N_{RB}) AND L_{CRB} \le Ceil(1/4 N_{RB})$$

For all transmission bandwidth configurations, an RB allocation is an Edge allocation if it is NOT a Region 1 inner allocation.

6.2.2.4 UE maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2.2.3 applies.

Table 6.2.2.4-1: Void

6.2.3 UE maximum output power with additional requirements

6.2.3.1 General

Additional emission requirements can be signalled by the network. Each additional emission requirement is associated with a unique network signalling (NS) value indicated in RRC signalling by an NR frequency band number of the applicable operating band and an associated value in the field *additionalSpectrumEmission*. Throughout this specification, the notion of indication or signalling of an NS value refers to the corresponding indication of an NR frequency band number of the applicable operating band (the IE field *freqBandIndicatorNR*) and an associated value of *additionalSpectrumEmission* in the relevant RRC information elements.

To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in clause 6.2.1. Unless stated otherwise, an A-MPR of 0 dB shall be used.

Table 6.2.3.1-1 specifies the additional requirements with their associated network signalling values and the allowed A-MPR and applicable operating band(s) for each NS value. The mapping of NR frequency band numbers and values of the *additionalSpectrumEmission* to network signalling labels is specified in Table 6.2.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2.2.

Table 6.2.3.1-1: Additional maximum power reduction (A-MPR)

Network Signalling label	Requirements (clause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (N _{RB})	A-MPR (dB)	
NS_200					N/A	
NS_201 (NOTE 1)	6.5.3.2.2	n258			6.2.3.2	
NS_202	6.5.3.2.3	n257, n258	50, 100, 200, 400	Table 5.3.2-1	6.2.3.3	
NS_203	6.5.3.2.4	n258	50, 100, 200, 400	Table 5.3.2-1	6.2.3.4	
NOTE 1: NS_201 is obsolete, the associated additional spurious emission requirements are						

NOTE 1: NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.

Table 6.2.3.1-2: Mapping of Network Signalling label

NR Band	Value of additionalSpectrumEmission (NOTE 1)							
	0	1	2	3	4	5	6	7
n257	NS_200	NS_202						
n258	NS_200	NS_201 (NOTE 2)	NS_202	NS_203				
n259	NS_200							
n260	NS_200							
n261	NS_200							

NOTE 1: additional Spectrum Emission corresponds to an information element of the same name defined in sub-clause 6.3.2 of TS 38.331 [13].

NOTE 2: NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.

6.2.3.2 Void

6.2.3.2.1 Void

Table 6.2.3.2.1-1: (Void)

6.2.3.2.2 Void

Table 6.2.3.2.2-1: (Void)

6.2.3.2.3 Void

Table 6.2.3.2.3-1: (Void)

6.2.3.2.4 Void

6.2.3.3 A-MPR for NS_202

6.2.3.3.1 A-MPR for NS_202 for power class 1

For power class 1, A-MPR for NS_202 shall be 11.0 dB.

6.2.3.3.2 A-MPR for NS_202 for power class 2

For power class 2, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.3.3 A-MPR for NS 202 for power class 3

For power class 3, A-MPR for NS_202 shall be 1.0 dB.

6.2.3.3.4 A-MPR for NS_202 for power class 4

For power class 4, A-MPR for NS_202 specified in clause 6.2.3.3.3 applies.

6.2.3.4 A-MPR for NS 203

6.2.3.4.1 A-MPR for NS_203 for power class 1

For power class 1, A-MPR for NS_203 shall be 3.0 dB if Offset frequency < BW_{channel}, 0.0 dB otherwise. The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the channel bandwidth.

6.2.3.4.2 A-MPR for NS_203 for power class 2

For power class 2, A-MPR for NS 203 specified in subclause 6.2.3.4.3 applies.

6.2.3.4.3 A-MPR for NS_203 for power class 3

For power class 3, A-MPR for NS_203 shall be 0 dB.

6.2.3.4.4 A-MPR for NS_203 for power class 4

For power class 4, A-MPR for NS_203 specified in subclause 6.2.3.4.3 applies.

6.2.4 Configured transmitted power

The UE can configure its maximum output power. The configured UE maximum output power $P_{CMAX,f,c}$ for carrier f of a serving cell c is defined as that available to the reference point of a given transmitter branch that corresponds to the reference point of the higher-layer filtered RSRP measurement as specified in TS 38.215 [11].

The configured UE maximum output power $P_{CMAX,f,c}$ for carrier f of a serving cell c shall be set such that the corresponding measured peak EIRP $P_{UMAX,f,c}$ is within the following bounds

$$\begin{split} P_{Powerclass} + \Delta P_{IBE} - MAX(MAX(MPR_{f,c}, A-MPR_{f,c})) + \Delta MB_{P,n}, P-MPR_{f,c}) - MAX\{T(MAX(MPR_{f,c}, A-MPR_{f,c})), T(P-MPR_{f,c})\} \leq P_{UMAX,f,c} \leq EIRP_{max} \end{split}$$

while the corresponding measured total radiated power P_{TMAX,f,c} is bounded by

$$P_{TMAX,f,c} \leq TRP_{max}$$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2.1, EIRP_{max} the applicable maximum EIRP as specified in sub-clause 6.2.1, MPR_{f,c} as specified in sub-clause 6.2.2, A-MPR_{f,c} as specified in sub-clause 6.2.3, $\Delta MB_{P,n}$ the peak EIRP relaxation as specified in clause 6.2.1 and TRP_{max} the maximum TRP for the UE power class as specified in sub-clause 6.2.1. ΔP_{IBE} is 1.0 dB if UE declares support for mpr-PowerBoost-FR2-r16, UL transmission is QPSK, MPR_{f,c} = 0 and when NS_200 applies and the network configures the UE to operate with mpr-PowerBoost-FR2-r16otherwise ΔP_{IBE} is 0.0 dB. The requirement is verified in beam peak direction.

maxUplinkDutyCycle-FR2, as defined in TS 38.306 [14], is a UE capability to facilitate electromagnetic power density exposure requirements. This UE capability is applicable to all FR2 power classes.

If the field of UE capability maxUplinkDutyCycle-FR2 is present and the percentage of uplink symbols transmitted within any 1 s evaluation period is larger than maxUplinkDutyCycle-FR2, the UE follows the uplink scheduling and can apply P-MPR_{f,c}.

If the field of UE capability *maxUplinkDutyCycle-FR2* is absent, the compliance to electromagnetic power density exposure requirements are ensured by means of scaling down the power density or by other means.

 $P ext{-MPR}_{f,c}$ is the power management maximum output power reduction. The UE shall apply $P ext{-MPR}_{f,c}$ for carrier f of serving cell c only for the cases described below. For UE conformance testing $P ext{-MPR}_{f,c}$ shall be 0 dB.

- a) ensuring compliance with applicable electromagnetic power density exposure requirements and addressing unwanted emissions / self desense requirements in case of simultaneous transmissions on multiple RAT(s) for scenarios not in scope of 3GPP RAN specifications;
- b) ensuring compliance with applicable electromagnetic power density exposure requirements in case of proximity detection is used to address such requirements that require a lower maximum output power.
- NOTE 1: P-MPR_{f,c} was introduced in the $P_{CMAX,f,c}$ equation such that the UE can report to the gNB the available maximum output transmit power. This information can be used by the gNB for scheduling decisions.
- NOTE 2: P-MPR_{f,c} and *maxUplinkDutyCycle-FR2* may impact the maximum uplink performance for the selected UL transmission path.
- NOTE 3: MPE P-MPR Reporting capability *tdd-MPE-P-MPR-Reporting-r16*, as defined in TS 38.306 [14], is used to report P-MPR_{f,c} when the reporting conditions configured by gNB are met. This UE capability is applicable to all FR2 power classes.

The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB) is specified in Table 6.2.4-1.

Operating Band ΔP (dB) Tolerance T(∆P) (dB) n257, n258, n259, 0 $\Delta P = 0$ n260, n261 $0 < \Delta P \le 2$ 1.5 $2 < \Delta P \le 3$ 2.0 $3 < \Delta P \le 4$ 3.0 $4 < \Delta P \le 5$ 4.0 5.0 $5 < \Delta P \le 10$ 10 < ΔP ≤ 15 7.0 $15 < \Delta P \le X$ 8.0

Table 6.2.4-1: P_{UMAX,f,c} tolerance

NOTE: X is the value such that $P_{umax,f,c}$ lower bound, $P_{Powerclass}$ - $\Delta P - T(\Delta P)$ = minimum output power specified in clause 6.3.1

6.2A Transmitter power for CA

6.2A.1 UE maximum output power for CA

For downlink intra-band contiguous and non-contiguous carrier aggregation with a single uplink component carrier configured in the NR band, the maximum output power is specified in clause 6.2.1.

For uplink intra-band contiguous and non-contiguous carrier aggregation for any CA bandwidth class, the maximum output power is specified in clause 6.2.1.

Power class 3 is default power class.

6.2A.2 UE maximum output power reduction for CA

6.2A.2.1 General

The UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA. In CA operation, the UE may reduce its maximum output power due to higher order modulations and transmit bandwidth configurations. This Maximum Power Reduction (MPR) is defined in clauses below. The allowed MPR for SRS, PUCCH formats 0, 1, 3 and 4, shall be as specified for QPSK modulated DFT-s-OFDM of equivalent RB allocation. The allowed MPR for PUCCH format 2, shall be as specified for QPSK modulated CP-OFDM of equivalent RB allocation.

When the maximum output power of a UE is modified by MPR, the power limits specified in clause 6.2A.4 apply.

The requirements in the following clauses are applicable to the following CA configurations:

- intra-band contiguous uplink CA, with the aggregated channel bandwidth no greater than 800 MHz.
- intra-band non-contiguous uplink CA with UL frequency separation no greater than 1400 MHz, and no more than 3 sub-blocks. A sub-block may consist of single CC or multiple contiguous CCs.
- In case the CA configuration consists of a single UL CC, MPR for contiguous UL CA applies and where necessary, BW_{channel} shall be used as BW_{channel} CA.

6.2A.2.2 Maximum output power reduction for power class 1

6.2A.2.2.1 Maximum output power reduction for power class 1 intra-band contiguous UL CA

For power class 1, MPR for intra-band contiguous UL CA with contiguous allocations within the cumulative aggregated bandwidth is defined as:

$$MPR_{C CA} = max(MPR_{WT C CA}, MPR_{narrow})$$

Where,

 $MPR_{narrow} = 14.4 \text{ dB}$, when $BW_{alloc,RB}$ is less than or equal to 1.44 MHz, $MPR_{narrow} = 10 \text{ dB}$, when 1.44 MHz < $BW_{alloc,RB} \le 10.8 \text{ MHz}$, where $BW_{alloc,RB}$ is the bandwidth of the RB allocation size.

MPR_{WT_C_CA} is the maximum power reduction due to modulation orders, transmit bandwidth configurations, and waveform types. MPR_{WT_C_CA} is defined in Table 6.2A.2.2-1.

Waveform Type		Cumulative aggregated channel bandwidth				
		< 400 MHz	≥ 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz	
DFT-s-OFDM	Pi/2 BPSK	≤ 5.5 ¹	7.7	8.2	≤ 8.7	
	QPSK	≤ 6.5 ¹	8.7	9.7	≤ 9.7	
	16 QAM	≤ 6.5	8.7	9.2	≤ 9.7	
	64 QAM	≤ 9.0	10.7	11.2	≤ 11.7	
CP-OFDM	QPSK	≤ 6.5	8.7	8.7	≤ 9.7	
	16 QAM	≤ 6.5	8.7	8.7	≤ 9.7	
	64 QAM	≤ 9.0	10.7	11.2	≤ 11.7	
NOTE 1: (Void)						

In case of a contiguous RB, DFT-s-BPSK or DFT-s-QPSK UL allocation in a single CC of a CA configuration with contiguous CCs, and whose cumulative aggregated BW \leq 400 MHz, MPR_{WT_C_CA} shall be derived instead as MAX(MPR₁, MPR₂), where:

MPR₁ shall be determined from Table 6.2.2.1-1 if CABW \leq 200 MHz, from Table 6.2.2.1-2 if CABW > 200 MHz.

MPR₂ shall be determined from Table 6.2.2.1-1 if UL BW_{channel_CA} \leq 200 MHz, from Table 6.2.2.1-2 if UL BW_{channel_CA} > 200 MHz.

and assume all UL CCs use the same SCS for the purpose of determination of inner and outer RB allocations in Table 6.2.2.1-1 and Table 6.2.2.1-2:

N_{RB} shall be chosen as the sum of N_{RB} of all constituent UL CCs in the CA configuration.

 L_{CRB} shall be chosen as $BW_{alloc,RB}$

 $RB_{start_allocatedCC} + N_{RB_unallocatedCC_low}$

RB_{start_allocatedCC} is the index of the first allocated RB in the CC with allocation

N_{RB_unallocatedCC_low} is the sum of N_{RB} in all UL CCs lower in frequency compared to the CC with allocation

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest MPR_{CCA} .

For intra-band contiguous UL CA with non-contiguous RB allocations, the following rule for MPR applies:

$$MPR = max(MPR_{C CA}, -10*A + 14.4)$$

Where:

 $A = N_{RB_alloc} / N_{RB_agg_C.}$

 $N_{RB\ alloc}$ is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs

6.2A.2.2.2 Maximum output power reduction for power class 1 intra-band non-contiguous UL

For intra-band non-contiguous UL CA, the following rule for MPR applies:

$$MPR = max(MPRNC CA, -10*A + 14.4)$$

Where:

MPR_{NC_CA} is derived from table 6.2A.2.2-1

 $A = N_{RB_alloc} / N_{RB_agg_C}$

N_{RB} alloc is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs.

Table 6.2A.2.2.1: MPR_{NC_CA} for UE power class 1

Wavefo	Cumulative	aggregated cha	annel bandwidth	(CABW)	
			≥ 400 MHz	≥ 800 MHz	> 1400 MHz
			and < 800	and ≤ 1400	and ≤ 2400
			MHz	MHz	MHz
DFT-s-OFDM	Pi/2 BPSK	≤ 6	≤ 7.7	≤ 8.2	≤ 8.7
	QPSK	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	16 QAM	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7
CP-OFDM	QPSK	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	16 QAM	≤ 7	≤ 8.7	≤ 9.2	≤ 9.7
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest MPR_{NC_CA} .

6.2A.2.3 Maximum output power reduction for power class 2

For power class 2, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

Table 6.2A.2.3-1: (Void)

6.2A.2.4 Maximum output power reduction for power class 3

6.2A.2.4.1 Maximum output power reduction for power class 3 intra-band contiguous CA

For power class 3, MPR for intra-band contiguous UL CA with contiguous allocations within the cumulative aggregated bandwidth is denoted as MPR_{C_CA} and is defined in Table 6.2A.2.4-1.

Table 6.2A.2.4-1: Maximum power reduction (MPR_{C_CA}) for UE power class 3

		Cumulative aggregated channel bandwidth (CABW)			
		≤ 400 MHz	> 400 MHz and < 800 MHz	≥ 800 MHz and ≤ 1400 MHz	> 1400 MHz and ≤ 2400 MHz
DFT-s-OFDM	Pi/2 BPSK	≤ 5.0 ¹	≤ 7.7	≤ 8.2	≤ 8.7
	QPSK	≤ 5.0 ¹	≤ 7.7	≤ 8.2	≤ 9.7
	16 QAM	≤ 6.5	≤ 8.7	≤ 9.3	≤ 9.7
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7
CP-OFDM	QPSK	≤ 5.0	≤ 7.5	≤ 8.0	≤ 9.7
	16 QAM	≤ 6.5	≤ 8.7	≤ 9.2	≤ 9.7
	64 QAM	≤ 9.0	≤ 10.7	≤ 11.2	≤ 11.7
NOTE 1: (Void).	•	•	•		

In case of a contiguous RB, DFT-s-BPSK or DFT-s-QPSK UL allocation in a single CC of a CA configuration with contiguous CCs, and whose cumulative aggregated BW \leq 400 MHz, MPR_{C_CA} shall be derived instead as MAX(MPR₁, MPR₂), where:

MPR₁ shall be determined from Table 6.2.2.3-1 if CABW \leq 200 MHz, from Table 6.2.2.3-2 if CABW > 200 MHz.

MPR₂ shall be determined from Table 6.2.2.3-1 if UL BW_{channel_CA} \leq 200 MHz, from Table 6.2.2.3-2 if UL BW_{channel_CA} \geq 200 MHz.

and assume all UL CCs use the same SCS for the purpose of determination of inner and outer RB allocations in Table 6.2.2.3-1 and Table 6.2.2.3-2:

N_{RB} shall be chosen as the sum of N_{RB} of all constituent UL CCs in the CA configuration.

 L_{CRB} shall be chosen as $BW_{alloc,RB}$

 RB_{start} shall be derived as: $RB_{start_allocatedCC} + N_{RB_unallocatedCC_low}$

RB_{start_allocatedCC} is the index of the first allocated RB in the CC with allocation

N_{RB} unallocatedCC low is the sum of N_{RB} in all UL CCs lower in frequency compared to the CC with allocation

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the highest contiguous MPR.

For intra-band contiguous UL CA with non-contiguous RB allocations, the following rule for MPR applies:

$$MPR = max(MPR_{C CA}, -10*A +7.0)$$

Where:

 $A = N_{RB_alloc} / N_{RB_agg_C}$.

 $N_{RB\ alloc}$ is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs

6.2A.2.4.2 Maximum output power reduction for power class 3 intra-band non-contiguous CA

For intra-band non-contiguous UL CA, the following rule for MPR applies:

MPR = max(MPRNC CA, -8*A + 10.0)

Where:

MPR_{NC CA} is derived from table 6.2A.2.4.2-1

 $A = N_{RB_alloc} / N_{RB_agg_C}.$

 $N_{RB\ alloc}$ is the total number of allocated UL RBs

 $N_{RB_agg_C}$ is the number of the aggregated RBs within the fully allocated cumulative aggregated channel bandwidth assuming lowest SCS among all configured CCs.

Cumulative aggregated channel bandwidth (CABW) ≤ 400 MHz > 400 MHz and ≥ 800 MHz and > 1400 MHz < 800 MHz ≤ 1400 MHz and ≤ 2400 MHz DFT-s-OFDM Pi/2 BPSK ≤ 5.5 ≤ 7.7 ≤ 8.2 ≤ 8.7 **QPSK** ≤ 6 ≤ 7.7 ≤ 8.2 ≤ 8.7 **16 QAM** ≤ 7 ≤ 8.7 ≤ 9.3 ≤ 9.8 64 QAM ≤ 9.0 ≤ 10.7 ≤ 11.2 ≤ 11.7 CP-OFDM QPSK ≤ 6 ≤ 7.5 ≤ 8.0 ≤ 8.5 16 QAM ≤ 9.7 ≤ 7 ≤ 8.7 ≤ 9.2 ≤ 11.7 64 QAM ≤ 9.0 ≤ 10.7 ≤ 11.2

Table 6.2A.2.4.2-1: MPR_{NC_CA} for UE power class 3

When different waveform types exist across CCs, the requirement is set by the waveform type used in the configuration with the largest $MPR_{NC\ CA}$.

6.2A.2.5 Maximum output power reduction for power class 4

For power class 4, MPR specified in sub-clause 6.2A.2.4.1 applies for intra-band contiguous UL CA and sub-clause 6.2A.2.4.2 applies for intra-band non-contiguous UL CA.

6.2A.3 UE maximum output power with additional requirements for CA

6.2A.3.1 General

Additional emission requirements can be signalled by the network with network signalling value indicated by the field *additionalSpectrumEmission*. To meet these additional requirements, additional maximum power reduction (A-MPR) is allowed for the maximum output power as specified in clause 6.2A.1. Unless stated otherwise, an A-MPR of 0 dB shall be used. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2A.2.

For intra-band contiguous aggregation with the UE configured for transmissions on two serving cells, the maximum output power reduction specified in Table 6.2A.3.1-1 is allowed for all serving cells of the applicable uplink contiguous CA configurations according to the CA network signalling value indicated by the field *additionalSpectrumEmissionSCell*.

Table 6.2A.3.1-1 specifies the additional requirements and allowed A-MPR with corresponding network signalling label and operating band. The mapping between network signalling labels and the *additionalSpectrumEmission* IE defined in TS 38.331 [13] is specified in Table 6.2A.3.1-2. Unless otherwise stated, the allowed total back off is maximum of A-MPR and MPR specified in clause 6.2A.2.

Table 6.2A.3.1-1: Additional maximum power reduction (A-MPR)

Network Signalling value	Requirements (clause)	NR Band	Channel bandwidth (MHz)	Resources Blocks (N _{RB})	A-MPR (dB)
CA_NS_200					N/A
CA_NS_201	6.5.3.2.2	n258			6.2A.3.2
CA_NS_202	6.5.3.2.3	n257, n258			6.2A.3.3
CA_NS_203	6.5.3.2.4	n258			6.2A.3.4
NOTE: CA_NS_201 is obsolete, the associated additional spurious emission requirements					
are not applicable.					

Table 6.2A.3.1-2: Value of additional Spectrum Emission

NR Band		Value of additionalSpectrumEmission / NS number						
	0	1	2	3	4	5	6	7
n257	CA_NS_200	CA_NS_202						
n258	CA_NS_200	CA_NS_201	CA_NS_202	CA_NS_203				
n259	CA_NS_200							
n260	CA_NS_200							
n261	CA_NS_200							

NOTE 1: additionalSpectrumEmission corresponds to an information element of the same name defined in clause 6.3.2 of TS 38.331 [13].

NOTE 2: CA_NS_201 is obsolete, the associated additional spurious emission requirements are not applicable.

6.2A.3.2	Void	
6.2A.3.2.1	Void	
		Table 6.2A.3.2.1-1: (Void)
6.2A.3.2.2	Void	
		Table 6.2A.3.2.2-1: (Void)
6.2A.3.2.3	Void	
		Table 6.2A.3.2.3-1: Void

6.2A.3.2.4 Void

6.2A.3.3 A-MPR for CA_NS_202

6.2A.3.3.1 A-MPR for CA_NS_202 for power class 1

For intra-band contiguous CA, A-MPR for CA_NS_202 shall be 11.0 dB.

6.2A.3.3.2 A-MPR for CA_NS_202 for power class 2

For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.

6.2A.3.3.3 A-MPR for CA_NS_202 for power class 3

For intra-band contiguous CA, A-MPR for CA_NS_202 shall be 2.0 dB.

6.2A.3.3.4 A-MPR for CA_NS_202 for power class 4

For intra-band contiguous CA, A-MPR for CA_NS_202 specified in sub-clause 6.2A.3.3.3 applies.

6.2A.3.4 A-MPR for CA_NS_203

6.2A.3.4.1 A-MPR for CA NS 203 for power class 1

For intra-band contiguous CA, A-MPR for CA_NS_203 shall be 6.5 dB, if Offset frequency < BW_{Channel_CA} of the UL CA configuration, 0.0 dB, otherwise

The Offset frequency is defined as the frequency from 24.25 GHz to the lower edge of the lowest CC among the configured UL CA.

6.2A.3.4.2 A-MPR for CA_NS_203 for power class 2

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.3.4.3 A-MPR for CA_NS_203 for power class 3

For intra-band contiguous CA, A-MPR for CA_NS_203 shall be 2.5 dB, if Offset frequency < BW_{Channel_CA} of the UL CA configuration, 0.0 dB otherwise.

The Offset frequency is defined as the frequency from 24.25 GHz to to the lower edge of the lowest CC among the configured UL CA.

6.2A.3.4.4 A-MPR for CA_NS_203 for power class 4

For intra-band contiguous CA, AMPR specified in sub-clause 6.2A.3.4.3 applies.

6.2A.4 Configured transmitted power for CA

A UE configured with carrier aggregation can configure its maximum output power for each uplink activated serving cell c and its total configured maximum output power P_{CMAX} . The definition of the configured UE maximum output power $P_{CMAX,f,c}$ for each carrier f of a serving cell c is used for power headroom reporting for carrier f of serving cell c only and is in accordance with that specified in clause 6.2.4 with parameters MPR, A-MPR and P-MPR replaced with those specified in subclause 6.2A.2, 6.2A.3 and 6.2.4, respectively. The UE maximum configured power P_{CMAX} in a transmission occasion is determined by the UL grants for carriers f of all serving cells c with non-zero granted power in the respective reference point.

For uplink intra-band contiguous carrier aggregation, MPR is specified in clause 6.2A.2. P_{CMAX} is calculated under the assumption that power spectral density for each RB in each component carrier is same.

The configured UE maximum output power P_{CMAX} shall be set such that the corresponding measured total peak EIRP P_{UMAX} is within the following bounds

$$P_{Powerclass} - MAX(MAX(MPR, A-MPR) + \Delta MB_{P,n}, P-MPR) - MAX\{T(MAX(MPR, A-MPR)), T(P-MPR)\} \leq P_{UMAX} \leq EIRP_{max}$$

with $P_{Powerclass}$ the UE minimum peak EIRP as specified in sub-clause 6.2A.1, EIRP_{max} the applicable maximum EIRP as specified in sub-clause 6.2A.1, MPR as specified in sub-clause 6.2A.2, A-MPR as specified in sub-clause 6.2A.3, $\Delta MB_{P,n}$ the peak EIRP relaxation as specified in clause 6.2.1, P-MPR the power management term for the UE as described in 6.2.4.

The measured configured power P_{UMAX} for carrier aggregation is defined as

$$P_{UMAX} = 10 \log_{10} \sum_{c,f(c)} p_{UMAX,f,c}$$

where $p_{UMAX,f,c}$ is the linear value of the measured power $P_{UMAX,f,c}$ for carrier f=f(c) of serving cell c. The measured total radiated power P_{TMAX} for carrier aggregation is defined as

$$P_{TMAX} = 10 \log_{10} \sum_{c,f(c)} p_{TMAX,f,c}$$

where $p_{TMAX,f,c}$ is the linear value of the measured total radiated power $P_{TMAX,f,c}$ for carrier f = f(c) of serving cell c. The total radiated power P_{TMAX} is bounded by

$$P_{TMAX} < TRP_{max}$$

where TRP_{max} the maximum TRP for the UE power class as specified in sub-clause 6.2A.1.

The tolerance $T(\Delta P)$ for applicable values of ΔP (values in dB) is specified in Table 6.2A.4-1.

Table 6.2A.4-1: P_{UMAX} tolerance

Operating Band	∆ P (dB)	Tolerance T(∆P) (dB)		
n257, n258, n259, n260, n261	$\Delta P = 0$	0		
	0 < ΔP ≤ 2	1.5		
	2 < ΔP ≤ 3	2.0		
	3 < ΔP ≤ 4	3.0		
	4 < ΔP ≤ 5	4.0		
	5 < ΔP ≤ 10	5.0		
	10 < ΔP ≤ 15	7.0		
	15 < ΔP ≤ X	8.0		
	X is the value such that P_{umax} lower bound, $P_{Powerclass}$ - ΔP - $T(\Delta P)$ = minimum output power specified in clause			

6.2D Transmitter power for UL MIMO

6.2D.1 UE maximum output power for UL MIMO

6.2D.1.0 General

The requirements in the following clauses define the maximum output power radiated by the UE with *nrofSRS-Ports* set to 2, for any transmission bandwidth within the channel bandwidth for non-CA configuration, unless otherwise stated. MPR shall be applied as specified in clause 6.2D.2

For the maximum output power requirement for 2-layer UL MIMO operation, a UE shall be configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.0-1.

Table 6.2D.1.0-1: UL MIMO configuration

Transmission scheme	DCI format	Number of layers	TPMI index
Codebook based uplink	DCI format 0 1	2	0

The maximum output power requirement for single layer transmission shall apply to a UE that supports ULFPTx feature and is configured for single layer transmission in its declared full power mode [10, TS 38.213] as specified in Table 6.2D.1.0-2.

Table 6.2D.1.0-2: PUSCH Configuration for uplink full power transmission (ULFPTx)

ULFPTx Mode	Transmission scheme	DCI format	Modulation	Number of layers	TPMI index
Mode-1	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM 1	1	2
Mode-2	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM	1	0 or 1 ²
Mode-full	Codebook based uplink	DCI format 0_1	DFT-s-OFDM, CP-OFDM	1	0,1
power					

NOTE 1: For PUSCH configured with ULFPTxModes set to Mode-1, all requirements for 1-layer CP-OFDM based modulation in subsection 6.2D are assumed to be met if the requirement for 2-layer UL MIMO has been validated.

NOTE 2: TPMI index selected shall be based upon the full power TPMI reported by the UE [10, TS 38.213].

6.2D.1.1 UE maximum output power for UL MIMO for power class 1

The following requirements define the maximum output power radiated by the PC1 UE . Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.1-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle). Power class 1 UE is used for fixed wireless access (FWA).

Table 6.2D.1.1-1: UE minimum peak EIRP for UL MIMO for power class 1

Operating band	Min peak EIRP (dBm)	
n257	40.0	
n258	40.0	
n260	38.0	
n261	40.0	
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance		

Table 6.2D.1.1-2: (void)

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.1-3 below for UE with UL MIMO. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.1-3: UE maximum output power limits for UL MIMO for power class 1

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	35	55
n258	35	55
n260	35	55
n261	35	55

The minimum EIRP at the 85th percentile of the distribution of radiated power measured over the full sphere around the UE with UL MIMO is defined as the spherical coverage requirement and is found in Table 6.2D.1.1-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.1-4: UE spherical coverage for UL MIMO for power class 1

Operating band	Min EIRP at 85 %-tile CDF (dBm)		
n257	32.0		
n258	32.0		
n260	30.0		
n261	32.0		
NOTE 1: Minimum I	EIRP at 85 %-tile CDF is defined as		
the lower limit without tolerance			

6.2D.1.2 UE maximum output power for UL MIMO for power class 2

The following requirements define the maximum output power radiated by the PC2 UE. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.2-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.2-1: UE minimum peak EIRP for UL MIMO for power class 2

Operating band	Min peak EIRP (dBm)		
n257	29		
n258	29		
n261	29		
NOTE 1: Minimum p	peak EIRP is defined as the		
lower limit	without tolerance.		
NOTE 2: Min Peak I	Min Peak EIRP refers to the total EIRP		
for the UL	beams peaks.		

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.2-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.2-2: UE maximum output power limits for UL MIMO for power class 2

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n261	23	43

Table 6.2D.1.2-3: (void)

The minimum EIRP at the 60th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.2-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.2-4: UE spherical coverage for UL MIMO for power class 2

Operating band	Min EIRP at 60 %-tile CDF (dBm)	
n257	18.0	
n258	18.0	
n261	18.0	
NOTE 1: Minimum EIRP at 60 %-tile CDF is defined as		
the lower limit without tolerance		

6.2D.1.3 UE maximum output power for UL MIMO for power class 3

The following requirements define the maximum output power radiated by the PC3 UE. Requirements apply to UEs when configured for 2-layer transmission as well as when configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.3-1 below. The period of measurement shall be at least one sub frame (1 ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.3-1: UE minimum peak EIRP for UL MIMO for power class 3

Operating band	Min peak EIRP (dBm)
n257	22.4
n258	22.4
n259	18.7
n260	20.6
n261	22.4
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance.	
NOTE 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.	

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.3-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.3-2: UE maximum output power limits for UL MIMO for power class 3

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n259	23	43
n260	23	43
n261	23	43

Table 6.2D.1.3-3: (void)

The minimum EIRP at the 50th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.3-4 below. The requirement is verified with the test metric of EIRP (Link=spherical coverage grid, Meas=Link angle).

Table 6.2D.1.3-4: UE spherical coverage for UL MIMO for power class 3

	Operating band	Min EIRP at 50 %-tile CDF (dBm)
	n257	11.5
	n258	11.5
	n259	5.8
	n260	8
n261		11.5
NOTE 1: Minimum EIRP at 50 %-tile CDF is defined as the lower limit without tolerance		
NOTE 2: The requirements in this table are only applicable for UE which supports single band in FR2		

6.2D.1.4 UE maximum output power for UL MIMO for power class 4

The following requirements define the maximum output power radiated by the PC4 UE. Requirements apply to UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), with configuration per clause 6.2D.1.0.

The minimum peak EIRP requirements are found in Table 6.2D.1.4-1 below. The period of measurement shall be at least one sub frame (1ms). The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.4-1: UE minimum peak EIRP for UL MIMO for power class 4

Operating band	Min peak EIRP (dBm)
n257	34
n258	34
n260	31
n261	34
NOTE 1: Minimum peak EIRP is defined as the lower limit without tolerance.	
NOTE 2: Min Peak EIRP refers to the total EIRP for the UL beams peaks.	

The maximum output power values for TRP and EIRP are found in Table 6.2D.1.4-2 below. The maximum allowed EIRP is derived from regulatory requirements [8]. The requirements are verified with the test metrics of TRP (Link=TX beam peak direction, Meas=TRP grid) in beam locked mode and EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.2D.1.4-2: UE maximum output power limits for UL MIMO for power class 4

Operating band	Max TRP (dBm)	Max EIRP (dBm)
n257	23	43
n258	23	43
n260	23	43
n261	23	43

Table 6.2D.1.4-3: (void)

The minimum EIRP at the 20th percentile of the distribution of radiated power measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 6.2D.1.4-4 below. The requirement is verified with the test metric of EIRP (Link=Spherical coverage grid, Meas=Link angle).

Table 6.2D.1.4-4: UE spherical coverage for UL MIMO for power class 4

Operating band Min EIRP at 20 %-tile CDF		
n257	25	
n258	25	
n260	19	
n261	25	
NOTE 1: Minimum E	1: Minimum EIRP at 20 %-tile CDF is defined as	
the lower limit without tolerance		

6.2D.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO

6.2D.2.1 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 1

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.1-1 is specified in sub-clause 6.2.2.1. The requirements shall be met with configurations specified in sub-clause 6.2.D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.2 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 2

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.2-1 is specified in sub-clause 6.2.2.2. The requirements shall be met with configurations specified in sub-clause 6.2.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.3 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 3

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.3-1 is specified in sub-clause 6.2.2.3. The requirements shall be met with configurations specified in sub-clause 6.2.D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.2.4 UE maximum output power reduction for modulation / channel bandwidth for UL MIMO for power class 4

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the allowed Maximum Power Reduction (MPR) for the maximum output power in Table 6.2D.1.4-1 is specified in sub-clause 6.2.2.4. The requirements shall be met with configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3 UE maximum output power reduction with additional requirements for UL MIMO

6.2D.3.1 UE maximum output power reduction with additional requirements for UL MIMO for power class 1

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.1-1. The requirements shall be met with the configurations specified in sub-clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.2 UE maximum output power reduction with additional requirements for UL MIMO for power class 2

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.2-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.3 UE maximum output power reduction with additional requirements for UL MIMO for power class 3

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.3-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

For the UE maximum output power modified by A-MPR, the power limits specified in clause 6.2D.4 apply.

6.2D.3.4 UE maximum output power reduction with additional requirements for UL MIMO for power class 4

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the A-MPR values specified in clause 6.2.3 shall apply to the maximum output power specified in Table 6.2D.1.4-1. The requirements shall be met with the configurations specified in clause 6.2D.1.0.

6.2D.4 Configured transmitted power for UL MIMO

For UEs configured for 2-layer transmission as well as UEs configured for single layer uplink full power transmission (ULFPTx), the configured maximum output power $P_{CMAX,c}$ for serving cell c is defined as sum of all streams and is bound by limits set in clause 6.2.4.

6.3 Output power dynamics

6.3.1 Minimum output power

6.3.1.0 General

The minimum controlled output power of the UE is defined as the EIRP in the channel bandwidth for all transmit bandwidth configurations (resource blocks) when the power is set to a minimum value.

The minimum output power is defined as the mean power in at least one sub frame (1ms).

6.3.1.1 Minimum output power for power class 1

For power class 1 UE, the minimum output power shall not exceed the values specified in Table 6.3.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3.1.1-1: Minimum output power for power class 1

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	4	47.58
	100	4	95.16
	200	4	190.20
	400	4	380.28

6.3.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3.1.2-1: Minimum output power for power class 2, 3, and 4

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)	
n257, n258, n259, n260, n261	50	-13	47.58	
	100	-13	95.16	
	200	-13	190.20	
	400	-13	380.28	
NOTE 1: n260 is not applied for power class 2.				
NOTE 2: n259 is not applied for power class 2 and 4.				

6.3.2 Transmit OFF power

The transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports.

The transmit OFF power shall not exceed the values specified in Table 6.3.2-1 for each operating band supported. The requirement is verified with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Table 6.3.2-1: Transmit OFF power

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz 100 MHz 200 MHz 400 MHz			
n257, n258, n259, n260, n261	-35	-35	-35	-35
	47.58 MHz	95.16 MHz	190.20 MHz	380.28 MHz

6.3.3 Transmit ON/OFF time mask

6.3.3.1 General

The transmit ON/OFF time mask defines the transient period(s) allowed

- between transmit OFF power and transmit ON power symbols (transmit ON/OFF)
- between continuous ON-power transmissions when power change or RB hopping is applied.

In case of RB hopping, transition period is shared symmetrically.

Unless otherwise stated the minimum requirements in clause 6.5 apply also in transient periods.

The transmit ON/OFF time mask is defined as a directional requirement. The requirement is verified in beam locked mode at beam peak direction. The maximum allowed EIRP OFF power level is -30dBm at beam peak direction. The requirement is verified with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

In the following sub-clauses, following definitions apply:

- A slot transmission is a Type A transmission.
- A long subslot transmission is a Type B transmission with more than 2 symbols.
- A short subslot transmission is a Type B transmission with 1 or 2 symbols.

6.3.3.2 General ON/OFF time mask

The general ON/OFF time mask defines the observation period allowed between transmit OFF and ON power. ON/OFF scenarios include: contiguous, and non-contiguous transmission, etc

The OFF power measurement period is defined in a duration of at least one slot excluding any transient periods. The ON power is defined as the mean power over one slot excluding any transient period.



Figure 6.3.3.2-1: General ON/OFF time mask for NR UL transmission in FR2

6.3.3.3 Transmit power time mask for slot and short or long subslot boundaries

The transmit power time mask for slot and a long subslot transmission boundaries defines the transient periods allowed between slot and long subslot PUSCH transmissions. For PUSCH-PUCCH and PUSCH-SRS transitions and multiplexing the time masks in sub-clause 6.3.3.7 apply.

The transmit power time mask for slot or long subslot and short subslot transmission boundaries defines the transient periods allowed between slot or long subslot and short subslot transmissions. The time masks in sub-clause 6.3.3.8 apply.

The transmit power time mask for short subslot transmissiona boundaries defines the transient periods allowed between short subslot transmissions. The time masks in sub-clause 6.3.3.9 apply.

6.3.3.4 PRACH time mask

The PRACH ON power is specified as the mean power over the PRACH measurement period excluding any transient periods as shown in Figure 6.3.3.4-1. The measurement period for different PRACH preamble format is specified in Table 6.3.3.4-1.

Measurement period **Format** SCS 60 kHz 0.035677 ms A_1 120 kHz 0.017839 ms A_2 60 kHz 0.071354 ms 120 kHz 0.035677 ms A_3 60 kHz 0.107031 ms 120 kHz 0.053516 ms B₁ 0.035091 ms 60 kHz 120 kHz 0.0175455 ms B₄ 60 kHz 0.207617 ms 120 kHz 0.103809 ms A_1/B_1 60 kHz 0.035677 ms for front X1 occasion 0.035091 ms for last occasion X1 = [2,5]120 kHz 0.017839 ms for front X1occasion 0.017546 ms for last occasion X1 = [2,5] A_2/B_2 60 kHz 0.071354 ms for front X2 occasion 0.069596 ms for last occasion X2 = [1,2]0.035677 ms for front X2 occasion 120 kHz 0.034798 ms for last occasion X2 = [1,2]A₃/B₃ 60 kHz 0.107031 ms for first occasion 0.104101 ms for second occasion 120 kHz 0.053515 ms for first occasion 0.052050 ms for second occasion C_0 60 kHz 0.026758 ms 120 kHz 0.013379 ms C_2 60 kHz 0.083333 ms 120 kHz 0.0416667 ms NOTE: For PRACH on PRACH occasion start from begin of 0ms or 0.5 ms boundary, the measurement period will plus 0.032552 µs

Table 6.3.3.4-1: PRACH ON power measurement period

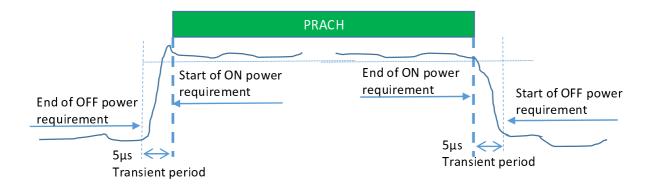


Figure 6.3.3.4-1: PRACH ON/OFF time mask

6.3.3.5 Void

6.3.3.6 SRS time mask

In the case a single SRS transmission, the ON power is defined as the mean power over the symbol duration excluding any transient period; Figure 6.3.3.6-1.

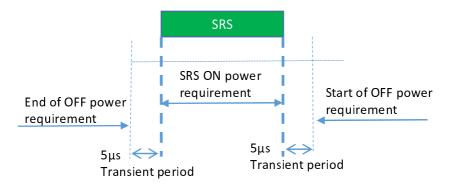


Figure 6.3.3.6-1: Single SRS time mask for NR UL transmission

In the case multiple consecutive SRS transmission, the ON power is defined as the mean power for each symbol duration excluding any transient period. See Figure 7.7.4-2

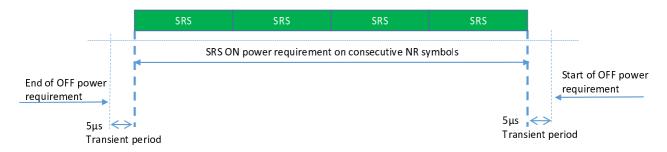


Figure 6.3.3.6-2: Consecutive SRS time mask for the case when no power change is required

When power change between consecutive SRS transmissions is required, then Figure 6.3.3.6-3 and Figure 6.3.3.6-4 apply.

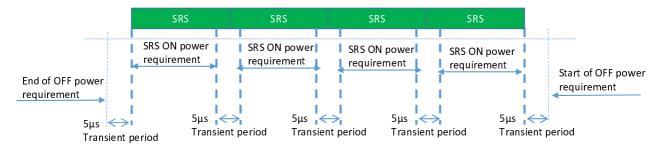


Figure 6.3.3.6-3: Consecutive SRS time mask for the case when power change is required and when 60kHz SCS is used in FR2

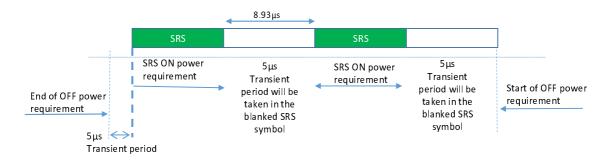


Figure 6.3.3.6-4: Consecutive SRS time mask for the case when power change is required and when 120kHz SCS is used in FR2

6.3.3.7 PUSCH-PUCCH and PUSCH-SRS time masks

The PUCCH/PUSCH/SRS time mask defines the observation period between sounding reference symbol (SRS) and an adjacent PUSCH/PUCCH symbol and subsequent UL transmissions. The time masks apply for all types of frame structures and their allowed PUCCH/PUSCH/SRS transmissions unless otherwise stated.

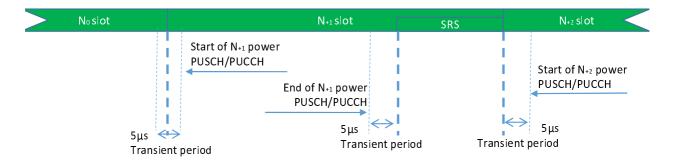


Figure 6.3.3.7-1: PUCCH/PUSCH/SRS time mask when there is a transmission before or after or both before and after SRS

When there is no transmission preceding SRS transmission or succeeding SRS transmission, then the same time mask applies as shown in Figure 6.3.3.7-1.

6.3.3.8 Transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries

The transmit power time mask for consecutive slot or long subslot transmission and short subslot transmission boundaries defines the transient periods allowed between such transmissions.

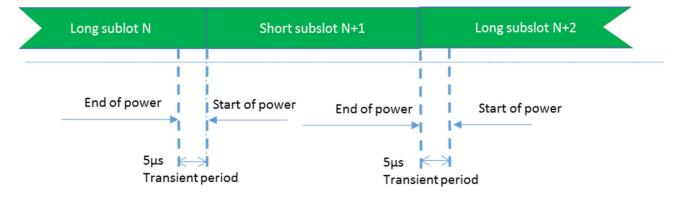


Figure 6.3.3.8-1: Consecutive slot or long subslot transmission and short subslot transmission time mask

6.3.3.9 Transmit power time mask for consecutive short subslot transmissions boundaries

The transmit power time mask for consecutive short subslot transmission boundaries defines the transient periods allowed between short subslot transmissions.

The transient period shall be equally shared as shown on Figure 6.3.3.9-2.

Figure 6.3.3.9-1: Void

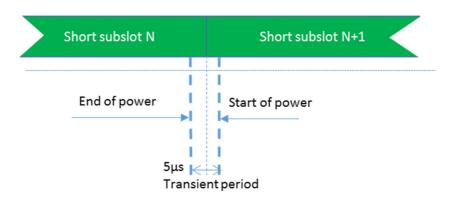


Figure 6.3.3.9-2: Consecutive short subslot transmissions time mask where DMRS is not the first symbol in the adjacent short subslot transmission

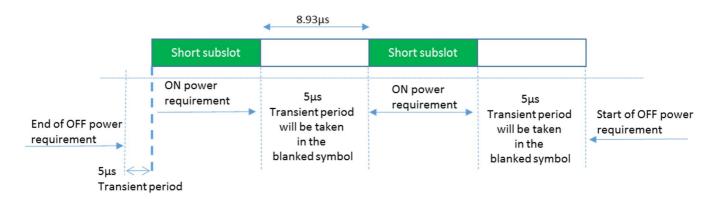


Figure 6.3.3.9-3: Consecutive short subslot (1 symbol gap) time mask for the case when transient period is required on both sides of the symbol and when 120 kHz SCS is used in FR2

6.3.4 Power control

6.3.4.1 General

The requirements on power control accuracy apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction.

6.3.4.2 Absolute power tolerance

The absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame (1 ms) at the start of a contiguous transmission or non-contiguous transmission with a transmission gap larger than 20 ms. The tolerance includes the channel estimation error RSRP estimate.

The minimum requirements specified in Table 6.3.4.2-1 apply in the power range bounded by the minimum output power as specified in sub-clause 6.3.1 (P_{min}) and the maximum output power as specified in sub-clause 6.2.1 as minimum peak EIRP (P_{max}). The intermediate power point P_{int} is defined in table 6.3.4.2-2

Table 6.3.4.2-1: Absolute power tolerance

Power Range	Tolerance
$P_{int} \ge P \ge P_{min}$	± 14.0 dB
$P_{max} \ge P > P_{int}$	± 12.0 dB

Table 6.3.4.2-2: Intermediate power point

Power Parameter	Value
Pint	P _{max} – 12.0 dB

6.3.4.3 Relative power tolerance

The relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame (1 ms) relatively to the power of the most recently transmitted reference sub-frame (1 ms) if the transmission gap between these sub-frames is less than or equal to 20 ms.

The minimum requirements specified in Table 6.3.4.3-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and Pint as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.3-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the measured P_{UMAX} as defined in sub-clause 6.2.4.

For a test pattern that is either a monotonically increasing or monotonically decreasing power sweep over the range specified for Tables 6.3.4.3-1 and 6.3.4.3-2, 3 exceptions are allowed for each of the test patterns. For these exceptions, the power tolerance limit is a maximum of ± 11.0 dB.

Table 6.3.4.3-1: Relative power tolerance, P_{int} ≥ P ≥ P_{min}

Power step ∆P (Up or down) (dB)	All combinations of PUSCH and PUCCH, PUSCH/PUCCH and SRS transitions between subframes, PRACH (dB)	
ΔP < 2	±5.0	
2 ≤ ΔP < 3	±6.0	
3 ≤ ΔP < 4	±7.0	
4 ≤ ΔP < 10	10 ±8.0	
10 ≤ ΔP < 15	±10.0	
15 ≤ ΔP	±11.0	
NOTE: The requirements apply with <i>ue-BeamLockFunction</i> enabled.		

All combinations of PUSCH and Power step △P (Up PUCCH, PUSCH/PUCCH and or down) SRS transitions between sub-(dB) frames, PRACH (dB) ΔP < 2 ± 3.0 2 ≤ ΔP < 3 ± 4.0 $3 \le \Delta P < 4$ ± 5.0 4 ≤ ΔP < 10 ± 6.0 10 ≤ ΔP < 15 ± 8.0 ± 9.0 15 ≤ ΔP NOTE 1: The requirements apply with ue-BeamLockFunction enabled. NOTE 2: For PUSCH to PUSCH transitions with the allocated resource blocks fixed in frequency and

Table 6.3.4.3-2: Relative power tolerance, P_{UMAX} ≥ P > P_{int}

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no transmission gaps other than those

generated by downlink subframes, guard periods: for a power step $\Delta P = 1$ dB, the relative power tolerance for transmission is ± 1.0 dB.

6.3.4.4 Aggregate power tolerance

The aggregate power control tolerance is the ability of the UE transmitter to maintain its power in a sub-frame (1 ms) during non-contiguous transmissions within 21ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in 38.213 kept constant.

The minimum requirements specified in Table 6.3.4.4-1 apply when the power of the target and reference sub-frames are within the power range bounded by the minimum output power as defined in sub-clause 6.3.1 and P_{int} as defined in sub-clause 6.3.4.2. The minimum requirements specified in Table 6.3.4.4-2 apply when the power of the target and reference sub-frames are within the power range bounded by Pint as defined in sub-clause 6.3.4.2 and the maximum output power as specified in sub-clause 6.2.1.

Table 6.3.4.4-1: Aggregate power tolerance, P_{int} ≥ P ≥ P_{min}

TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± 5.5 dB
0 dB	PUSCH	± 5.5 dB

Table 6.3.4.4-2: Aggregate power tolerance, P_{max} ≥ P > P_{int}

TPC command	UL channel	Aggregate power tolerance within 21 ms
0 dB	PUCCH	± 3.5 dB
0 dB	PUSCH	± 3.5 dB

6.3A Output power dynamics for CA

6.3A.1 Minimum output power for CA

Table 6.3A.1-1: Void

6.3A.1.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the minimum controlled output power of the UE is defined as the transmit power of the UE per component carrier, i.e., EIRP in the channel bandwidth of each component carrier for all transmit bandwidth configurations (resource blocks), when the power on both component carriers are set to a minimum value.

The minimum output power is defined as the mean power in at least one sub frame (1ms).

6.3A.1.1 Minimum output power for power class 1

The minimum output power shall not exceed the values specified in Table 6.3A.1.1-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3A.1.1-1: Minimum output power for power class 1

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n260, n261	50	4	47.58
	100	4	95.16
	200	4	190.20
	400	4	380.28

6.3A.1.2 Minimum output power for power class 2, 3, and 4

The minimum output power shall not exceed the values specified in Table 6.3A.1.2-1 for each operating band supported. The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

Table 6.3A.1.2-1: Minimum output power for CA for power class 2, 3, and 4

Operating band	Channel bandwidth (MHz)	Minimum output power (dBm)	Measurement bandwidth (MHz)
n257, n258, n259, n260, n261	50	-13	47.58
	100	-13	95.16
	200	-13	190.20
	400	-13	380.28
NOTE 1: n260 is not appl	ied for power class 2.		

6.3A.2 Transmit OFF power for CA

For intra-band contiguous and non-contiguous carrier aggregation, the transmit OFF power is defined as the TRP in the channel bandwidth per component carrier when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of it sports.

The transmit OFF power shall not exceed the values specified in Table 6.3A.2-1 for each operating band supported.

Table 6.3A.2-1: Transmit OFF power for CA

Operating band	Channel bandwidth / Transmit OFF power (dBm) / measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
n257, n258, n259, n260, n261	-35	-35	-35	-35
	47.58 MHz	95.16 MHz	190.20 MHz	380.28 MHz

6.3A.3 Transmit ON/OFF time mask for CA

For intra-band contiguous and non-contiguous UL carrier aggregation, the general output power ON/OFF time mask specified in clause 6.3.3.2 is applicable for each component carrier during the ON power period and the transient periods. The OFF period as specified in clause 6.3.3.2 shall only be applicable for each component carrier when all the component carriers are OFF.

6.3A.4 Power control for CA

6.3A.4.1 General

The requirements in this clause apply to a UE when it has at least one of UL or DL configured for CA operation. The requirements on power control accuracy in CA operation apply under normal conditions and are defined as a directional requirement. The requirements are verified in beam locked mode on beam peak direction. The requirements apply for one single PUCCH, PUSCH or SRS transmission of contiguous PRB allocation per configured UL CC with power setting in accordance with Clause 7.1 of [10]

6.3A.4.2 Absolute power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission gap on each active component carriers larger than 20 ms. For SRS switching, the absolute power tolerance is the ability of the UE transmitter to set its initial output power to a specific value for the first sub-frame at the start of a contiguous transmission or non-contiguous transmission with a transmission gap on component carriers (to which SRS switching occurs) larger than 20 ms. The requirement can be tested by time aligning any transmission gaps on the component carriers. For intra-band contiguous CA, the absolute power control tolerance per configured UL CC is given in Tables 6.3.4.2-1 and 6.3.4.2-2.

6.3A.4.3 Relative power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the relative power tolerance is the ability of the UE transmitter to set its output power in a target sub-frame relative to the power of the most recently transmitted reference sub-frame if the transmission gap between these sub-frames is less than or equal to 20ms.

For intra-band contiguous CA, the requirements apply when the power of the target and reference sub-frames on each component carrier exceed the minimum output power as defined in clause 6.3A.1 and the total power is limited by P_{UMAX} as defined in clause 6.2A.4. For the purpose of these requirements, the power in each component carrier is specified over only the transmitted resource blocks. The UE shall meet the requirements in tables 6.3.4.3-1 and 6.3.4.3-1 for transmission on each assigned component carrier, when the average PSDs over each CC are aligned with each other in the reference sub-frame. The requirements apply per component carrier to:

- a. All possible combinations of PUSCH and PUCCH transitions
- b. SRS and PUSCH/PUCCH transitions, only with simultaneous SRS of constant SRS bandwidth allocated in the target and reference subrames
- c. RACH, primary component carrier

When applicable, the power step ΔP between the reference and target subframes shall be set by a TPC command and/or an uplink scheduling grant transmitted by means of an appropriate DCI Format.

6.3A.4.4 Aggregate power tolerance

For intra-band contiguous and non-contiguous UL carrier aggregation, the aggregate power control tolerance is the ability of the UE transmitter to maintain its power during non-contiguous transmissions within 21 ms in response to 0 dB TPC commands with respect to the first UE transmission and all other power control parameters as specified in [10] kept constant.

For intra-band contiguous CA, the aggregate power tolerance per CC is given in Tables 6.3.4.4.1-1 and 6.3.4.4.1-2, with simultaneous PUSCH configured. The average PSDs over each assigned CC shall be aligned before the start of the test. The requirement can be tested with the transmission gaps time aligned between component carriers.

6.3D Output power dynamics for UL MIMO

6.3D.0 General

The requirements in subclause 6.3D shall be met with configurations specified in sub-clause 6.2D.1.x, where 'x' depends on power class. Unless otherwise specified, the requirements shall be verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

6.3D.1 Minimum output power for UL MIMO

6.3D.1.0 General

The minimum output power is defined as the mean power in at least one sub frame (1ms). The minimum controlled output power is defined as the EIRP, i.e. the sum of the power in the channel bandwidth for all transmit bandwidth configurations (resource blocks), when the UE power is set to a minimum value.

6.3D.1.1 Minimum output power for UL MIMO for power class 1

For UE supporting UL MIMO, the minimum output power shall not exceed the sum of the values specified in Table 6.3.1.1-1 and the quantity 10*log₁₀(Number of Layers). The minimum power is verified in beam locked mode with the test metric of EIRP (Link=TX beam peak direction, Meas=Link angle).

6.3D.1.2 Minimum output power for UL MIMO for power class 2, 3 and 4

For UE supporting UL MIMO, the minimum output power shall not exceed the sum of the values specified in Table 6.3.1.2-1 and the quantity 10*log₁₀(Number of Layers).

6.3D.2 Transmit OFF power for UL MIMO

For UE supporting UL MIMO, the transmit OFF power is defined as the TRP in the channel bandwidth when the transmitter is OFF. The transmitter is considered OFF when the UE is not allowed to transmit on any of its ports. During DTX and measurements gaps, the transmitter is not considered OFF. The minimum output power shall not exceed the values specified in Table 6.3.2-1. The requirement is verified with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

6.3D.3 Transmit ON/OFF time mask for UL MIMO

For UE supporting UL MIMO, the ON/OFF time mask requirements in clause 6.3.3 apply.

6.4 Transmit signal quality

6.4.1 Frequency Error

The UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequency shall be accurate to within \pm 0.1 PPM observed over a period of 1 msec of cumulated measurement intevals compared to the carrier frequency received from the NR gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of Frequency (Link=TX beam peak direction, Meas=Link angle).

6.4.2 Transmit modulation quality

6.4.2.0 General

Transmit modulation quality defines the modulation quality for expected in-channel RF transmissions from the UE. The transmit modulation quality is specified in terms of:

- Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)
- EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process
- Carrier leakage
- In-band emissions for the non-allocated RB

All the parameters defined in clause 6.4.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with parameter *maxRank* (as defined in TS 38.331 [13]) set to 1. The requirements are applicable to UL transmission from each configurable antenna port (as defined in TS 38.331 [13]) of UE, enabled one at a time.

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrentList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4.2.2 and 6.4.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

6.4.2.1 Error vector magnitude

The Error Vector Magnitude is a measure of the difference between the reference waveform and the measured waveform. This difference is called the error vector. Before calculating the EVM, the measured waveform is corrected by the sample timing offset and RF frequency offset. Then the carrier leakage shall be removed from the measured waveform before calculating the EVM.

The measured waveform is further equalised using the channel estimates subjected to the EVM equaliser spectrum flatness requirement specified in sub-clauses 6.4.2.4 and 6.4.2.5. For DFT-s-OFDM waveforms, the EVM result is defined after the front-end FFT and IDFT as the square root of the ratio of the mean error vector power to the mean reference power expressed as a %. For CP-OFDM waveforms, the EVM result is defined after the front-end FFT as the square root of the ratio of the mean error vector power to the mean reference power expressed as a %.

The basic EVM measurement interval in the time domain is one preamble sequence for the PRACH and one slot for PUCCH and PUSCH in the time domain. The EVM measurement interval is reduced by any symbols that contains an allowable power transient in the measurement interval as as defined in clause 6.3.3.

The RMS average of the basic EVM measurements over 10 subframes for the average EVM case, and over 60 subframes for the reference signal EVM case, for the different modulation schemes shall not exceed the values specified in Table 6.4.2.1-1 for the parameters defined in Table 6.4.2.1-2 or 6.4.2.1-3, depending on UE power class. For EVM evaluation purposes, all 13 PRACH preamble formats and all 5 PUCCH formats are considered to have the same EVM requirement as QPSK modulated.

The requirement is verified with the test metric of EVM (Link=TX beam peak direction, Meas=Link angle).

Table 6.4.2.1-1: Minimum requirements for error vector magnitude

Parameter	Unit	Average EVM level	Reference signal EVM level
Pi/2 BPSK	%	30.0	30.0
QPSK	%	17.5	17.5
16 QAM	%	12.5	12.5
64 QAM	%	8.0	8.0

Table 6.4.2.1-2: Parameters for Error Vector Magnitude for power class 1

Parameter	Unit	Level
UE EIRP	dBm	≥ 4
UE EIRP for UL 16 QAM	dBm	≥ 7
UE EIRP for UL 64 QAM	dBm	≥ 11
Operating conditions		Normal conditions

Table 6.4.2.1-3: Parameters for Error Vector Magnitude for power class 2, 3, and 4

Parameter	Unit	Level
UE EIRP	dBm	≥ -13
UE EIRP for UL 16 QAM	dBm	≥ -10
UE EIRP for UL 64 QAM	dBm	≥ -6
Operating conditions		Normal conditions

6.4.2.2 Carrier leakage

6.4.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier. The measurement interval is one slot in the time domain. The relative carrier leakage power is a power ratio of the additive sinusoid waveform to the power in the modulated waveform.

The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

6.4.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum confined within the configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.2-1 for power class 1 UEs.

Table 6.4.2.2.2-1: Minimum requirements for relative carrier leakage power for power class 1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

6.4.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.3-1 for power class 2.

Table 6.4.2.2.3-1: Minimum requirements for relative carrier leakage power for power class 2

Parameters	Relative Limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

6.4.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.4-1 for power class 3 UEs.

Table 6.4.2.2.4-1: Minimum requirements for relative carrier leakage power for power class 3

Parameters	Relative Limit (dBc)
EIRP > 0 dBm	-25
-13 dBm ≤ EIRP ≤ 0 dBm	-20

6.4.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by the configured UL CCs and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4.2.2.5-1 for power class 4.

Table 6.4.2.2.5-1: Minimum requirements for relative carrier leakage power for power class 4

Parameters	Relative Limit (dBc)
EIRP > 11 dBm	-25
-13 dBm ≤ EIRP ≤ 11 dBm	-20

6.4.2.3 In-band emissions

6.4.2.3.1 General

The in-band emission is defined as the average across 12 sub-carriers and as a function of the RB offset from the edge of the allocated UL transmission bandwidth. The in-band emission is measured as the ratio of the UE output power in a non–allocated RB to the UE output power in an allocated RB. The IBE requirement does not apply if UE declares support for *mpr-PowerBoost-FR2-r16*, UL transmission is QPSK,MPR_{f,c} = 0 and when NS_200 applies, and the network configures the UE to operate with *mpr-PowerBoost-FR2-r16*.

The basic in-band emissions measurement interval is identical to that of the EVM test.

The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

6.4.2.3.2 In-band emissions for power class 1

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.2-1 for power class 1 UEs.

Table 6.4.2.3.2-1: Requirements for in-band emissions for power class 1

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{\left(\Delta_{RB} - 1\right)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 27 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 27 dBm	
Carrier leakage	dBc	-25	Output power > 17 dBm	Carrier frequency (NOTES 4, 5)
		-20	4 dBm ≤ Output power ≤ 17 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (\overline{P}_{RB} 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. \overline{P}_{RB} is defined in NOTE 10.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrent* IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3).
- NOTE 7: N_{RB} is the Transmission Bandwidth Configuration (see Clause 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10: P_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

6.4.2.3.3 In-band emissions for power class 2

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.3-1 for power class 2.

Table 6.4.2.3.3-1: Requirements for in-band emissions for power class 2

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 16 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 16 dBm	
Carrier leakage	dBc	-25	Output power > 6 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 6 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (\overline{P}_{RB} 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. \overline{P}_{RB} is defined in NOTE 10.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrent* IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3).
- NOTE 7: N_{RB} is the Transmission Bandwidth Configuration (see Clause 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

6.4.2.3.4 In-band emissions for power class 3

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.4-1 for power class 3 UEs.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated (NOTE 2)
IQ Image	dB	-25	Output power > 10 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 10 dBm	, , ,
Carrier leakage	dBc	-25	Output power > 0 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 0 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (\overline{P}_{RB} 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. \overline{P}_{RB} is defined in NOTE 10.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter txDirectCurrentLocation in UplinkTxDirectCurrent IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3).
- NOTE 7: N_{RR} is the Transmission Bandwidth Configuration (see Clause 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10: P_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

6.4.2.3.5 In-band emissions for power class 4

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4.2.3.5-1 for power class 4 UEs.

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB		$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$	
IQ Image	dB	-25	Output power > 21 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 21 dBm	
Carrier leakage	dBc	-25	Output power > 11 dBm	Carrier frequency (NOTES 4, 5)

Table 6.4.2.3.5-1: Requirements for in-band emissions for power class 4

NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (\overline{P}_{RB} - 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. \overline{P}_{RB} is defined in NOTE 10.

-13 dBm ≤ Output power ≤ 11 dBm

- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD
- NOTE 3: The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit depend on the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrent* IE, and are those that are enclosed in the RBs containing the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth (see Clause 5.3).

-20

- NOTE 7: N_{RB} is the Transmission Bandwidth Configuration (see Clause 5.3).
- NOTE 8: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 9: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. Δ_{RB} = 1 or Δ_{RB} = -1 for the first adjacent RB outside of the allocated bandwidth).
- NOTE 10: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 11: All powers are EIRP in beam peak direction.

6.4.2.4 EVM equalizer spectrum flatness

The EVM measurement process (as described in Annex F) entails generation of a zero-forcing equalizer. The EVM equalizer spectrum flatness is defined in terms of the maximum peak-to-peak ripple of the equalizer coefficients (dB) across the allocated uplink block. The basic measurement interval is the same as for EVM.

For Pi/2 BPSK modulation, the minimum requirements are defined in Clause 6.4.2.5.

The peak-to-peak variation of the EVM equalizer coefficients contained within the frequency range of the uplink allocation shall not exceed the maximum ripple specified in Table 6.4.2.4-1 for normal conditions. For uplink allocations contained within both Range 1 and Range 2, the coefficients evaluated within each of these frequency ranges shall meet the corresponding ripple requirement and the following additional requirements: the relative difference between the maximum coefficient in Range 1 and the minimum coefficient in Range 2 (Table 6.4.2.4-1) must not be larger than 7 dB, and the relative difference between the maximum coefficient in Range 2 and the minimum coefficient in Range 1 must not be larger than 8 dB (see Figure 6.4.2.4-1).

The requirement is verified with the test metric of EVM SF (Link=TX beam peak direction, Meas=Link angle).

Table 6.4.2.4-1: Minimum requirements for EVM equalizer spectrum flatness (normal conditions)

Frequency range	Maximum ripple (dB)
Ful_Meas - F_center ≤ X MHz	6 (p-p)
(Range 1)	
Ful_Meas - F_center > X MHz	9 (p-p)
(Range 2)	
NOTE 1: FUL_Meas refers to the sub-carrier frequency for which	the equalizer coefficient is
evaluated	
NOTE 2: F_center refers to the center frequency of the CC	
NOTE 3: X, in MHz, is equal to 30 % of the CC bandwidth	

Table 6.4.2.4-2: (Void)

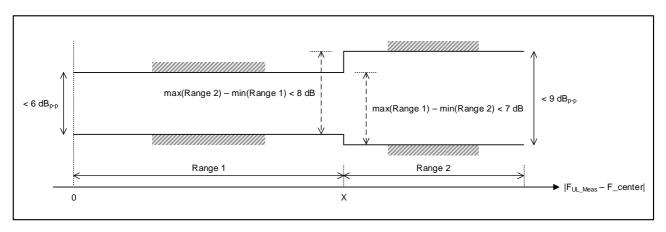


Figure 6.4.2.4-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation of the coefficients indicated under normal conditions

6.4.2.5 EVM spectral flatness for Pi/2 BPSK modulation

These requirements are defined for Pi/2 BPSK modulation. The EVM equalizer coefficients across the allocated uplink block shall be modified to fit inside the mask specified in Table 6.4.2.5-1 for normal conditions, prior to the calculation of EVM. The limiting mask shall be placed to minimize the change in equalizer coefficients in a sum of squares sense.

Table 6.4.2.5-1: Mask for EVM equalizer coefficients for pi/2 BPSK (normal conditions)

Frequency range	Parameter	Maximum ripple (dB)			
FuL_Meas - F_center ≤ X MHz	X1	6 (p-p)			
(Range 1)					
Ful_Meas - F_center > X MHz	X2	14 (p-p)			
(Range 2)					
NOTE 1: Ful_Meas refers to the sub-carrier frequency for which the equalizer coefficient is evaluated					
NOTE 2: F_center refers to the center frequency of an allocated block of PRBs					
NOTE 3: X, in MHz, is equal to 25% of the bandwidth of the PRB allocation					
NOTE 4: See Figure 6.4.2.5-1 for description of X1, X2 and X3					

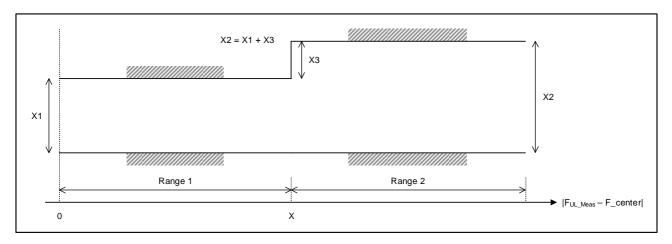


Figure 6.4.2.5-1: The limits for EVM equalizer spectral flatness with the maximum allowed variation.

F_center denotes the center frequency of the allocated block of PRBs.

This requirement does not apply to other modulation types. The UE shall be allowed to employ spectral shaping for Pi/2 BPSK. The shaping filter shall be restricted so that the impulse response of the transmit chain shall meet

$$\begin{aligned} \left| \tilde{a}_{t}(t,0) \right| \geq \left| \tilde{a}_{t}(t,\tau) \right| & \forall \tau \neq 0 \\ 20log_{10} \left| \tilde{a}_{t}(t,\tau) \right| < -15 \text{ dB} & 1 < \tau < M - 1, \end{aligned}$$

Where:

$$|\tilde{a}_t(t,\tau)| = IDFT\{ |\tilde{a}_t(t,f)| e^{j\phi(t,f)} \},$$

f is the frequency of the M allocated subcarriers,

 $\tilde{a}(t,f)$ and $\phi(t,f)$ are the amplitude and phase response, respectively of the transmit chain

0dB reference is defined as $20\log_{10} |\tilde{a}_t(t,0)|$

6.4A Transmit signal quality for CA

6.4A.0 General

The requirements in this clause apply if the UE has at least one of UL or DL configured for CA.

6.4A.1 Frequency error

The requirements in this clause apply to UEs of all power classes.

For intra-band contiguous and non-contiguous carrier aggregation, the UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequencies per band shall be accurate to within \pm 0.1 PPM observed over a period of 1ms of cumulated measurement intevals compared to the carrier frequency of primary component carrier received from the gNB.

The frequency error is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction.

6.4A.2 Transmit modulation quality

6.4A.2.0 General

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in clauses 6.4A.2.1, 6.4A.2.2, and 6.4A.2.3.

All the parameters defined in clause 6.4A.2 are defined using the measurement methodology specified in Annex F.

All the requirements in 6.4A.2 are defined as directional requirement. The requirements are verified in beam locked mode on beam peak direction, with both UL polarizations active.

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrenList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4A.2.2 and 6.4A.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

The UE is defined to be configured for CA operation when it has at least one of UL or DL configured for CA.

6.4A.2.1 Error Vector magnitude

The requirements in this clause apply to UEs of all power classes. For intra-band contiguous and non-contiguous carrier aggregation, the Error Vector Magnitude requirement of clause 6.4.2.2 is defined for each component carrier. Requirements only apply with PRB allocation in one of the component carriers. Similar transmitter impairment removal procedures are applied for CA waveform before EVM calculation as is specified for non-CA waveform.

6.4A.2.2 Carrier leakage

6.4A.2.2.1 General

Carrier leakage is an additive sinusoid waveform. The carrier leakage requirement is defined for each component carrier and is measured on the component carrier with PRBs allocated. The measurement interval is one slot in the time domain.

Note: When UE has DL configured for non-contiguous CA, carrier leakage may land outside the spectrum occupied by all configured UL and DL CC.

The relative carrier leakage power is a power ratio of the additive sinusoid waveform and the modulated waveform. The requirement is verified with the test metric of Carrier Leakage (Link=TX beam peak direction, Meas=Link angle).

6.4A.2.2.2 Carrier leakage for power class 1

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.2-1 for power class 1 UEs.

Table 6.4A.2.2.2-1: Minimum requirements for relative carrier leakage for power class 1

Parameters	Relative Limit (dBc)
EIRP > 17 dBm	-25
4 dBm ≤ EIRP ≤ 17 dBm	-20

6.4A.2.2.3 Carrier leakage for power class 2

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.3-1 for power class 2.

Table 6.4A.2.2.3-1: Minimum requirements for relative carrier leakage power class 2

Parameters	Relative limit (dBc)
EIRP > 6 dBm	-25
-13 dBm ≤ EIRP ≤ 6 dBm	-20

6.4A.2.2.4 Carrier leakage for power class 3

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.4-1 for power class 3 UEs.

Table 6.4A.2.2.4-1: Minimum requirements for relative carrier leakage power class 3

Parameters	Relative limit (dBc)
Output power > 0 dBm	-25
-13 dBm ≤ Output	-20
power EIRP ≤ 0 dBm	

6.4A.2.2.5 Carrier leakage for power class 4

When carrier leakage is contained inside the spectrum occupied by all configured UL and DL CCs, the relative carrier leakage power shall not exceed the values specified in Table 6.4A.2.2.5-1 for power class 4 UEs.

Table 6.4A.2.2.5-1: Minimum requirements for relative carrier leakage power class 4

Parameters	Relative limit (dBc)
Output power > 11 dBm	-25
-13 dBm ≤ Output power EIRP ≤ 11 dBm	-20

6.4A.2.3 Inband emissions

6.4A.2.3.1 General

Inband emission requirement is defined over the spectrum occupied by all configured UL and DL CCs. The measurement interval is as defined in clause 6.4.2.4. The requirement is verified with the test metric of In-band emission (Link=TX beam peak direction, Meas=Link angle).

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in this clause apply with all component carriers active and with one single contiguous PRB allocation in one of uplink component carriers. The inband emission is defined as the interference falling into the non-allocated resource blocks for all component carriers.

6.4A.2.3.2 Inband emissions for power class 1

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.2-1 for power class 1 UEs.

Table 6.4A.2.3.2-1: Requirements for in-band emissions for power class 1

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(\text{EVM}) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 27 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 27 dBm	
Carrier leakage	dBc	-25	Output power > 17 dBm	Carrier frequency (NOTES 4, 5)
		-20	4 dBm ≤ Output power ≤ 17 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. P RB is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the carrier frequency reported DC location position, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.3.3 Inband emissions for power class 2

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.3-1 for power class 2.

Table 6.4A.2.3.3-1: Requirements for in-band emissions for power class 2

Parameter description	Unit	Limit (NOTE 1)		Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(\text{EVM}) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 16 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 16 dBm	
Carrier leakage	dBc	-25	Output power > 6 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 6 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (\overline{P}_{RB} 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. \overline{P}_{RB} is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the reported DC location position, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.3.4 Inband emissions for power class 3

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.4-1 for power class 3 UEs.

Table 6.4A.2.3.4-1: Requirements for in-band emissions for power class 3

Parameter description	Unit	Limit (NOTE 1)		Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(EVM) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 10 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 10 dBm	
Carrier leakage	dBc	-25	Output power > 0 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 0 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. P RB is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For Pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the reported DC location position, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.3.5 Inband emissions for power class 4

The average of the in-band emission measurement over 10 sub-frames shall not exceed the values specified in Table 6.4A.2.3.5-1 for power class 4 UEs.

Table 6.4A.2.3.5-1: Requirements for in-band emissions for power class 4

Parameter description	Unit		Limit (NOTE 1)	Applicable Frequencies
General	dB	$max \begin{bmatrix} -25 - 10.\log_{10}\left(\frac{N_{RB}}{L_{CRB}}\right), \\ 20.\log_{10}(\text{EVM}) - 5.\frac{(\Delta_{RB} - 1)}{L_{CRB}}, \\ -55.1dBm - \overline{P_{RB}} \end{bmatrix}$		Any non-allocated RB in allocated component carrier and not allocated component carriers (NOTE 2)
IQ Image	dB	-25	Output power > 21 dBm	Image frequencies (NOTES 2, 3)
		-20	Output power ≤ 21 dBm	
Carrier leakage	dBc	-25	Output power > 11 dBm	Carrier frequency (NOTES 4, 5)
		-20	-13 dBm ≤ Output power ≤ 11 dBm	

- NOTE 1: An in-band emissions combined limit is evaluated in each non-allocated RB. For each such RB, the minimum requirement is calculated as the higher of (P RB 25 dB) and the power sum of all limit values (General, IQ Image or Carrier leakage) that apply. P RB is defined in NOTE 9.
- NOTE 2: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured average power per allocated RB, where the averaging is done across all allocated RBs. For pi/2 BPSK with Spectrum Shaping, the limit is expressed as a ratio of measured power in one non-allocated RB to the measured power in the allocated RB with highest PSD.
- NOTE 3: Image frequencies for UL CA are specified in relation to either UL or DL carrier frequency. The applicable frequencies for this limit are those that are enclosed in the reflection of the allocated bandwidth, based on symmetry with respect to the reported DC location position, but excluding any allocated RBs.
- NOTE 4: The measurement bandwidth is 1 RB and the limit is expressed as a ratio of measured power in one non-allocated RB to the measured total power in all allocated RBs.
- NOTE 5: The applicable frequencies for this limit are those that are enclosed in the RBs containing the DC frequency, or in the two RBs immediately adjacent to the DC frequency but excluding any allocated RB.
- NOTE 6: L_{CRB} is the Transmission Bandwidth for kth allocated component carrier (see Figure 5.3.3-1).
- NOTE 7: EVM s the limit for the modulation format used in the allocated RBs.
- NOTE 8: Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB outside of the allocated bandwidth), and may take non-integer values when the carrier spacing between the CCs is not a multiple of RB.
- NOTE 9: \overline{P}_{RB} is an average of the transmitted power over 10 sub-frames normalized by the number of allocated RBs, measured in dBm.
- NOTE 10: All powers are EIRP in beam peak direction.

6.4A.2.4 EVM equalizer spectrum flatness

6.4D Transmit signal quality for UL MIMO

6.4D.0 General

For a UE supporting UL MIMO, the transmit modulation quality requirements in clause 6.4 apply but with all references to sub-clauses 6.3.1.x in clause 6.4 redirected to sub-clauses 6.3D.1.x, where 'x' depends on power class. The requirements apply when the UE is configured for 2-layer UL MIMO transmission as specified in Table 6.2D.1.0-1

The requirement may alternatively be verified in each of the single layer UL MIMO configurations as specified in Table 6.4D.0-1. In this case, the transmit modulation quality requirements in clause 6.4 apply without modification.

Table 6.4D.0-1: Alternative UL MIMO configuration for transmit signal quality tests

Transmission scheme	DCI format	TPMI Index
Codebook based uplink	DCI format 0_1	0
Codebook based uplink	DCI format 0_1	1

6.4D.1 Frequency error for UL MIMO

For a UE supporting UL MIMO, the UE basic measurement interval of modulated carrier frequency is 1 UL slot. The mean value of basic measurements of UE modulated carrier frequency at each layer shall be accurate to within \pm 0.1 PPM observed over a period of 1ms of cumulated measurement intevals compared to the carrier frequency received from the NR Node B.

6.4D.2 Transmit modulation quality for UL MIMO

For UE supporting UL MIMO, the transmit modulation quality requirements are specified per layer in terms of:

Error Vector Magnitude (EVM) for the allocated resource blocks (RBs)

EVM equalizer spectrum flatness derived from the equalizer coefficients generated by the EVM measurement process

Carrier leakage (caused by IQ offset)

For UE supporting UL MIMO, the transmit modulation quality requirements are specified as the total component of EIRP in terms of:In-band emissions for the non-allocated RB

The requirements are defined as directional requirements. The requirements are verified in beam locked mode in the TX beam peak direction (Link=TX beam peak direction, Meas=Link angle).

In case the parameter 3300 or 3301 is reported from UE via the parameter *txDirectCurrentLocation* in *UplinkTxDirectCurrentList* IE (as defined in TS 38.331 [13]), carrier leakage measurement requirement in clause 6.4D.2.2 and 6.4D.2.3 shall be waived, and the RF correction with regard to the carrier leakage and IQ image shall be omitted during the calculation of transmit modulation quality.

6.4D.3 Time alignment error for UL MIMO

For a UE with multiple physical antenna ports supporting UL MIMO, this requirement applies to frame timing differences between transmissions on multiple physical antenna ports in the codebook transmission scheme.

The time alignment error (TAE) is defined as the average frame timing difference between any two transmissions on different physical antenna ports.

For a UE with multiple physical antenna ports, the Time Alignment Error (TAE) shall not exceed 130 ns.

6.4D.4 Requirements for coherent UL MIMO

For coherent UL MIMO, Table 6.4D.4-1 lists the maximum allowable difference between the measured relative power and phase errors between different physical antenna ports in any slot within the specified time window from the last transmitted SRS on the same antenna ports, for the purpose of uplink transmission (codebook or non-codebook usage) and those measured at that last SRS. The requirements in Table 6.4D.4-1 apply when the UL transmission power at each physical antenna port is larger than 0 dBm for SRS transmission and for the duration of time window. The requirement is verified with the test metric of EIRP (Link=TX Beam peak direction, Meas=Link angle).

Table 6.4D.4-1: Maximum allowable difference of relative phase and power errors in a given slot compared to those measured at last SRS transmitted

Difference of relative phase error	Difference of relative power error	Time window
40 degrees	4 dB	20 msec

The above requirements apply when all of the following conditions are met within the specified time window:

- UE is not signaled with a change in number of SRS ports in SRS-config, or a change in PUSCH-config
- UE remains in DRX active time (UE does not enter DRX OFF time)
- No measurement gap occurs
- No instance of SRS transmission with the usage antenna switching occurs
- Active BWP remains the same
- EN-DC and CA configuration is not changed for the UE (UE is not configured or de-configured with PScell or SCell(s))

6.5 Output RF spectrum emissions

6.5.1 Occupied bandwidth

Occupied bandwidth is defined as the bandwidth containing 99 % of the total integrated mean power of the transmitted spectrum on the assigned channel. The occupied bandwidth for all transmission bandwidth configurations (Resources Blocks) shall be less than the channel bandwidth specified in Table 6.5.1-1.

The occupied bandwidth is defined as a directional requirement. The requirement is verified in beam locked mode with the test metric of OBW (Link=TX beam peak direction, Meas=Link angle).

Table 6.5.1-1: Occupied channel bandwidth

6.5.2 Out of band emissions

6.5.2.0 General

The Out of band emissions are unwanted emissions immediately outside the assigned channel bandwidth resulting from the modulation process and non-linearity in the transmitter but excluding spurious emissions. This out of band emission limit is specified in terms of a spectrum emission mask and an adjacent channel leakage power ratio. Additional requirements to protect specific bands are also considered.

The requirements in clause 6.5.2.1 only apply when both UL and DL of a UE are configured for single CC operation, and they are of the same bandwidth. For a UE that is configured for single CC operation with different channel bandwidths in UL and DL, the requirements in clause 6.5A.2.1 apply.

All out of band emissions for frequency range 2 are TRP.

6.5.2.1 Spectrum emission mask

The spectrum emission mask of the UE applies to frequencies (Δf_{OOB}) starting from the \pm edge of the assigned NR channel bandwidth. For frequencies offset greater than F_{OOB} as specified in Table 6.5.2.1-1 the spurious requirements in clause 6.5.3 are applicable.

The power of any UE emission shall not exceed the levels specified in Table 6.5.2.1-1 for the specified channel bandwidth. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Table 6.5.2.1-1: General NR spectrum emission mask for frequency range 2.

Spect	Spectrum emission limit (dBm) / Channel bandwidth					
Δf _{OOB} (MHz)	50 MHz	100 MHz	200 MHz	400 MHz	Measurement bandwidth	
± 0-5	-5	-5	-5	-5	1 MHz	
± 5-10	-13	-5	-5	-5	1 MHz	
± 10-20	-13	-13	-5	-5	1 MHz	
± 20-40	-13	-13	-13	-5	1 MHz	
± 40-100	-13	-13	-13	-13	1 MHz	
± 100-200		-13	-13	-13	1 MHz	
± 200-400			-13	-13	1 MHz	
± 400-800				-13	1 MHz	
NOTE 1: Void						

6.5.2.2 Void

6.5.2.3 Adjacent channel leakage ratio

Adjacent Channel Leakage power Ratio (ACLR) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency. ACLR requirement is specified for a scenario in which adjacent carrier is another NR channel.

NR Adjacent Channel Leakage power Ratio (NR_{ACLR}) is the ratio of the filtered mean power centred on the assigned channel frequency to the filtered mean power centred on an adjacent channel frequency at nominal channel spacing. The assigned NR channel power and adjacent NR channel power are measured with rectangular filters with measurement bandwidths specified in Table 6.5.2.3-1.

If the measured adjacent channel power is greater than -35 dBm then the NR_{ACLR} shall be higher than the value specified in Table 6.5.2.3-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

	Channel bandwidth / NR _{ACLR} / Measurement bandwidth			
	50 MHz	100 MHz	200 MHz	400 MHz
NR _{ACLR} for band n257, n258, n261	17 dB	17 dB	17 dB	17 dB
NR _{ACLR} for band n259, n260	16 dB	16 dB	16 dB	16 dB
NR channel measurement bandwidth (MHz)	47.58	95.16	190.20	380.28
Adjacent channel centre frequency offset (MHz)	+50 / -50	+100 / -100	+200 / -200	+400 / -400

Table 6.5.2.3-1: General requirements for NR_{ACLR}

6.5.3 Spurious emissions

Spurious emissions are emissions which are caused by unwanted transmitter effects such as harmonics emission, parasitic emissions, intermodulation products and frequency conversion products, but exclude out of band emissions unless otherwise stated. The spurious emission limits are specified in terms of general requirements in line with SM.329 [7] and NR operating band requirement to address UE co-existence. Spurious emissions are measured as TRP.

To improve measurement accuracy, sensitivity and efficiency, the resolution bandwidth may be smaller than the measurement bandwidth. When the resolution bandwidth is smaller than the measurement bandwidth, the result should be integrated over the measurement bandwidth in order to obtain the equivalent noise bandwidth of the measurement bandwidth.

Unless otherwise stated, the spurious emission limits apply for the frequency ranges that are more than F_{OOB} (MHz) in Table 6.5.3-1 starting from the edge of the assigned NR channel bandwidth. The spurious emission limits in Table 6.5.3-2 apply for all transmitter band configurations (NRB) and channel bandwidths. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

Table 6.5.3-1: Boundary between NR out of band and spurious emission domain

Channel bandwidth	50	100	200	400
	MHz	MHz	MHz	MHz
OOB boundary Foob	100	200	400	800

Table 6.5.3-2: Spurious emissions limits

Frequency Range	Maximum Level	Measurement bandwidth
30 MHz ≤ f < 1000 MHz	-36 dBm	100 kHz
1 GHz ≤ f < 12.75 GHz	-30 dBm	1 MHz
12.75 GHz ≤ f ≤ 2 nd harmonic of the upper frequency edge of the UL operating band in GHz	-13 dBm	1 MHz

6.5.3.1 Spurious emission band UE co-existence

This clause specifies the requirements for the specified NR band, for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

Table 6.5.3.1-1: Requirements

NR Band	Spurious emission						
	Protected band/frequency range		ency (MHz	/ range z)	Maximum Level (dBm)	MBW (MHz)	NOTE
n257	NR Band n260	F _{DL_low}	-	F _{DL_high}	-2	100	
	Frequency range	57000	-	66000	2	100	
	Frequency range	23600	-	24000	1	200	3
n258	Frequency range	57000	-	66000	2	100	
n259	NR Band 257	F _{DL_low}	-	F _{DL_high}	-5	100	
	NR Band 261	F _{DL_low}	-	F _{DL_high}	-5	100	
	Frequency range	36000	-	37000	7	1000	
	Frequency range	57000	-	66000	2	100	
n260	NR Band 257	F _{DL_low}	-	F _{DL_high}	-5	100	
	NR Band 261	F _{DL_low}	-	F _{DL_high}	-5	100	
	Frequency range	57000	-	66000	2	100	
n261	NR Band 260	F _{DL_low}	-	F _{DL_high}	-2	100	
	Frequency range	57000	-	66000	2	100	

NOTE 1: F_{DL_low} and F_{DL_high} refer to each NR frequency band specified in Table 5.2-1

NOTE 2: Void

NOTE 3: The protection of frequency range 23600-24000 MHz is meant for protection of satellite passive services.

6.5.3.2 Additional spurious emissions

6.5.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

6.5.3.2.2 Void

Table 6.5.3.2.2-1: (Void)

6.5.3.2.3 Additional spurious emission requirements for NS_202

When "NS_202" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.3-1.

Table 6.5.3.2.3-1: Additional requirements (NS_202)

Frequency Range	Maximum Level	Measurement bandwidth	NOTE
7.25 GHz ≤ f ≤ 2 nd harmonic of the upper frequency edge of the UL operating band	-10 dBm	100 MHz	
23.6 GHz ≤ f ≤ 24.0 GHz	+1 dBm	200 MHz	1

NOTE 1: This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth. The protection of frequency range 23600 - 24000 MHz is meant for protection of satellite passive services.

6.5.3.2.4 Additional spurious emission requirements for NS_203

When "NS_203" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.4-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) in Table 6.5.3-1 from the edge of the channel bandwidth.

Table 6.5.3.2.4-1: Additional requirements (NS_203)

Frequency band (GHz)	Spectrum emission limit (dBm)	Measurement bandwidth
$23.6 \le f \le 24.0$	+1	200 MHz

6.5A Output RF spectrum emissions for CA

6.5A.1 Occupied bandwidth for CA

6.5A.1.0 General

The occupied bandwidth for UL CA is defined as a directional requirement. The requirement is verified in beam locked mode on beam peak direction. In case the CA configuration consists of a single UL CC, the occupied bandwidth requirement defined in subclause 6.5.1 applies.

6.5A.1.1 Occupied bandwidth for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the occupied bandwidth is a measure of the bandwidth containing 99 % of the total integrated power of the transmitted spectrum. The occupied bandwidth for UL CA shall be less than the UL aggregated channel bandwidth defined in clause 5.3A.

6.5A.1.2 Occupied bandwidth for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the occupied bandwidth requirement is met when the ratio of the transmitted power in all sub-blocks of the UL CA configuration to the total integrated power of the transmitted spectrum is greater than 99%.

6.5A.2 Out of band emissions

6.5A.2.1 Spectrum emission mask for CA

6.5A.2.1.0 General

The requirements specified in this clause shall apply if the UE has at least one of UL or DL configured for CA or if the UE is configured for single CC operation with different channel bandwidths in UL and DL carriers. In case the CA

configuration consists of a single UL CC, spectrum emission mask defined in subclause 6.5.2.1 applies. Spectral emission mask requirements do not apply at any frequency where IBE requirements of clause 6.4A.2.3 apply.

The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

6.5A.2.1.1 Spectrum emission mask for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the spectrum emission mask of the UE applies to frequencies (Δf_{OOB}) starting from the \pm edge of the UL aggregated channel bandwidth (Table 5.3A.5-1). For any bandwidth class defined in Table 5.3A.5-1, the UE emission shall not exceed the levels specified in Table 6.5A.2.1-1.

Table 6.5A.2.1.1-1: General NR spectrum emission mask for intra-band contiguous CA in frequency range 2

Δf _{OOB} (MHz)	Any carrier aggregation bandwidth class	Measurement bandwidth
± 0-0.1*BW _{Channel_CA}	-5	1 MHz
± 0.1*BW _{Channel_CA} -	-13	1 MHz
2*BWChannel_CA		
NOTE 1: (void)		

6.5A.2.1.2 Spectrum emission mask for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the spectrum emission mask requirement is defined as a composite spectrum emissions mask. Composite spectrum emission mask applies to frequencies up to \pm Δf_{OOB} starting from the edge of each UL sub-block. Composite spectrum emission mask is defined as follows:

- a) Composite spectrum emission mask is a combination of individual spectrum emissions masks defined for each sub-block. If for some frequency, spectrum emission masks from multiple sub-blocks overlap, the spectrum emission mask allowing the highest power spectral density applies for that frequency
- b) In case a sub-block comprises of multiple component carriers, the spectrum emissions mask is defined in subclause 6.5A.2.1.1 or in case of a single component carrier, the sub-block spectrum emission mask is defined in subclause 6.5.2.1
- c) If for some frequency the spectrum emission mask of one sub-block overlaps another sub-block, the emission mask does not apply for that frequency.
- d) If carrier leakage or I/Q image lands inside the spectrum occupied by the configured UL and DL CCs, exception to the general spectrum emission mask limit applies. For carrier leakage the requirements specified in section 6.4A.2.2 shall apply. For I/Q image the requirements specified in section 6.4A.2.3 shall apply.

6.5A.2.3 Adjacent channel leakage ratio for CA

6.5A.2.3.1 Adjacent channel leakage ratio for CA intra-band contiguous UL CA

In case the CA configuration consists of a single UL CC, the adjacent channel leakage ratio defined in subclause 6.5.2.3 applies. For intra-band contiguous UL carrier aggregation, the carrier aggregation NR adjacent channel leakage power ratio (CA NR_{ACLR}) is the ratio of the filtered mean power centred on the UL aggregated channel bandwidth to the filtered mean power centred on an adjacent UL aggregated channel bandwidth at spacing equal to the UL aggregated channel bandwidth. The assigned UL aggregated channel bandwidth power and adjacent UL aggregated channel bandwidth power are measured with rectangular filters with measurement bandwidths specified in Table 6.5A.2.3.1-1. If the measured adjacent channel power is greater than -35 dBm then the CA NR_{ACLR} shall be higher than the value specified in Table 6.5A.2.3.1-1.

Table 6.5A.2.3.1-1: General requirements for contiguous UL CA NR_{ACLR}

	CA bandwidth class / CA NR _{ACLR} / Measurement bandwidth Any CA bandwidth class
CA NR _{ACLR} for band n257, n258, n261	17 dB
CA NR _{ACLR} for band n259, n260	16 dB
NR channel measurement bandwidth ¹	BW _{Channel_CA} - 2*BW _{GB}
Adjacent channel centre frequency offset (in MHz)	+ BW _{Channel_CA} / - BW _{Channel_CA}
NOTE 1: BW _{GB} is defined in clause 5.3A.2.	

6.5A.2.3.2 Adjacent channel leakage ratio for CA intra-band non-contiguous UL CA

For intra-band non-contiguous carrier aggregation, adjacent channel leakage power ratio (CA NR_{ACLR}) is the ratio of the sum of the filtered mean powers centred on each sub-block bandwidth to the filtered mean power centred on an adjacent sub-block frequency at nominal spacing equal to the sub-block bandwidth. The power in the configured UL CCs and power in the sub-block bandwidth adjacent to each sub-block of configured UL CCs are measured with rectangular filters with measurement bandwidths specified in Table 6.5A.2.3.1-2. In case a sub-block consists of a single component carrier, the measurement bandwidths and adjacent frequency offset from subclause 6.5.2.3 shall be used. If the measured adjacent sub-block power is greater than -35 dBm then the CA NR_{ACLR} shall be higher than the value specified in Table 6.5A.2.3.1-2.

No requirement applies in the gap between neighbouring sub-blocks if the frequency span between the lowest edge of the upper sub-block and the highest edge of the lower sub-block is smaller than the bandwidth of either sub-block.

Table 6.5A.2.3.1-2: General requirements for NC UL CA NR_{ACLR}

	CA bandwidth class / CA NR _{ACLR} / Measurement bandwidth	
	Any CA bandwidth class	
CA NR _{ACLR} for band n257, n258, n261	17 dB	
CA NR _{ACLR} for band n260	16 dB	
NR channel measurement bandwidth ¹	$\Sigma(BW_{Channel,block})$	
Adjacent sub-block centre frequency offset (in MHz)	+ BWChannel,block / - BWChannel_block	
NOTE 1: BWChannel_block is defined in clause 5.3A.2. NOTE 2: 'Adjacent sub-block centre frequency offset' is defined for each sub-block in the UL CA configuration		

6.5A.3 Spurious emissions for CA

6.5A.3.0 General spurious emissions for CA

6.5A.3.0.0 General

This clause specifies the spurious emission requirements for carrier aggregation. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction).

In case the CA configuration consists of a single UL CC, spurious emissions requirements defined in subclause 6.5.3 apply. Spurious emissions requirements do not apply at any frequency where IBE requirements of clause 6.4A.2.3 apply.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

6.5A.3.0.1 Spurious emissions for intra-band contiguous UL CA

For intra-band contiguous UL carrier aggregation, the spurious emission limits apply for the frequency ranges that are more than F_{OOB} (MHz) from the edge of the UL aggregated channel bandwidth, where F_{OOB} is defined as the twice the UL aggregated channel bandwidth. For frequencies Δf_{OOB} greater than F_{OOB} , the spurious emission requirements in Table 6.5.3-2 are applicable.

6.5A.3.0.2 Spurious emissions for intra-band non-contiguous UL CA

For intra-band non-contiguous UL carrier aggregation, the spurious emission requirement is defined as a composite spurious emission requirement which is a combination of individual spurious emission requirements defined for each UL sub-block. The limits in Table 6.5.3-2 apply for the frequency ranges that are more than F_{OOB} (MHz) from the edge of each UL sub-block but excludes frequency ranges that coincide with another UL sub-block. No spurious emission limit applies in the gap between neighbouring UL sub-blocks if the frequency span between the lowest edge of the upper sub-block and the highest edge of the lower sub-block is smaller than F_{OOB} L + F_{OOB} H.

6.5A.3.1 Spurious emission band UE co-existence for UL CA

This clause specifies the requirements for the specified contiguous or non-contiguous ULcarrier aggregation configurations for coexistence with protected bands.

NOTE: For measurement conditions at the edge of each frequency range, the lowest frequency of the measurement position in each frequency range should be set at the lowest boundary of the frequency range plus MBW/2. The highest frequency of the measurement position in each frequency range should be set at the highest boundary of the frequency range minus MBW/2. MBW denotes the measurement bandwidth defined for the protected band.

For intra-band contiguous and non-contiguous carrier aggregation, the requirements in Table 6.5A.3-1 apply.

CA band Spurious emission Maximum **MBW NOTE** Protected band / frequency Frequency range range (MHz) Level (MHz) (dBm) $F_{D\underline{L_low}}$ CA_n257 NR Band n260 100 F_{DL_high} -2 66000 Frequency range 57000 2 100 Frequency range 23600 200 24000 1 2 CA_n258 Frequency range 57000 66000 2 100 NR Band 257 100 CA_n259 $F_{\mathsf{DL_low}}$ F_{DL_high} -5 NR Band 261 -5 100 F_{DL_low} F_{DL_high} Frequency range 36000 37000 7 1000 Frequency range 57000 66000 2 100 CA_n260 NR Band 257 F_{DL_low} F_{DL_high} -5 100 NR Band 261 F_{DL_low} F_{DL_high} -5 100 Frequency range 57000 66000 2 100 CA_n261 NR Band 260 F_{DL_low} -2 100 F_{DL_high} 57000 100 Frequency range 66000

Table 6.5A.3.1-1: Requirements for CA

NOTE 1: FDL_low and FDL_high refer to each NR frequency band specified in Table 5.2-1

NOTE 2: The protection of frequency range 23600-24000 MHz is meant for protection of satellite passive services.

6.5A.3.2 Additional spurious emissions

6.5A.3.2.1 General

These requirements are specified in terms of an additional spectrum emission requirement. Additional spurious emission requirements are signalled by the network to indicate that the UE shall meet an additional requirement for a specific deployment scenario as part of the cell handover/broadcast message.

6.5A.3.2.2 Void

6.5A.3.2.3 Additional spurious emission requirements for CA NS 202

When "CA_NS_202" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.3-1.

6.5A.3.2.4 Additional spurious emission requirements for CA_NS_203

When "CA_NS_203" is indicated in the cell, the power of any UE emission shall not exceed the levels specified in Table 6.5.3.2.4-1. This requirement also applies for the frequency ranges that are less than F_{OOB} (MHz) as defined in section 6.5A.3.

6.5D Output RF spectrum emissions for UL MIMO

6.5D.1 Occupied bandwidth for UL MIMO

For UE(s) supporting UL MIMO, the occupied bandwidth requirement in clause 6.5.1 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.5D.2 Out of band emissions for UL MIMO

For UE(s) supporting UL MIMO, the out of band emissions requirements in clause 6.5.2 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.5D.3 Spurious emissions for UL MIMO

For UE(s) supporting UL MIMO, the spurious emissions requirements in clause 6.5.3 apply. The requirements shall be met with the UL MIMO configurations specified in Table 6.2D.1.0-1.

6.6 Beam correspondence

6.6.1 General

Beam correspondence is the ability of the UE to select a suitable beam for UL transmission based on DL measurements with or without relying on UL beam sweeping. Unless explicitly addressed in subclauses below, the beam correspondence requirement is fulfilled if the UE meets the corresponding minimum peak EIRP requirement and spherical coverage requirement for that power class with its autonomously chosen UL beams and without uplink beam sweeping.

6.6.2 Void

6.6.3 Void

6.6.4 Beam correspondence for power class 3

6.6.4.1 General

The beam correspondence requirement for power class 3 UEs consists of three components: UE minimum peak EIRP (as defined in Clause 6.2.1.3), UE spherical coverage (as defined in Clause 6.2.1.3), and beam correspondence tolerance (as defined in Clause 6.6.4.2). The beam correspondence requirement is fulfilled if the UE satisfies one of the following conditions, depending on the UE's beam correspondence capability IE *beamCorrespondenceWithoutUL-BeamSweeping*, as defined in TS 38.306 [14]:

- If beamCorrespondenceWithoutUL-BeamSweeping is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with its autonomously chosen UL beams and without uplink beam sweeping. Such a UE is considered to have met the beam correspondence tolerance requirement.
- If beamCorrespondenceWithoutUL-BeamSweeping and beamCorrespondenceSSB-based-r16 are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.2.
- If beamCorrespondenceWithoutUL-BeamSweeping and beamCorrespondenceCSI-RS-based-r16 are supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.3.
- If beamCorrespondenceWithoutUL-BeamSweeping is not present, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].
- If beamCorrespondenceWithoutUL-BeamSweeping is not present and beamCorrespondenceSSB-based-r16 is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping using the side conditions for SSB based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.2. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].
- If beamCorrespondenceWithoutUL-BeamSweeping is not present and beamCorrespondenceCSI-RS-based-r16 is supported, the UE shall meet the minimum peak EIRP requirement according to Table 6.2.1.3-1 and spherical coverage requirement according to Table 6.2.1.3-3 with uplink beam sweeping using the side conditions for CSI-RS based enhanced beam correspondence requirements as defined in Clause 6.6.4.3.3. Such a UE shall meet the beam correspondence tolerance requirement defined in Clause 6.6.4.2 and shall support uplink beam management, as defined in TS 38.306 [14].

6.6.4.2 Beam correspondence tolerance for power class 3

The beam correspondence tolerance requirement $\Delta EIRP_{BC}$ for power class 3 UEs is defined based on a percentile of the distribution of $\Delta EIRP_{BC}$, defined as $\Delta EIRP_{BC}$ = $EIRP_2$ - $EIRP_1$ over the link angles spanning a subset of the spherical coverage grid points, such that

- EIRP₁ is the total EIRP in dBm calculated based on the beam the UE chooses autonomously (corresponding beam) to transmit in the direction of the incoming DL signal, which is based on beam correspondence without relying on UL beam sweeping.
- EIRP₂ is the best total EIRP (beam yielding highest EIRP in a given direction) in dBm which is based on beam correspondence with relying on UL beam sweeping.
- The link angles are the ones corresponding to the top Nth percentile of the EIRP₂ measurement over the whole sphere, where the value of N is according to the test point of EIRP spherical coverage requirement for power class 3, i.e. N = 50.

For power class 3 UEs, the requirement is fulfilled if the UE's corresponding UL beams satisfy the maximum limit in Table 6.6.4.2-1.

Table 6.6.4.2-1: UE beam correspondence tolerance for power class 3

Operating band	Max ∆EIRP _{BC} at 85 th %-tile ∆EIRP _{BC} CDF (dB)	
n257	3.0	
n258	3.0	
n259	3.2	
n260	3.2	
n261	3.0	
NOTE: The require	ments in this table are verified	
only under normal temperature conditions as defined in Annex F.2.1		

6.6.4.3 Side Conditions

6.6.4.3.1 Side Condition for beam correspondence based on SSB and CSI-RS

The beam correspondence requirements are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided and Type D QCL shall be maintained between SSB and CSI-RS.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-1 and Table 6.6.4.3.1-2.

Table 6.6.4.3.1-1: Conditions for SSB based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-96.2	≥6
-	n258	-96.2	
	n259	-90.7	
	n260	-91.9	
	n261	-96.2	

NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are increased by ΔMB_{S,n}, the UE multi-band relaxation factor in dB specified in clause 6.2.1.

NOTE 2: Values specified at the radiated requirements reference point to give minimum SSB Ês/lot, with no applied noise.

Table 6.6.4.3.1-2: Conditions for CSI-RS based L1-RSRP measurements for beam correspondence

Angle of arrival	NR operating bands	Minimum CSI-RS_RP Note 2	CSI-RS Ês/lot
		dBm / SCS _{CSI-RS}	dB
		SCS _{CSI-RS} = 120 kHz	
All angles Note 1	n257	-96.2	≥6
	n258	-96.2	
	n259	-90.7	
	n260	-91.9	
	n261	-96.2	

NOTE 1: For UEs that support multiple FR2 bands, the Minimum CSI-RS_RP values are increased by $\Delta MB_{S,n}$, the UE multi-band relaxation factor in dB specified in clause 6.2.1.

NOTE 2: Values specified at the radiated requirements reference point to give minimum CSI-RS Ês/lot, with no applied noise.

6.6.4.3.2 Side Condition for SSB based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on SSB are only applied under the following side conditions:

- The downlink reference signal SSB is provided and CSI-RS is not provided.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-1.

6.6.4.3.3 Side Condition for CSI-RS based enhanced Beam Correspondence requirements

The beam correspondence requirements for beam correspondence based on CSI-RS are only applied under the following side conditions:

- The downlink reference signals including both SSB and CSI-RS are provided.
- The reference measurement channel for beam correspondence is fulfilled according to the CSI-RS configuration in Annex A.3.
- For beam correspondence, conditions for L1-RSRP measurements are fulfilled according to Table 6.6.4.3.1-2 and SSB signal is provided according to Table 6.6.4.3.3-1.

Table 6.6.4.3.3-1: SSB signal conditions for CSI-RS based beam correspondence requirements

Angle of arrival	NR operating bands	Minimum SSB_RP Note 2	SSB Ês/lot
		dBm / SCS _{SSB}	dB
		SCS _{SSB} = 120 kHz	
All angles Note 1	n257	-101.2	≥1
	n258	-101.2	
	n259	-95.7	
	n260	-96.9	
	n261	-101.2	

NOTE 1: For UEs that support multiple FR2 bands, the Minimum SSB_RP values for all angles are increased by ΔMBs,n, the UE multi-band relaxation factor in dB specified in clause 6.2.1.

NOTE 2: Values specified at the radiated requirements reference point to give minimum SSB Es/lot, with no applied noise.

6.6.4.4 Applicability

For UEs supporting more than one type of beam correspondence, the following applicability rules apply:

- If a UE meets enhanced beam correspondence requirements either based on SSB or based on CSI-RS, it is considered to have met the beam correspondence requirements based on SSB and CSI-RS.
- For a UE supporting either SSB based or CSI-RS based enhanced beam correspondence, the UE shall meet the supported enhanced beam correspondence requirements.
- For a UE supporting both SSB based and CSI-RS based enhanced beam correspondence, the UE shall meet both SSB based and CSI-RS based enhanced beam correspondence requirements and the following applicability rules for verifying the requirements apply:
 - The enhanced beam correspondence requirements shall be verified with the SSB based enhanced beam correspondence side conditions in clause 6.6.4.3.2. If the UE meets the SSB based enhanced beam correspondence requirements using the side conditions in clause 6.6.4.3.2 and meets the minimum peak EIRP requirement as defined in clause 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.4.3.3, where the link direction is determined in the SSB based enhanced beam correspondence test, the UE is considered to have met both the SSB based and CSI-RS based enhanced beam correspondence requirements.
 - Otherwise, if UE does not meet the minimum peak EIRP requirement as defined in clasue 6.2.1.3 using the CSI-RS based side conditions in clause 6.6.4.3.3, the enhanced beam correspondence requirements shall be further verified for the UE with the CSI-RS based enhanced beam correspondence side conditions in clause 6.6.4.3.3.

6.6.5 Void

6.6A Beam correspondence for CA

For intra-band CA in FR2, the same beam correspondence relationship for beam management is supported across CCs in this release of the specification and no requirement is specified. Beam correspondence performance for intra-band CA is fulfilled if the beam correspondence requirements defined in clause 6.6 is met for non-CA case.

7 Receiver characteristics

7.1 General

Unless otherwise stated, the receiver characteristics are specified over the air (OTA). The reference receive sensitivity (REFSENS) is defined assuming a 0 dBi reference antenna located at the center of the quiet zone.

7.2 Diversity characteristics

The minimum requirements on effective isotropic sensitivity (EIS) apply to two measurements, corresponding to DL signals in orthogonal polarizations.

7.3 Reference sensitivity

7.3.1 General

The reference sensitivity power level REFSENS is defined as the EIS level at the centre of the quiet zone in the RX beam peak direction, at which the throughput shall meet or exceed the requirements for the specified reference measurement channel.

7.3.2 Reference sensitivity power level

7.3.2.1 Reference sensitivity power level for power class 1

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.1-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Operating REFSENS (dBm) / Channel bandwidth band 50 MHz 100 MHz 200 MHz 400 MHz -97.5 -94.5 -91.5 -88.5 n257 -97.5 -94.5 -91.5 -88.5 n258 n260 -94.5 -91.5 -88.5 -85<u>.5</u> n261 -97.5 -94.5 -91.5 -88.5 NOTE 1: The transmitter shall be set to P_{UMAX} as defined in clause 6.2.4

Table 7.3.2.1-1: Reference sensitivity for power class 1

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Table 7.3.2.1-2: Uplink configuration for reference sensitivity

Operating band	NR Band / Channel bandwidth / NRB / SCS / Duplex mode						
	50 MHz 100 MHz 200 MHz 400 MHz SCS Duple Mod						
n257	32	64	128	256	120 kHz	TDD	
n258	32	64	128	256	120 kHz	TDD	
n260	32	64	128	256	120 kHz	TDD	
n261	32	64	128	256	120 kHz	TDD	

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

Table 7.3.2.1-3: Reserved

Operating	Network
band	Signalling
	value

7.3.2.2 Reference sensitivity power level for power class 2

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.2-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Table 7.3.2.2-1: Reference sensitivity for power class 2

Operating band	REFSENS (dBm) / Channel bandwidth					
	50 MHz	50 MHz 100 MHz 200 MHz 400 MH				
n257	-92.0	-89.0	-86.0	-83.0		
n258	-92.0	-89.0	-86.0	-83.0		
n261	-92.0	-89.0	-86.0	-83.0		
NOTE 1: The trans	NOTE 1: The transmitter shall be set to P _{UMAX} as defined in clause 6.2.4					

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.3 Reference sensitivity power level for power class 3

The throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.3-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

For the UEs that support multiple FR2 bands, the minimum requirement for Reference sensitivity in Table 7.3.2.3-1 shall be increased per band, respectively, by the reference sensitivity relaxation parameter $\Delta MB_{P,n}$ as specified in clause 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.2.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.2.3-1 and Table 6.2.1.3-4.

Table 7.3.2.3-1: Reference sensitivity

Operating band	REFSENS (dBm) / Channel bandwidth					
	50 MHz	50 MHz 100 MHz 200 MHz				
n257	-88.3	-85.3	-82.3	-79.3		
n258	-88.3	-85.3	-82.3	-79.3		
n259	-84.7	-81.7	-78.7	-75.7		
n260	-85.7	-82.7	-79.7	-76.7		
n261	-88.3	-85.3	-82.3	-79.3		
NOTE 1: The trans	smitter shall be set t	o Pumax as defined in cla	ause 6.2.4			

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.2.4 Reference sensitivity power level for power class 4

The throughput shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity specified in Table 7.3.2.4-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link Angle).

Table 7.3.2.4-1: Reference sensitivity for power class 4

Operating band	REFSENS (dBm) / Channel bandwidth						
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz					
n257	-97.0	-94.0	-91.0	-88.0			
n258	-97.0	-94.0	-91.0	-88.0			
n260	-95.0	-92.0	-89.0	-86.0			
n261	-97.0	-94.0	-91.0	-88.0			
NOTE 1: The trans	smitter shall be set t	o Pumax as defined in cla	NOTE 1: The transmitter shall be set to Pumax as defined in clause 6.2.4				

The REFSENS requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.3 Void

7.3.4 EIS spherical coverage

7.3.4.1 EIS spherical coverage for power class 1

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.1

The maximum EIS at the 85th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.1-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Table 7.3.4.1-1: EIS spherical coverage for power class 1

Operating band	EIS at 85 th %-tile CCDF (dBm) / Channel bandwidth				
	50 MHz	100 MHz	200 MHz	400 MHz	
n257	-89.5	-86.5	-83.5	-80.5	
n258	-89.5	-86.5	-83.5	-80.5	
n260	-86.5	-83.5	-80.5	-77.5	
n261	-89.5	-86.5	-83.5	-80.5	

NOTE 1: The transmitter shall be set to Pumax as defined in clause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.2 EIS spherical coverage for power class 2

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.2

The maximum EIS at the 60th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.2-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Table 7.3.4.2-1: EIS spherical coverage for power class 2

Operating band	EIS at 60th %-tile CCDF (dBm) / Channel bandwidth					
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz				
n257	-81.0	-78.0	-75.0	-72.0		
n258	-81.0	-78.0	-75.0	-72.0		
n261	-81.0	-78.0	-75.0	-72.0		

NOTE 1: The transmitter shall be set to P_{UMAX} as defined in clause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.3 EIS spherical coverage for power class 3

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.3

The maximum EIS at the 50th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.3-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

For the UEs that support multiple FR2 bands, the minimum requirement for EIS spherical coverage in Table 7.3.4.3-1 shall be increased per band, respectively, by the EIS spherical coveragerelaxation parameter $\Delta MB_{S,n}$ as specified in clause 6.2.1.3. The requirement for the UE which supports a single FR2 band is specified in Table 7.3.4.3-1. The requirement for the UE which supports multiple FR2 bands is specified in both Table 7.3.4.3-1 and Table 6.2.1.3-4.

Table 7.3.4.3-1: EIS spherical coverage for power class 3

Operating band	EIS at 50th %-tile CCDF (dBm) / Channel bandwidth						
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz					
n257	-77.4	-74.4	-71.4	-68.4			
n258	-77.4	-74.4	-71.4	-68.4			
n259	-71.9	-68.9	-65.9	-62.9			
n260	-73.1	-70.1	-67.1	-64.1			
n261	-77.4	-74.4	-71.4	-68.4			

NOTE 1: The transmitter shall be set to P_{UMAX} as defined in clause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3.4.4 EIS spherical coverage for power class 4

The reference measurement channels and throughput criterion shall be as specified in clause 7.3.2.4

The maximum EIS at the 20th percentile of the CCDF of EIS measured over the full sphere around the UE is defined as the spherical coverage requirement and is found in Table 7.3.4.4-1 below. The requirement is verified with the test metric of EIS (Link=Spherical coverage grid, Meas=Link angle).

Table 7.3.4.4-1: EIS spherical coverage for power class 4

Operating band	EIS at 20th %-tile CCDF (dBm) / Channel bandwidth					
	50 MHz	100 MHz	200 MHz	400 MHz		
n257	-88.0	-85.0	-82.0	-79.0		
n258	-88.0	-85.0	-82.0	-79.0		
n260	-83.0	-80.0	-77.0	-74.0		
n261	-88.0	-85.0	-82.0	-79.0		

NOTE 1: The transmitter shall be set to Pumax as defined in clause 6.2.4

NOTE 2: The EIS spherical coverage requirements are verified only under normal thermal conditions as defined in Annex E.2.1.

The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in Table 7.3.2.1-2.

Unless given by Table 7.3.2.1-3, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3-1) configured.

7.3A Reference sensitivity for DL CA

7.3A.1 General

7.3A.2 Reference sensitivity power level for CA

7.3A.2.1 Intra-band contiguous CA

For each component carrier in the intra-band contiguous carrier aggregation, the throughput in QPSK R = 1/3 shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity values determined from clause 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.1-1.

Table 7.3A.2.1-1: ΔR_{IBC} EIS Relaxation for CA operation by aggregated channel bandwidth

Aggregated Channel BW 'BW _{Channel_CA} ' (MHz)	ΔR _{IBC} (dB)
BW _{Channel_CA} ≤ 800	0.0
800 < BW _{Channel_CA} ≤ 1200	0.5

7.3A.2.2 Intra-band non-contiguous CA

For each component carrier in the intra-band non-contiguous carrier aggregation, the throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity values determined from clause 7.3.2, and relaxation applied to peak reference sensitivity requirement as specified in Table 7.3A.2.2-1. The configured downlink spectrum is defined as the frequency band from the lowest edge of the lowest CC to the upper edge of the highest CC of all UL and DL configured CCs.

able 7.3A.2.2-1: ΔR_{IBNC} EIS Relaxation for CA operation

Configured DL spectrum (MHz)	ΔR _{IBNC} (dB)
≤ 800	0.0
> 800 and ≤ 1400	0.5
> 1400 and ≤ 2400	1.5

7.3A.2.3 Inter-band CA

The inter-band requirement applies for all active component carriers. The throughput for each component carrier shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with peak reference sensitivity for each carrier specified in section 7.3.2, and relaxation $\Delta R_{IB,P,n}$ applied to peak reference sensitivity requirement. $\Delta R_{IB,P,n}$ is specified in Table 7.3A.2.3-1. The requirement on each component carrier shall be met when the power in the component carrier in the other band is set to its EIS spherical coverage requirement for interband CA specified in sub-clause 7.3A.3.3.

For the combination of intra-band and inter-band carrier aggregation, the intra-band CA relaxation, ΔR_{IBNC} , are also applied according to the clause 7.3A.2.1 and 7.3A.2.2.

Table 7.3A.2.3-1: $\Delta R_{IB,P,n}$ reference sensitivity relaxation for inter-band CA for power class 3

NR CA band combination	NR band	ΔR _{IB,P,n} (dB)
CA_n260-n261	n260	3.5
	n261	3.5

7.3A.3 EIS spherical coverage for DL CA

7.3A.3.1 Void

7.3A.3.2 Void

7.3A.3.3 EIS spherical coverage for inter-band CA

The inter-band CA requirement applies per operating band, for all active component carriers with UL assigned to one band and one DL component carrier per band. The requirement on each component carrier shall be met when the power in the component carrier in the other band is set to its EIS spherical coverage requirement for inter-band CA specified in this sub-clause.

The inter-band CA spherical coverage requirement for each power class will be satisfied if the intersection set of spherical coverage areas exceeds the common coverage requirement. Intersection set of spherical coverage areas is defined as a fraction of area of full sphere measured around the UE where both bands meet their defined individual EIS spherical coverage requirements for inter-band CA operation. The common coverage requirement is determined as <100-percentile rank> %, where 'percentile rank' is the percentile value in the specification of spherical coverage for that power class from clause 7.3.4.The requirement is verified with the test metric of EIS (Link=Beam peak search grids, Meas=Link angle).

The reference measurement channels and throughput criterion shall be as specified in clause 7.3A.2.3. The requirement shall be met for an uplink transmission using QPSK DFT-s-OFDM waveforms and for uplink transmission bandwidth less than or equal to that specified in clause 7.3.2.

Unless otherwise specified, the minimum requirements for reference sensitivity shall be verified with the network signalling value NS_200 (Table 6.2.3.1-1) configured.

The required spherical coverage EIS for each band in inter-band CA operation is given in clause 7.3.4 and modified by $\Delta R_{IB,S,n}$. The value of $\Delta R_{IB,S,n}$ is defined in Table 7.3A.3.3-1.

Table 7.3A.3.3-1: ΔR_{IB,S,n} EIS spherical coverage requirement relaxation for inter-band CA for power class 3

NR CA band combination	NR band	$\Delta R_{IB,S,n}$ (dB)
CA_n260-n261	n260	3.5
	n261	3.5

7.3D Void

7.4 Maximum input level

The maximum input level is defined as the maximum mean power, for which the throughput shall meet or exceed the minimum requirements for the specified reference measurement channel.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved.

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annex A (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1) with parameters specified in Table 7.4.-1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.4-1: Maximum input level

Rx Parameter		Units	Channel bandwidth				
			50	100	200	400	
			MHz	MHz	MHz	MHz	
Power in transmission		dBm	-25 (NOTE 2)				
bandwidth configuration			-27 (NOTE 3)				
NOTE 1:	The transmitter shal	l be set to	4 dB belo	ow the P _{UMAX,f,c} as do	efined in clause	e 6.2.4, with	
uplink configuration specified in Table 7.3.2.1-2.							
NOTE 2: Reference measurement chan			nnel is specified in Annex A.3.3.2: QPSK, R=1/3 variant				
with one sided dynamic OCNG Pattern as described in Annex A.							

NOTE 3: Reference measurement channel is specified in Annex A.3.3.5: 256QAM, R=4/5 variant

with one sided dynamic OCNG Pattern as described in Annex A.

Table 7.4-2: Void

7.4A Maximum input level for DL CA

Table 7.4A-1: Void

Table 7.4A-2: Void

7.4A.1 Maximum input level for Intra-band contiguous CA

For intra-band contiguous carrier aggregation the input level is defined as the cumulative received power, summed over the transmission bandwidth configurations of each active DL CC. All DL CCs shall be active throughout the test. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. At the maximum input level, the specified relative throughput shall meet or exceed the minimum requirements for the specified reference measurement channel over each component carrier. The minimum requirement is specified in Table 7.4A-1.

The maximum input level is defined as a directional requirement. The requirement is verified in beam locked mode in the direction where peak gain is achieved. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.4A.1-1: Maximum input level for Intra-band contiguous CA

Rx Parameter	Units	Level		
Power summed over transmission bandwidth	dBm	-25 (NOTE 2)		
configurations of all active DL CCs		-27 (NOTE 3)		
NOTE 1: The transmitter shall be set to 4 dB below the Pumax,f,c as defined in clause 6.2.4, with				
uplink configuration specified in Table 7.3.2.1-2				
NOTE 2: Reference measurement channel in each CC is specified in Annex A.3.3.2: QPSK, R=1/3				
variant with one sided dynamic OCNG Pattern as described in Annex A.				
NOTE 3: Reference measurement channel is specified in Annex A.3.3.5: 256QAM, R=4/5 variant				
with one sided dynamic OCNG Pat	tern as descri	bed in Annex A.		

7.4A.2 Maximum input level for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation the requirement of section 7.4A.1 applies

7.4A.3 Maximum input level for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the maximum input level is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.4 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.4A.1 and 7.4A.2 for each band while all downlink carriers are active.

7.4D Void

7.5 Adjacent channel selectivity

Adjacent Channel Selectivity (ACS) is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an adjacent channel signal at a given frequency offset from the centre frequency of the assigned channel. ACS is the ratio of the receive filter attenuation on the assigned channel frequency to the receive filter attenuation on the adjacent channel(s).

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

The UE shall fulfil the minimum requirement specified in Table 7.5-1 for all values of an adjacent channel interferer up to -25 dBm. However, it is not possible to directly measure the ACS, instead the lower and upper range of test parameters are chosen in Table 7.5-2 and Table 7.5-3 where the throughput shall be ≥ 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2, with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1. The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.5-1: Adjacent channel selectivity

Operating band	Units	Adjacent channel selectivity / Channel bandwidth				
		50 MHz	100 MHz	200 MHz	400 MHz	
n257, n258, n261	dB	23	23	23	23	
n259, n260	dB	22	22	22	22	

Table 7.5-2: Adjacent channel selectivity test parameters, Case 1

Rx Parameter	Units	Channel bandwidth			
		50 MHz	100 MHz	200 MHz	400 MHz
Power in Transmission Bandwidth Configuration	dBm		RE	FSENS + 14 dB	
P _{Interferer} for band n257, n258, n261	dBm	REFSENS + 35.5 dB	REFSENS +35.5 dB	REFSENS +35.5 dB	REFSENS +35.5 dB
P _{Interferer} for band n259, n260	dBm	REFSENS + 34.5 dB	REFSENS +34.5 dB	REFSENS +34.5 dB	REFSENS +34.5 dB
BW _{Interferer}	MHz	50	100	200	400
Finterferer (offset)	MHz	50 / -50 NOTE 3	100 / -100 NOTE 3	200 / -200 NOTE 3	400 / -400 NOTE 3

NOTE 1: The interferer consists of the Reference measurement channel specified in Annex A.3.2 with one sided dynamic OCNG Pattern as described in Annex A.3.2 and set-up according to Annex C.

NOTE 2: The REFSENS power level is specified in Clause 7.3.2, which are applicable to different UE power classes.

NOTE 3: The absolute value of the interferer offset F_{Interferer} (offset) shall be further adjusted to

 $(CEIL(|F_{Interferer}(offset)|/SCS) + 0.5)*SCS MHz$ with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS.

NOTE 4: The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.

Table 7.5-3: Adjacent channel selectivity test parameters, Case 2

Rx Parameter	Units		Channel	l bandwidth	
		50 MHz	100 MHz	200 MHz	400 MHz
Power in Transmission Bandwidth Configuration for band n257, n258, n261	dBm	-46.5	-46.5	-46.5	-46.5
Power in Transmission Bandwidth Configuration for band n259, n260	dBm	-45.5	-45.5	-45.5	-45.5
PInterferer	dBm		•	-25	1
BWInterferer	MHz	50	100	200	400
Finterferer (offset)	MHz	50 / -50 NOTE 2	100 / -100 NOTE 2	200 / -200 NOTE 2	400 / -400 NOTE 2

NOTE 1: The interferer consists of the Reference measurement channel specified in Annex 3.2 with one sided dynamic OCNG Pattern TDD as described in Annex A and set-up according to Annex C.

NOTE 2: The absolute value of the interferer offset F_{Interferer} (offset) shall be further adjusted to (CEIL(|F_{Interferer}(offset)|/SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS.

NOTE 3: The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.

7.5A Adjacent channel selectivity for DL CA

Table 7.5A-1: Void

Table 7.5A-2: Void

Table 7.5A-3: Void

7.5A.1 Adjacent channel selectivity for Intra-band contiguous CA

For intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. The UE shall fulfil the minimum requirement specified in Table 7.5A.1-1 for an adjacent channel interferer on either side of the aggregated downlink signal at a specified frequency offset and for an interferer power up to -25 dBm.

The throughput of each carrier shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.5A.1-1: Adjacent channel selectivity for intra-band contiguous CA

Operating band	Units	Adjacent channel selectivity / CA bandwidth class All CA bandwidth class
n257, n258, n261	dB	23
n259, n260	dB	22

Table 7.5A.1-2: Adjacent channel selectivity test parameters for intra-band contiguous CA, Case 1

Rx Parameter	Units	All CA bandwidth Classes
Pw in Transmission Bandwidth		REFSENS + 14 dB
Configuration, per CC		
P _{Interferer} for band n257, n258, n261	dBm	Aggregated power + 21.5
P _{Interferer} for band n259, n260	dBm	Aggregated power + 20.5
BW _{Interferer}	MHz	BW _{Channel_CA}
F _{Interferer} (offset)	MHz	
		+ BW _{channel} CA
		/
		- BW _{channel} CA
		NOTE 3

- NOTE 1: The interferer consists of the Reference measurement channel specified in Annex 3.2 with one sided dynamic OCNG Pattern as described in Annex A and set-up according to Annex C.
- NOTE 2: The F_{interferer} (offset) is the frequency separation between the center of the aggregated CA bandwidth and the center frequency of the Interferer signal
- NOTE 3: The absolute value of the interferer offset F_{Interferer} (offset) shall be further adjusted to (CEIL(|F_{Interferer}(offset)|/SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the carrier closest to the interferer in MHz. The interfering signal has the same SCS as that of the closest carrier.
- NOTE 4: The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.

Table 7.5A.1-3: Adjacent channel selectivity test parameters for intra-band contiguous CA, Case 2

Rx Parameter	Units	All CA bandwidth classes
Pw in Transmission Bandwidth Configuration,	dBm	- 46.5
aggregated power for band n257, n258, n261		
Pw in Transmission Bandwidth Configuration,	dBm	- 45.5
aggregated power for band n259, n260		
Pinterferer	dBm	- 25
BWInterferer	MHz	BW _{Channel_CA}
F _{Interferer} (offset)	MHz	+ BW _{channel} CA
		/
		- BW _{channel CA}
		NOTE 3
NOTE 1: The interferer consists of the Referen		
A.3.3.2 with one sided dynamic OCN		1 TDD as described in Annex
A.5.2.1 and set-up according to Anne		
NOTE 2: The Finterferer (offset) is the frequency s		
aggregated CA bandwidth and the ce		
NOTE 3: The absolute value of the interferer of		
(CEIL(F _{Interferer} (offset) /SCS) + 0.5)*S		
the carrier closest to the interferer in I	MHz. The inte	rtering signal has the same SCS
as that of the closest carrier.	5	
NOTE 4: The transmitter shall be set to 4 dB be		
with uplink configuration specified in 7	l able 7.3.2.1-2	2.

7.5A.2 Adjacent channel selectivity for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation with two component carriers, two different requirements apply for out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier as specified in clauses 7.5. For in-gap, the requirement applies if the following minimum gap condition is met:

$$\Delta f_{ACS} \ge BW_1/2 + BW_2/2 + \max(BW_1, BW_2),$$

where Δf_{ACS} is the frequency separation between the center frequencies of the component carriers and BW_k are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirements specified in clauses 7.5 for each component carrier considered. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met.

For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active and the input power shall be distributed among the active DL CCs so their PSDs are aligned with each other.

7.5A.3 Adjacent channel selectivity for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the adjacent channel requirements are defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.5 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clauses 7.5A.1 and 7.5A.2 for each band while all downlink carriers are active.

7.5D Void

7.6 Blocking characteristics

7.6.1 General

The blocking characteristic is a measure of the receiver's ability to receive a wanted signal at its assigned channel frequency in the presence of an unwanted interferer on frequencies other than those of the spurious response or the adjacent channels, without this unwanted input signal causing a degradation of the performance of the receiver beyond a specified limit. The blocking performance shall apply at all frequencies except those at which a spurious response occurs.

The requirement applies at the RIB when the AoA of the incident wave of the wanted signal and the interfering signal are both from the direction where peak gain is achieved.

The wanted and interfering signals apply to all supported polarizations, under the assumption of polarization match.

7.6.2 In-band blocking

In-band blocking is a measure of a receiver's ability to receive a NR signal at its assigned channel frequency in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel.

The throughput shall be \geq 95 % of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.6.2-1: In band blocking requirements

Rx parameter	Units		Channel b	oandwidth			
		50 MHz	50 MHz 100 MHz		400 MHz		
Power in Transmission Bandwidth Configuration	dBm	REFSENS + 14 dB					
BW _{Interferer}	MHz	50	100	200	400		
P _{Interferer} for bands n257, n258, n261	dBm	REFSENS + 35.5 dB	REFSENS + 35.5 dB	REFSENS + 35.5 dB	REFSENS + 35.5 dB		
P _{Interferer} for band n259, n260	dBm	REFSENS + 34.5 dB	REFSENS + 34.5 dB	REFSENS + 34.5 dB	REFSENS + 34.5 dB		
F _{Interferer} (offset)	MHz	≤ -100 & ≥ 100 NOTE 5	≤ -200 & ≥ 200 NOTE 5	≤ -400 & ≥ 400 NOTE 5	≤ -800 & ≥ 800 NOTE 5		
FInterferer	MHz	F _{DL_low} + 25 to F _{DL_high} - 25	F _{DL_low} + 50 to F _{DL_high} - 50	F _{DL_low} + 100 to F _{DL_high} - 100	F _{DL_low} + 200 to F _{DL_high} - 200		

NOTE 1: The interferer consists of the Reference measurement channel specified in Annex A.3.3.2 with one sided dynamic OCNG Pattern OP.1. TDD as described in Annex A.5.2.1 and set-up according to Annex C.

NOTE2: The REFSENS power level is specified in Clause 7.3.2, which are applicable according to different UE power classes.

NOTE 3: The wanted signal consists of the reference measurement channel specified in Annex A.3.3.2 with one sided dynamic OCNG pattern OP.1 TDD as described in Annex A.5.2.1 and set-up according to Annex C.

NOTE 4: Void

NOTE 5: The absolute value of the interferer offset F_{Interferer} (offset) shall be further adjusted (CEIL(|F_{Interferer}(offset)|/SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of the wanted signal in MHz. Wanted and interferer signal have same SCS.

NOTE 6: Finterferer range values for unwanted modulated interfering signals are interferer center frequencies.

NOTE 7: The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4, with uplink configuration specified in Table 7.3.2.1-2.

7.6.3 Void

7.6A Blocking characteristics for DL CA

7.6A.1 General

7.6A.2 In-band blocking

NOTE 7:

Table 7.6A.2-1: Void

Table 7.6A.2-2: Void

7.6A.2.1 In-band blocking for Intra-band contiguous CAFor intra-band contiguous carrier aggregation, the SCC(s) shall be configured at nominal channel spacing to the PCC. The input power shall be distributed among the active DL CCs so their PSDs are aligned with each other. The UE shall fulfil the minimum requirement specified in Table 7.6A.2-1 for in the presence of an interferer at a given frequency offset from the centre frequency of the assigned channel and an interferer power shall not exceed -25 dBm. The throughput of each carrier shall be \geq 95% of the maximum throughput of the reference measurement channels as specified in Annexes A.2.3.2 and A.3.3.2 (with one sided dynamic OCNG Pattern OP.1 TDD for the DL-signal as described in Annex A.5.2.1). The requirement is verified with the test metric of EIS (Link=RX beam peak direction, Meas=Link angle).

Table 7.6A.2.1-1: In band blocking minimum requirements for intra-band contiguous CA

Rx Parameter	Units	All CA bandwidth classes
Power in	dBm	REFSENS + 14 dB
Transmission		
Bandwidth		
Configuration,		
per CC		
Pinterferer for	dBm	Aggregated power + 21.5 dB
band n257,		
n258, n261		
Pinterferer for	dBm	Aggregated power + 20.5 dB
band n260		
BWInterferer	MHz	BW _{Channel_CA}
F _{Interferer}	MHz	
(offset)		+2*BW _{Channel_CA} / -2*BW _{Channel_CA}
		NOTE 5
		NOTE 5
F _{Interferer}	MHz	F _{DL_low} + 0.5*BW _{Channel_CA}
		То
		FDL_high - 0.5*BWChannel_CA
Anne	ex A.3.3.2 w	onsists of the Reference measurement channel specified in with one sided dynamic OCNG Pattern OP.1 TDD as described in and set-up according to Annex C.
		power level is specified in Table 7.3.2-1.
		QPSK, R=1/3 with one sided dynamic OCNG pattern OP.1 TDD as
desc	cribed in Anr	nex A.5.2.1 and set-up according to Annex C.
NOTE 4: The	Finterferer (off	set) is the frequency separation between the center of the
		bandwidth and the center frequency of the Interferer signal.
		lue of the interferer offset F _{Interferer} (offset) shall be further adjusted to
		st to the interferer in MHz. The interfering signal has the same SCS
		osest carrier.
	•	alues for unwanted modulated interfering signals are interferer center
NOTE 3: The Annotation described Annotation describ	wanted signex A.3.3.2 Coribed in Ann Finterferer (officegated CA absolute vall (Finterferer(officegated carrier close that of the close	nal consists of the reference measurement channel specified in QPSK, R=1/3 with one sided dynamic OCNG pattern OP.1 TDD as nex A.5.2.1 and set-up according to Annex C. set) is the frequency separation between the center of the bandwidth and the center frequency of the Interferer signal. lue of the interferer offset F _{Interferer} (offset) shall be further adjusted to offset) /SCS) + 0.5)*SCS MHz with SCS the sub-carrier spacing of set to the interferer in MHz. The interfering signal has the same SCS

with uplink configuration specified in Table 7.3.2.1-2.

The transmitter shall be set to 4 dB below the P_{UMAX,f,c} as defined in clause 6.2.4,

7.6A.2.2 In-band blocking for Intra-band non-contiguous CA

For intra-band non-contiguous carrier aggregation with two component carriers, the requirement applies to out-of-gap and in-gap. For out-of-gap, the UE shall meet the requirements for each component carrier with parameters as specified in 7.6.2-1. The requirement associated to the maximum channel between across the component carriers is selected. For in-gap, the requirement shall apply if the following minimum gap condition is met:

$$\Delta f_{IBB} \ge 0.5(BW_1 + BW_2) + 2 \max(BW_1, BW_2),$$

where Δf_{IBB} is the frequency separation between the center frequencies of the component carriers and BW_k are the channel bandwidths of carrier k, k = 1,2.

If the minimum gap condition is met, the UE shall meet the requirement specified in Table 7.6.2-1 for each component carrier. The respective channel bandwidth of the component carrier under test will be used in the parameter calculations of the requirement. In case of more than two component carriers, the minimum gap condition is computed for any pair of adjacent component carriers following the same approach as the two component carriers. The in-gap requirement for the corresponding pairs shall apply if the minimum gap condition is met. For every component carrier to which the requirements apply, the UE shall meet the requirement with one active interferer signal (in-gap or out-of-gap) while all downlink carriers are active and the input power shall be distributed among the active DL CCs so their PSDs are aligned with each other.

7.6A.2.3 In-band blocking for Inter-band CA

For inter-band carrier aggregation with one component carrier per operating band and the uplink assigned to one NR band, the in-band blocking requirements are defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clause 7.6.2 for each component carrier while all downlink carriers are active.

For the combination of intra-band and inter-band carrier aggregation and uplink carrier(s) assigned to one NR band, the requirement is defined with the uplink active on the band other than the band whose downlink is being tested. The UE shall meet the requirements specified in clauses 7.6A.2.1 and 7.6A.2.2 for each band while all downlink carriers are active.

- 7.6D Void
- 7.7 Void
- **7.8** Void

7.9 Spurious emissions

The spurious emissions power is the power of emissions generated or amplified in a receiver. The spurious emissions power level is measured as TRP.

The power of any narrow band CW spurious emission shall not exceed the maximum level specified in Table 7.9-1. The requirement is verified in beam locked mode with the test metric of TRP (Link=TX beam peak direction, Meas=TRP grid).

Table 7.9-1: General receiver spurious emission requirements

Frequency range	Measurement bandwidth	Maximum level	NOTE
30MHz ≤ f < 1GHz	100 kHz	-57 dBm	1
1GHz ≤ f ≤ 2^{nd} harmonic of the upper frequency edge of the DL operating band in GHz	1 MHz	-47 dBm	

NOTE 1: Unused PDCCH resources are padded with resource element groups with power level given by PDCCH as defined in Annex C.3.1.

7.10 Void

Annex A (normative): Measurement channels

A.1 General

- A.2 UL reference measurement channels
- A.2.1 General
- A.2.2 Void

A.2.3 Reference measurement channels for TDD

For UL RMCs defined below, TDD slot pattern defined in Table A.2.3-1 will be used for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, TDD slot patterns defined for reference sensitivity tests in Table A.3.3.1-1 will be used.

Table A.2.3-1: Additional reference channels parameters for TDD

	Parameter	Va	lue	
		SCS 60 kHz	SCS 120 kHz	
		(µ=2)	(µ=3)	
TDD Slot	Configuration pattern (Note 1)	DDDSUUUU	7DS8U	
Special	Slot Configuration (Note 2)	S=4D+6G+4U	S=12D+2G	
refe	renceSubcarrierSpacing	60 kHz	120 kHz	
UL-DL configuration	dl-UL-TransmissionPeriodicity	2 ms	2 ms	
-	nrofDownlinkSlots	3	7	
	nrofDownlinkSymbols	4	12	
	nrofUplinkSlot	4	8	
	nrofUplinkSymbols	4	0	
Inc	dexes of active UL slots	$mod(slot index, 40) = \{36,,39\}$	mod(slot index, 80) = {72,,79}	

NOTE 1: D denotes a slot with all DL symbols; S denotes a slot with a mix of DL, UL and guard symbols; U denotes a slot with all UL symbols. The field is for information.
 NOTE 2: D, G, U denote DL, guard and UL symbols, respectively. The field is for information.

A.2.3.1 DFT-s-OFDM Pi/2-BPSK

Table A.2.3.1-1: Reference Channels for DFT-s-OFDM pi/2-BPSK

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	pi/2 BPSK	0	24	16	2	1	132	132
	16	11	pi/2 BPSK	0	504	16	2	1	2112	2112
	32	11	pi/2 BPSK	0	1032	16	2	1	4224	4224
	64	11	pi/2 BPSK	0	2024	16	2	1	8448	8448
	128	11	pi/2 BPSK	0	3976	24	2	2	16896	16896
	256	11	pi/2 BPSK	0	7944	24	2	3	33792	33792

NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.

NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.

NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)

NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.

NOTE 5: The RMCs apply to all channel bandwidth where LCRB ≤ NRB.

Table A.2.3.1-2: Void

A.2.3.2 DFT-s-OFDM QPSK

Table A.2.3.2-1: Reference Channels for DFT-s-OFDM QPSK

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	QPSK	2	48	16	2	1	264	132
	16	11	QPSK	2	808	16	2	1	4224	2112
	20	11	QPSK	2	1032	16	2	1	5280	2640
	32	11	QPSK	2	1608	16	2	1	8448	4224
	64	11	QPSK	2	3240	16	2	1	16896	8448
	128	11	QPSK	2	6408	24	2	2	33792	16896
	256	11	QPSK	2	12808	24	2	4	67584	33792

- NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.
- NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.
- NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)
- NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
- NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.2-2: Void

A.2.3.3 DFT-s-OFDM 16QAM

Table A.2.3.3-1: Reference Channels for DFT-s-OFDM 16QAM

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	16QAM	10	176	16	2	1	528	132
	16	11	16QAM	10	2792	16	2	1	8448	2112
	32	11	16QAM	10	5632	24	1	1	16896	4224
	64	11	16QAM	10	11272	24	1	2	33792	8448
	128	11	16QAM	10	22536	24	1	3	67584	16896
	256	11	16QAM	10	45096	24	1	6	135168	33792

- NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.
- NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.
- NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)
- NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
- NOTE 5: The RMCs apply to all channel bandwidth where LCRB ≤ NRB.

Table A.2.3.3-2: Void

A.2.3.4 DFT-s-OFDM 64QAM

Table A.2.3.4-1: Reference Channels for DFT-s-OFDM 64QAM

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	64QAM	18	408	16	2	1	792	132
	16	11	64QAM	18	6400	24	1	1	12672	2112
	32	11	64QAM	18	12808	24	1	2	25344	4224
	64	11	64QAM	18	25608	24	1	4	50688	8448
	128	11	64QAM	18	51216	24	1	7	101376	16896
	256	11	64QAM	18	102416	24	1	13	202752	33792

- NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.
- NOTE 2: MCS Index is based on MCS table 6.1.4.1-1 defined in 38.214.
- NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)
- NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
- NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.4-2: Void

A.2.3.5 CP-OFDM QPSK

Table A.2.3.5-1: Reference Channels for CP-OFDM QPSK

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	QPSK	2	48	16	2	1	264	132
	16	11	QPSK	2	808	16	2	1	4224	2112
	32	11	QPSK	2	1608	16	2	1	8448	4224
	33	11	QPSK	2	1672	16	2	1	8712	4356
	66	11	QPSK	2	3368	16	2	1	17424	8712
•	132	11	QPSK	2	6536	24	2	2	34848	17424
	264	11	QPSK	2	13064	24	2	4	69696	34848

- NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.
- NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.
- NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)
- NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
- NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.5-2: Void

A.2.3.6 CP-OFDM 16QAM

Table A.2.3.6-1: Reference Channels for CP-OFDM 16QAM

Parameter	Allocated resource blocks (L _{CRB)}	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	16QAM	10	176	16	2	1	528	132
	16	11	16QAM	10	2792	16	2	1	8448	2112
	32	11	16QAM	10	5632	24	1	1	16896	4224
	33	11	16QAM	10	5760	24	1	1	17424	4356
	66	11	16QAM	10	11528	24	1	2	34848	8712
	132	11	16QAM	10	23040	24	1	3	69696	17424
	264	11	16QAM	10	46104	24	1	6	139392	34848

- NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.
- NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.
- NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)
- NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
- NOTE 5: The RMCs apply to all channel bandwidth where L_{CRB} ≤ N_{RB}.

Table A.2.3.6-2: Void

A.2.3.7 CP-OFDM 64QAM

Table A.2.3.7-1: Reference Channels for CP-OFDM 64QAM

Parameter	Allocated resource blocks (LCRB)	DFT-s- OFDM Symbols per slot (Note 1)	Modulation	MCS Index (Note 2)	Payload size	Transport block CRC	LDPC Base Graph	Number of code blocks per slot (Note 3)	Total number of bits per slot	Total modulated symbols per slot
Unit					Bits	Bits			Bits	
	1	11	64QAM	19	408	16	2	1	792	132
	16	11	64QAM	19	6400	24	1	1	12672	2112
	32	11	64QAM	19	12808	24	1	2	25344	4224
	33	11	64QAM	19	13064	24	1	2	26136	4356
	66	11	64QAM	19	26120	24	1	4	52272	8712
	132	11	64QAM	19	53288	24	1	7	104544	17424
	264	11	64QAM	19	106576	24	1	13	209088	34848

- NOTE 1: PUSCH mapping Type-A and single-symbol DM-RS configuration Type-1 with 2 additional DM-RS symbols, such that the DM-RS positions are set to symbols 2, 7, 11. DMRS is [TDM'ed] with PUSCH data. DM-RS symbols are not counted.
- NOTE 2: MCS Index is based on MCS table 5.1.3.1-1 defined in 38.214.
- NOTE 3: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit)
- NOTE 4: Indexes of active UL slots are given by Table A.2.3-1 with TDD UL-DL configuration specified in A2.3 for the requirements requiring at least one sub frame (1ms) for the measurement period. For other requirements, indexes of active UL slots are given by the slots satisfying mod(slot index+1, 5) = 0 with TDD UL-DL configuration specified in A.3.3.1.
- NOTE 5: The RMCs apply to all channel bandwidth where LCRB ≤ NRB.

Table A.2.3.7-2: Void

A.3 DL reference measurement channels

A.3.1 General

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 are applicable for measurements of the Receiver Characteristics (clause 7).

Unless otherwise stated, Tables A.3.3.2-1 and A.3.3.2-2 also apply for the modulated interferer used in Clauses 7.5 and 7.6 with test specific bandwidths.

CSI-RS configuration parameter defined in Table A.3.1-2 and Table A.3.1-3 are used for verifying the beam correspondence requirement, 2 slots of CSI-RS shall be provided at each test grid point. The DL channel shall be configured for zero power on all tones except those used by CSI-RS in slots containing CSI-RS for beam refinement, and the DL and UL channel sizes shall be the same during verification.

Table A.3.1-1: Test parameters

Para	meter	Unit	Value
CORESET frequen	CORESET frequency domain allocation		Full BW
CORESET time domain allocation			2 OFDM symbols at the begin of each slot
PDSCH ma	apping type		Type A
PDSCH start s	ymbol index (S)		2
Number of consecutive	e PDSCH symbols (L)		12
PDSCH PF	RB bundling	PRBs	2
Dynamic P	RB bundling		false
	BS determination		64QAM
Overhead value for	TBS determination		0
First DMRS position for	Type A PDSCH mapping		2
	S type		Type 1
Number of ad	ditional DMRS		2
FDM between DI	FDM between DMRS and PDSCH		Disable
CSI-RS for tracking	First subcarrier index in		
	the PRB used for CSI-RS		0 for CSI-RS resource 1,2
	(k0)		
	OFDM symbols in the		$l_0 = 8$ for CSI-RS resource 1
	PRB used for CSI-RS		l ₀ = 12 for CSI-RS resource 2
	Number of CSI-RS ports		1 for CSI-RS resource 1,2
	CDM Type		'No CDM' for CSI-RS resource 1,2
	Density (ρ)		3 for CSI-RS resource 1,2
	CSI-RS periodicity	Slots	60 kHz SCS: 80 for CSI-RS resources 1 and 2
			120 kHz SCS: 160 for CSI-RS resources 1 and 2
	CSI-RS offset	Slots	60 kHz SCS: 40 for CSI-RS resources 1 and 2
			120kHz SCS: 80 for CSI-RS resources 1 and 2
	Frequency Occupation		Start PRB 0
			Number of PRB = BWP size
	QCL info		TCI state #0
PTRS configuration			PTRS is not configured

Table A.3.1-2: CSI-RS parameters for beam correspondence based on SSB and CSI-RS

Resource Type	aperiodic
Resource Set Config	
repetition	on
aperiodicTriggeringOffset	Depending on UE capability
Resource Config	
nzp-CSI-RS-ResourceId	30 for resource #0
	31 for resource #1
	32 for resource #2
	33 for resource #3
	34 for resource #4
	35 for resource #5
	36 for resource #6
	37 for resource #7
powerControlOffset	0
powerControlOffsetSS	db0
nrofPorts	1
firstOFDMSymbolInTimeDomain	6 for resource #0
	7 for resource #1
	8 for resource #2
	9 for resource #3
	10 for resource #4
	11 for resource #5
	12 for resource #6
	13 for resource #7
cdm-Type	noCDM
density	3
nrofRBs	48 for channel
	bandwidth≥100MHz
	32 for channel
	bandwidth=50MHz
qcl-info	Type D to SSB

CSI-RS configuration parameter defined in Table A.3.1-3 is used for verifying the beam correspondence requirement, CSI-RS shall be provided once every 10msec.

Table A.3.1-3: CSI-RS parameters for CSI-RS based beam correspondence

Resource Type	aperiodic
Resource Set Config	
repetition	on
aperiodicTriggeringOffset	Depending on UE capability
Resource Config	
nzp-CSI-RS-ResourceId	30 for resource #0
	31 for resource #1
	32 for resource #2
	33 for resource #3

	29+N for resource #(N-1), where N is maxNumberRxBeam in UE capability IE of
	MIMO-ParametersPerBand
powerControlOffset	0
powerControlOffsetSS	db0
nrofPorts	1
firstOFDMSymbolInTimeDomain	6 for resource #0
	7 for resource #1
	8 for resource #2
	9 for resource #3
	5+N for resource #(N-1), where N=maxNumberRxBeam-1 in UE capability IE of
	MIMO-ParametersPerBand
cdm-Type	noCDM
density	3
nrofRBs	48 for channel bandwidth≥100MHz
	32 for channel bandwidth=50MHz
qcl-info	Type D to SSB

A.3.2 Void

A.3.3 DL reference measurement channels for TDD

A.3.3.1 General

Table A.3.3.1-1. Additional test parameters for TDD

Parameter		Value		
		SCS 60 kHz (μ=2)	SCS 120 kHz (µ=3)	
TDD Slot Configuration pattern (Note 1)		DDDSU	DDDSU	
Special Slot	Configuration (Note 2)	S=4D+6G+4U	S=10D+2G+2U	
reference	eSubcarrierSpacing	60 kHz	120 kHz	
UL-DL	dl-UL-	1.25 ms	0.625 ms	
configuration	TransmissionPeriodicity			
	nrofDownlinkSlots	3	3	
	nrofDownlinkSymbols	4	10	
	nrofUplinkSlot	1	1	
	nrofUplinkSymbols	4	2	
Number of	of HARQ Processes	8	8	
The number of	slots between PDSCH and	K1 = 4 if mod(i,5) = 0	K1 = 4 if mod(i,5) = 0	
corresponding HARQ-ACK information (Note 3)		K1 = 3 if mod(i,5) = 1	K1 = 3 if mod(i,5) = 1	
		K1 = 7 if mod(i,5) = 2	K1 = 7 if mod(i,5) = 2	
		where i is slot index per frame;	where i is slot index per frame;	
		$i = \{0,, 39\}$	$i = \{0,, 79\}$	

NOTE 1: D denotes a slot with all DL symbols; S denotes a slot with a mix of DL, UL and guard symbols; U denotes a slot with all UL symbols. The field is for information.

NOTE 2: D, G, U denote DL, guard and UL symbols, respectively. The field is for information.

NOTE 3: i is the slot index per frame.

A.3.3.2 FRC for receiver requirements for QPSK

Table A.3.3.2-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit	Value		
Channel bandwidth	MHz	50	100	200
Subcarrier spacing configuration μ		2	2	2
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame (NOTE 7)		23 /24	23 / 24	23 / 24
MCS index		4	4	4
Modulation		QPSK	QPSK	QPSK
Target Coding Rate		1/3	1/3	1/3
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$ (NOTE 5)	Bits	N/A	N/A	N/A
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,79\}$ (NOTE 6)	Bits	4224	8456	16896
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79} (NOTE 5)	CBs	N/A	N/A	N/A
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,79\}$ (NOTE 6)	CBs	1	2	3
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,79} (NOTE 5)	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$ (NOTE 6)	Bits	14256	28512	57024
Max. Throughput averaged over 1 frame (NOTE 8)	Mbps	10.138	20.294	40.550

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).
- NOTE 3: SS/PBCH block is transmitted in slot 0 with periodicity 20 ms
- NOTE 4: Slot i is slot index per 2 frames
- NOTE 5: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 8) = {3,4,5,6,7} for i from {0,...,79} together with the TDD UL-DL configuration specified in A2.3.
- NOTE 6: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if mod(i, 8) = {0,1,2} for i from {0,...,79} together with the TDD UL-DL configuration specified in A2.3.
- NOTE 7: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.
- NOTE 8: Throughput is averaged over 2nd frame of RMC.

Table A.3.3.2-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

Parameter	Unit	Value			
Channel bandwidth	MHz	50	100	200	400
Subcarrier spacing configuration μ		3	3	3	3
Allocated resource blocks		32	66	132	264
Subcarriers per resource block		12	12	12	12
Allocated slots per Frame (NOTE 7)		47 / 48	47 / 48	47 / 48	47 / 48
MCS index		4	4	4	4
Modulation		QPSK	QPSK	QPSK	QPSK
Target Coding Rate		1/3	1/3	1/3	1/3
Maximum number of HARQ transmissions		1	1	1	1
Information Bit Payload per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$ (NOTE 5)	Bits	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	Bits	2088	4224	8456	16896
Transport block CRC	Bits	16	24	24	24
LDPC base graph		2	1	1	1
Number of Code Blocks per Slot					
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	CBs	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$ (NOTE 6)	CBs	1	1	2	3
Binary Channel Bits Per Slot					
For Slots 0 and Slot i, if mod(i, 5) = {3,4} for i from {0,,159} (NOTE 5)	Bits	N/A	N/A	N/A	N/A
For Slot i, if mod(i, 5) = {0,1,2} for i from {1,,159} (NOTE 6)	Bits	6912	14256	28512	57024
Max. Throughput averaged over 1 frame (NOTE 8)	Mbps	10.022	20.275	40.589	81.101

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).
- NOTE 3: SS/PBCH block is transmitted in slot 0 with periodicity 20 ms
- NOTE 4: Slot i is slot index per 2 frames
- NOTE 5: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if $mod(i, 16) = \{7,...,15\}$ for i from $\{0,...,159\}$ together with the TDD UL-DL configuration specified in A2.3.
- NOTE 6: When this DL RMC used together with the UL RMC for the transmitter requirements requiring at least one sub frame (1ms) for the measurement period, Slot i, if $mod(i, 16) = \{0,...,6\}$ for i from $\{0,...,159\}$ together with the TDD UL-DL configuration specified in A2.3.
- NOTE 7: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.
- NOTE 8: Throughput is averaged over 2nd frame of RMC.

A.3.3.3 FRC for receiver requirements for 16QAM

A.3.3.4 FRC for receiver requirements for 64QAM

Table A.3.3.4-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit	Value		
Channel bandwidth	MHz	50	100	200
Subcarrier spacing configuration μ		2	2	2
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame (NOTE 6)		23 / 24	23 / 24	23 / 24
MCS index		19	19	19
Modulation		64QAM	64QAM	64QAM
Target Coding Rate		1/2	1/2	1/2
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	Bits	N/A	N/A	N/A
For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,79\}$	Bits	20496	40976	81976
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slot i, if $mod(i, 10) = \{0,1,2\}$ for i from $\{1,,79\}$	CBs	N/A	N/A	N/A
$\{1,,79\}$ For Slot i, if mod(i, 5) = $\{0,1,2\}$ for i from $\{1,,79\}$	CBs	3	5	10
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$	Bits	40392	80784	161568
Max. Throughput averaged over 1 frame (NOTE 7)	Mbps	49.190	98.343	196.742

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L=0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 with periodicity 20 ms
- NOTE 4: Slot i is slot index per 2 frames
- NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6.
- NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.
- NOTE 7: Throughput is averaged over 2nd frame of RMC

Table A.3.3.4-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

Parameter	Unit	Value			
Channel bandwidth	MHz	50	100	200	400
Subcarrier spacing configuration μ		3	3	3	3
Allocated resource blocks		32	66	132	264
Subcarriers per resource block		12	12	12	12
Allocated slots per Frame (NOTE 6)		47 / 48	47 / 48	47 / 48	47 / 48
MCS index		19	19	19	19
Modulation		64QAM	64QAM	64QAM	64QAM
Target Coding Rate		1/2	1/2	1/2	1/2
Maximum number of HARQ transmissions		1	1	1	1
Information Bit Payload per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$	Bits	9992	20496	40976	81976
Transport block CRC	Bits	24	24	24	24
LDPC base graph		1	1	1	1
Number of Code Blocks per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$	CBs	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$	CBs	2	3	5	10
Binary Channel Bits Per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$	Bits	19584	40392	80784	161568
Max. Throughput averaged over 1 frame (NOTE 7)	Mbps	47.962	98.381	196.685	393.485

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).
- NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame
- NOTE 4: Slot i is slot index per frame
- NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6.
- NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.
- NOTE 7: Throughput is averaged over 2nd frame of RMC.

A.3.3.5 FRC for receiver requirements for 256QAM

Table A.3.3.5-1 Fixed Reference Channel for Receiver Requirements (SCS 60 kHz, TDD)

Parameter	Unit	Value		
Channel bandwidth	MHz	50	100	200
Subcarrier spacing configuration μ		2	2	2
Allocated resource blocks		66	132	264
Subcarriers per resource block		12	12	12
Allocated slots per Frame (NOTE 6)		23 / 24	23 / 24	23 / 24
MCS index		24	24	24
Modulation		256QAM	256QAM	256QAM
Target Coding Rate		4/5	4/5	4/5
Maximum number of HARQ transmissions		1	1	1
Information Bit Payload per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$	Bits	44040	88064	176208
Transport block CRC	Bits	24	24	24
LDPC base graph		1	1	1
Number of Code Blocks per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	CBs	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$	CBs	6	11	21
Binary Channel Bits Per Slot				
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,79\}$	Bits	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,79\}$	Bits	54648	109296	218592
Max. Throughput averaged over 1 frame (NOTE 7)	Mbps	105.696	211.354	422.899

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L=0 Bit). NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame
- NOTE 4: Slot i is slot index per 2 frames
- NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6.
- NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.
- NOTE 7: Throughput is averaged over 2nd frame of RMC.

Table A.3.3.5-2 Fixed Reference Channel for Receiver Requirements (SCS 120 kHz, TDD)

Parameter	Unit	Value			
Channel bandwidth	MHz	50	100	200	400
Subcarrier spacing configuration μ		3	3	3	3
Allocated resource blocks		32	66	132	264
Subcarriers per resource block		12	12	12	12
Allocated slots per Frame (NOTE 6)		47 / 48	47 / 48	47 / 48	47 / 48
MCS index		24	24	24	24
Modulation		256QAM	256QAM	256QAM	256QAM
Target Coding Rate		4/5	4/5	4/5	4/5
Maximum number of HARQ transmissions		1	1	1	1
Information Bit Payload per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$	Bits	21504	44040	88064	176208
Transport block CRC	Bits	24	24	24	24
LDPC base graph		1	1	1	1
Number of Code Blocks per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$	CBs	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$	CBs	3	6	11	21
Binary Channel Bits Per Slot					
For Slots 0 and Slot i, if $mod(i, 5) = \{3,4\}$ for i from $\{0,,159\}$	Bits	N/A	N/A	N/A	N/A
For Slot i, if $mod(i, 5) = \{0,1,2\}$ for i from $\{1,,159\}$	Bits	26496	54648	109296	218592
Max. Throughput averaged over 1 frame (NOTE 7)	Mbps	103.219	211.392	422.707	845.798

- NOTE 1: Additional parameters are specified in Table A.3.1-1 and Table A.3.3.1-1.
- NOTE 2: If more than one Code Block is present, an additional CRC sequence of L = 24 Bits is attached to each Code Block (otherwise L = 0 Bit).
- NOTE 3: SS/PBCH block is transmitted in slot 0 of each frame
- NOTE 4: Slot i is slot index per 2 frames
- NOTE 5: PTRS is configured on symbols containing PDSCH with 1 port, per 2PRB in frequency domain, per symbol in time domain. Overhead for TBS calculation is assumed to be 6.
- NOTE 6: First number corresponds to the number slots allocated in the first frame of the RMC; second number corresponds to the number slots allocated in the second frame of the RMC.
- NOTE 7: Throughput is averaged over 2nd frame of RMC.

A.4 Void

A.5 OFDMA Channel Noise Generator (OCNG)

A.5.1 OCNG Patterns for FDD

A.5.2 OCNG Patterns for TDD

A.5.2.1 OCNG TDD pattern 1: Generic OCNG TDD Pattern for all unused REs

Table A.5.2.1-1: OP.1 TDD: Generic OCNG TDD Pattern for all unused REs

OCNG Appliance OCNG Parameters	Control Region (Core Set)	Data Region
Resources allocated	All unused REs (Note 1)	All unused REs (Note 2)
Structure	PDCCH	PDSCH
Content	Uncorrelated pseudo random QPSK modulated data	Uncorrelated pseudo random QPSK modulated data
Transmission scheme for multiple antennas ports transmission	Single Tx port transmission	Spatial multiplexing using any precoding matrix with dimensions same as the precoding matrix for PDSCH
Subcarrier Spacing	Same as for RMC PDCCH in the active BWP	Same as for RMC PDSCH in the active BWP
Power Level	Same as for RMC PDCCH	Same as for RMC PDSCH

Note 1: All unused REs in the active CORESETS appointed by the search spaces in use.

Note 2: Unused available REs refer to REs in PRBs not allocated for any physical channels, CORESETs, synchronization signals or reference signals in channel bandwidth.

Annex B (informative): Void

Annex C (normative): Downlink physical channels

C.1 General

C.2 Setup

Table C.2-1 describes the downlink Physical Channels that are required for connection set up.

Table C.2-1: Downlink Physical Channels required for connection set-up

Physical Channel
PBCH
SSS
PSS
PDCCH
PDSCH
PBCH DMRS
PDCCH DMRS
PDSCH DMRS
CSI-RS
PTRS

C.3 Connection

C.3.1 Measurement of Receiver Characteristics

Unless otherwise stated, Table C.3.1-1 is applicable for measurements on the Receiver Characteristics (clause 7).

Table C.3.1-1: Downlink Physical Channels transmitted during a connection (TDD)

Parameter	Unit	Value
SSS transmit power	W	Test specific
EPRE ratio of PSS to SSS	dB	0
EPRE ratio of PBCH to SSS	dB	0
EPRE ratio of PBCH to PBCH DMRS	dB	0
EPRE ratio of PDCCH to SSS	dB	0
EPRE ratio of PDCCH to PDCCH DMRS	dB	0
EPRE ratio of PDSCH to SSS	dB	0
EPRE ratio of PDSCH to PDSCH DMRS (Note 1)	dB	-3
EPRE ratio of CSI-RS to SSS	dB	0
EPRE ratio of PTRS to PDSCH	dB	Test specific
EPRE ratio of OCNG DMRS to SSS	dB	0
EPRE ratio of OCNG to OCNG DMRS (Note 1)	dB	0
	=	

Note 1: No boosting is applied to any of the channels except PDSCH DMRS. For PDSCH DMRS, 3 dB power boosting is applied assuming DMRS Type 1 configuration when DMRS and PDSCH are TDM'ed and only half of the DMRS REs are occupied.

Note 2: Number of DMRS CDM groups without data for PDSCH DMRS configuration for OCNG is set to 1.

Annex D (normative): Characteristics of the interfering signal

D.1 General

Unless otherwise stated, a modulated full bandwidth NR downlink signal, which equals to channel bandwidth of the wanted signal for Single Carrier case is used as interfering signals when RF performance requirements for NR UE receiver are defined. For intra-band contiguous CA case, a modulated NR downlink signal which equals to the aggregated channel bandwidth of the wanted signal is used.

D.2 Interference signals

Table D.2-1 describes the modulated interferer for different channel bandwidth options.

Table D.2-1: Description of modulated NR interferer

Channel bandwidth for Single Carrier					Intra band	
	50 MHz	50 MHz 100 MHz 200 MHz 400 MHz contigu				
BW _{Interferer}	50 MHz	100 MHz	200 MHz	400MHz	BW _{Channel_CA}	
RB						
NOTE 1: The RB configured for interfering signal is the same as maximum RB number						
de	defined in Table 5.3.2-1 for each sub-carrier spacing					

Annex E (normative): Environmental conditions

E.1 General

This annex specifies the environmental requirements of the UE. Within these limits the requirements of the present documents shall be fulfilled.

E.2 Environmental

The requirements in this clause apply to all types of UE(s).

E.2.1 Temperature

All RF requirements for UEs operating in FR2 are defined over the air and can only be tested in an OTA chamber.

The UE shall fulfil all the requirements in the temperature range for extreme conditions, as defined in Table E.2.1-1, unless explicitly stated otherwise in any requirement.

Table E.2.1-1: Temperature conditions

+ 25 °C ± 10 °C	For normal (room temperature) conditions with relative
	humidity up to 75 %
-10°C to +55°C	For extreme conditions

Outside this temperature range the UE, if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation.

E.2.2 Voltage

Editor's note: This requirement is incomplete. The following aspects are either missing or not yet determined:

Methodology to control the voltage in a case which a power cable is not connected to DUT is FFS since it is not agreed whether we can connect the power cable to DUT at the OTA measurement situation yet.

The UE shall fulfil all the requirements in the full voltage range, i.e. the voltage range between the extreme voltages.

The manufacturer shall declare the lower and higher extreme voltages and the approximate shutdown voltage. For the equipment that can be operated from one or more of the power sources listed below, the lower extreme voltage shall not be higher, and the higher extreme voltage shall not be lower than that specified below.

Table E.2.2-1: Voltage conditions

Power source	Lower extreme voltage	Higher extreme voltage	Normal conditions voltage
AC mains	0,9 * nominal	1,1 * nominal	nominal
Regulated lead acid battery	0,9 * nominal	1,3 * nominal	1,1 * nominal
Nonregulated batteries:			
Leclanché	0,85 * nominal	Nominal	Nominal
Lithium	0,95 * nominal	1,1 * Nominal	1,1 * Nominal
Mercury/nickel & cadmium	0,90 * nominal		Nominal

Outside this voltage range the UE if powered on, shall not make ineffective use of the radio frequency spectrum. In no case shall the UE exceed the transmitted levels as defined in clause 6.2 for extreme operation. In particular, the UE shall inhibit all RF transmissions when the power supply voltage is below the manufacturer declared shutdown voltage.

E.2.3 Void

Annex F (normative): Transmit modulation

F.1 Measurement Point

Figure F.1-1 shows the measurement point for the unwanted emission falling into non-allocated RB(s) and the EVM for the allocated RB(s).

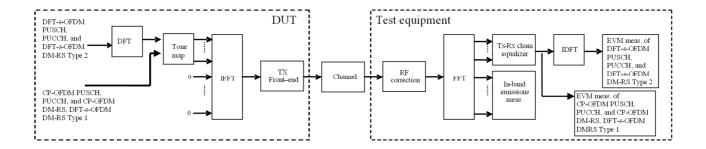


Figure F.1-1: EVM measurement points

F.2 Basic Error Vector Magnitude measurement

The EVM is the difference between the ideal waveform and the measured waveform for the allocated RB(s)

$$EVM = \sqrt{\frac{\sum_{v \in T_m} |z'(v) - i(v)|^2}{|T_m| \cdot P_0}},$$

where

 T_m is a set of $|T_m|$ modulation symbols with the considered modulation scheme being active within the measurement period,

Z'(V) are the samples of the signal evaluated for the EVM,

i(v) is the ideal signal reconstructed by the measurement equipment, and

 P_0 is the average power of the ideal signal. For normalized modulation symbols $\ P_0$ is equal to 1.

The basic EVM measurement interval is defined over one slot in the time domain for PUCCH and PUSCH and over one preamble sequence for the PRACH.

F.3 Basic in-band emissions measurement

The in-band emissions are a measure of the interference falling into the non-allocated resources blocks. The in-band emission requirement is evaluated for PUCCH and PUSCH transmissions. The in-band emission requirement is not evaluated for PRACH transmissions.

The in-band emissions are measured as follows

$$Emissions_{absolute}(\Delta_{RB}) = \begin{cases} \frac{1}{|T_{s}|} \sum_{t \in T_{s}} \sum_{\substack{max(f_{\min}, f_{l} + 12 \cdot \Delta_{RB} + \Delta f) \\ \min(f_{\max}, f_{h} + 12 \cdot \Delta_{RB} * \Delta f)}} |Y(t, f)|^{2}, \Delta_{RB} < 0 \\ \frac{1}{|T_{s}|} \sum_{t \in T_{s}} \sum_{\substack{f_{h} + (12 \cdot \Delta_{RB} + \Delta f) \\ f_{h} + (12 \cdot \Delta_{RB} - 11) * \Delta f}} |Y(t, f)|^{2}, \Delta_{RB} > 0 \end{cases}$$

where

 T_s is a set of $|T_s|$ OFDM symbols with the considered modulation scheme being active within the measurement period,

 Δ_{RB} is the starting frequency offset between the allocated RB and the measured non-allocated RB (e.g. $\Delta_{RB} = 1$ or $\Delta_{RB} = -1$ for the first adjacent RB),

 f_{\min} (resp. f_{\max}) is the lower (resp. upper) edge of the UL system BW,

 f_l and f_h are the lower and upper edge of the allocated BW, and

Y(t, f) is the frequency domain signal evaluated for in-band emissions as defined in the clause (ii)

The relative in-band emissions are, given by

$$Emissions_{relative}(\Delta_{RB}) = \frac{Emissions_{absolute}(\Delta_{RB})}{\frac{1}{\left|T_{s}\right| \cdot N_{RB}} \sum_{t \in T_{s}}^{f_{t} + (12N_{RB} - 1)\Delta f} \left|Y(t, f)\right|^{2}}$$

where

 N_{RB} is the number of allocated RBs

The basic in-band emissions measurement interval is defined over one slot in the time domain. When the PUSCH or PUCCH transmission slot is shortened due to multiplexing with SRS, the in-band emissions measurement interval is reduced by one OFDM symbol, accordingly.

In the evaluation of in-band emissions, the timing is set according to $\Delta \tilde{t} = \Delta \tilde{c}$, where sample time offsets $\Delta \tilde{t}$ and $\Delta \tilde{c}$ are defined in clause F.4.

F.4 Modified signal under test

Implicit in the definition of EVM is an assumption that the receiver is able to compensate a number of transmitter impairments.

The DFT-s-OFDM modulated signals or PRACH signal under test is modified and, in the case of DFT-s-OFDM modulated signals, decoded according to:

$$Z'(t,f) = IDFT \left\{ \frac{FFT \left\{ z(v - \Delta \widetilde{t}) \cdot e^{-j2\pi \Delta \widetilde{y}_{t}} \right\} e^{j2\pi j\Delta \widetilde{t}}}{\widetilde{a}(t,f) \cdot e^{j\widetilde{\varphi}(t,f)}} \right\}$$

where

 $\mathcal{Z}(\mathcal{V})$ is the time domain samples of the signal under test.

The CP-OFDM modulated signals or PUSCH demodulation reference signal or CP-OFDM modulated signalsunder test is equalised and, in the case of PUCCH data signal decoded according to:

$$Z'(t,f) = \frac{FFT\left\{z(v - \Delta \tilde{t}) \cdot e^{-j2\pi\Delta \tilde{f}v}\right\}}{\tilde{a}(t,f) \cdot e^{j\tilde{\varphi}(t,f)}} e^{j2\pi f\Delta \tilde{t}}$$

where

 $\mathcal{Z}(\mathcal{V})$ is the time domain samples of the signal under test.

To minimize the error, the signal under test should be modified with respect to a set of parameters following the procedure explained below.

Notation:

 $\Delta \tilde{t}$ is the sample timing difference between the FFT processing window in relation to nominal timing of the ideal signal.

 $\Delta \widetilde{f}$ is the RF frequency offset.

 $\widetilde{\varphi}(t,f)$ is the phase response of the TX chain.

 $\widetilde{a}(t,f)$ is the amplitude response of the TX chain.

In the following $\Delta \tilde{c}$ represents the middle sample of the EVM window of length W (defined in the next clauses) or the last sample of the first window half if W is even.

The EVM analyser shall

- detect the start of each slot and estimate $\Delta \tilde{t}$ and $\Delta \tilde{f}$,
- determine $\Delta \tilde{c}$ so that the EVM window of length W is centred
 - on the time interval determined by the measured cyclic prefix minus 16κ samples of the considered OFDM symbol for symbol 1 for subcarrier spacing configuration μ in a subframe, with l=0 or $l=7*2^{\mu}$ for normal CP, i.e. the first 16κ samples of the CP should not be taken into account for this step. In the determination of the number of excluded samples, a sampling rate of $1/T_c$ is assumed. If a different sampling rate is used, the number of excluded samples is scaled linearly.
 - on the measured cyclic prefix of the considered OFDM symbol symbol for all other symbols for normal CP and for symbol 0 to 11 for extended CP.
 - on the measured preamble cyclic prefix for the PRACH

To determine the other parameters a sample timing offset equal to $\Delta \widetilde{c}$ is corrected from the signal under test. The EVM analyser shall then

- correct the RF frequency offset $\Delta \widetilde{f}$ for each time slot, and

- apply an FFT of appropriate size. The chosen FFT size shall ensure that in the case of an ideal signal under test, there is no measured inter-subcarrier interference.

The carrier leakage shall be removed from the evaluated signal before calculating the EVM and the in-band emissions; however, the removed relative carrier leakage power also has to satisfy the applicable requirement.

At this stage the allocated RBs shall be separated from the non-allocated RBs. In the case of PUCCH and PUSCH EVM, the signal on the non-allocated RB(s), Y(t, f), is used to evaluate the in-band emissions.

Moreover, the following procedure applies only to the signal on the allocated RB(s).

- In the case of PUCCH and PUSCH, the UL EVM analyzer shall estimate the TX chain equalizer coefficients $\widetilde{a}(t,f)$ and $\widetilde{\phi}(t,f)$ used by the ZF equalizer for all subcarriers by time averaging at each signal subcarrier of the amplitude and phase of the reference and data symbols. The time-averaging length is 1 slot. This process creates an average amplitude and phase for each signal subcarrier used by the ZF equalizer. The knowledge of data modulation symbols may be required in this step because the determination of symbols by demodulation is not reliable before signal equalization.
- In the case of PRACH, the UL EVM analyzer shall estimate the TX chain coefficients $\widetilde{a}(t)$ and $\widetilde{\phi}(t)$ used for phase and amplitude correction and are seleted so as to minimize the resulting EVM. The TX chain coefficients are not dependent on frequency, i.e. $\widetilde{a}(t,f) = \widetilde{a}(t)$ and $\widetilde{\phi}(t,f) = \widetilde{\phi}(t)$. The TX chain coefficient are chosen independently for each preamble transmission and for each $\Delta \widetilde{t}$.

At this stage estimates of $\Delta \widetilde{f}$, $\widetilde{a}(t,f)$, $\widetilde{\varphi}(t,f)$ and $\Delta \widetilde{c}$ are available. $\Delta \widetilde{t}$ is one of the extremities of the window W, i.e. $\Delta \widetilde{t}$ can be $\Delta \widetilde{c} + \alpha - \left\lfloor \frac{W}{2} \right\rfloor$ or $\Delta \widetilde{c} + \left\lfloor \frac{W}{2} \right\rfloor$, where $\alpha = 0$ if W is odd and $\alpha = 1$ if W is even. The EVM analyser shall then

- calculate EVM₁ with $\Delta \tilde{t}$ set to $\Delta \tilde{c} + \alpha - \left\lfloor \frac{W}{2} \right\rfloor$,

- calculate EVM_h with $\Delta \tilde{t}$ set to $\Delta \tilde{c} + \left\lfloor \frac{W}{2} \right\rfloor$.

F.5 Window length

F.5.1 Timing offset

As a result of using a cyclic prefix, there is a range of $\Delta \tilde{t}$, which, at least in the case of perfect Tx signal quality, would give close to minimum error vector magnitude. As a first order approximation, that range should be equal to the length of the cyclic prefix. Any time domain windowing or FIR pulse shaping applied by the transmitter reduces the $\Delta \tilde{t}$ range within which the error vector is close to its minimum.

F.5.2 Window length

The window length *W* affects the measured EVM and is expressed as a function of the configured cyclic prefix length. In the case where equalization is present, as with frequency domain EVM computation, the effect of FIR is reduced. This is because the equalization can correct most of the linear distortion introduced by the FIR. However, the time domain windowing effect can't be removed.

F.5.3 Window length for normal CP

Table F.5.3-1 and Table F.5.3-2 below specify the EVM window length (W) for normal CP for FR2.

Table F.5.3-1: EVM window length for normal CP for 60 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)	
50	1024	72	36	50	
100	2048	144	72	50	
200	4096 288 144 50			50	
Note 1: These percentages are informative and apply to all OFDM symbols within subframe except for symbol 0 of slot 0 and slot 2. Symbol 0 of slot 0 and slot 2 may have a longer CP and therefore a lower percentage.					

Table F.5.3-2: EVM window length for normal CP for 120 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)	
50	512	36	18	50	
100	1024	72	36	50	
200	2048 144 72 50				
400	4096	288	144	50	
Note 1: These percentages are informative and apply to all OFDM symbols within subframe except for symbol 0 of slot 0 and slot 4. Symbol 0 of slot 0 and slot 4 may have					

a longer CP and therefore a lower percentage.

F.5.4 Window length for Extended CP

Table F.5.4-1 below specifies the EVM window length (*W*) for extended CP. The number of CP samples excluded from the EVM window is the same as for normal CP length.

Table F.5.4-1: EVM window length for extended CP for 60 kHz SCS

Channel Bandwidth (MHz)	FFT size	Cyclic prefix length in FFT samples	EVM window length W	Ratio of W to total CP length ¹ (%)	
50	1024	256	220	85.9	
100	2048	512	440	85.9	
200	4096	1024	880	85.9	
Note 1: These percentages are informative.					

F.5.5 Window length for PRACH

The table below specifies the EVM window length for PRACH preamble formats for L_{RA} = 139 and Δf^{RA} = 15·2 $^{\mu}$ kHz where $\mu \in \{2,3\}$.

Preamble format	Cyclic prefix N_{cp} length	Nominal FFT size ¹	EVM window length W in FFT samples	Ratio of <i>W</i> to CP ²
A1	1152·2 ⁻	8192·2 ⁻	576·2 ^{-μ}	50.0%
A2	2304·2 ^{-μ}	8192·2 ⁻	1728·2 ^{-μ}	75.0%
A3	3456·2 ⁻	8192·2 ⁻	2880·2 ^{-μ}	83.3%
B1	864·2 ^{-μ}	8192·2 ⁻ µ	288·2 ⁻ µ	33.3%
B2	1440·2 ⁻	8192·2 ⁻ µ	864·2 ⁻	60.0%
B3	2016·2 ^{-μ}	8192·2 ^{-μ}	1440·2 ^{-μ}	71.4%
B4	3744·2 ⁻	8192·2 ^{-μ}	3168·2 ⁻	84.6%
C0	4960·2 ^{-μ}	8192·2 ^{-μ}	4384·2 ⁻	88.4%
C2	8192·2 ⁻ µ	8192·2 ⁻ µ	7616·2⁻	93.0%

Table F.5.5-1: EVM window length for PRACH formats for $L_{RA} = 139$

Note 1: The use of other FFT sizes is possible as long as appropriate

scaling of the window length is applied Note 2: These percentages are informative

F.6 Averaged EVM

The general EVM is averaged over basic EVM measurements for n slots in the time domain.

$$\overline{EVM} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{i}^{2}},$$

where n is

$$n = \begin{cases} 40, for 60 \, kHz \, SCS \\ 80, for 120 \, kHz \, SCS \end{cases}$$

for PUCCH, PUSCH.

The EVM requirements shall be tested against the maximum of the RMS average at the window W extremities of the EVM measurements:

Thus $\overline{\text{EVN}}_{l}$ is calculated using $\Delta \widetilde{t} = \Delta \widetilde{t}_{l}$ in the expressions above and $\overline{\text{EVM}}_{l}$ is calculated using $\Delta \widetilde{t} = \Delta \widetilde{t}_{h}$.

Thus we get:

$$EVM = \max(\overline{EVM}, \overline{EVM}_n)$$

The calculation of the EVM for the demodulation reference signal, EVM_{DMRS} , follows the same procedure as calculating the general EVM, with the exception that the modulation symbol set T_m defined in clause F.2 is restricted to symbols containing uplink demodulation reference signals.

The basic EVM_{DMRS} measurements are first averaged over n slots in the time domain to obtain an intermediate average EVM_{DMRS} .

$$\overline{EVM}_{DMRS} = \sqrt{\frac{1}{n} \sum_{i=1}^{n} EVM_{DMRS,i}^{2}}$$

In the determination of each $EVM_{DMRS,i}$, the timing is set to $\Delta \tilde{t} = \Delta \tilde{t}_l$ if $\overline{EVM} > \overline{EVM}_n$, and it is set to

 $\Delta \widetilde{t} = \Delta \widetilde{t}_h$ otherwise, where $\overline{\text{EVM}}_h$ and $\overline{\text{EVM}}_h$ are the general average EVM values calculated in the same n slots

over which the intermediate average *EVM* _{DMRS} is calculated. Note that in some cases, the general average EVM may be calculated only for the purpose of timing selection for the demodulation reference signal EVM.

Then the results are further averaged to get the EVM for the demodulation reference signal, EVM_{DMRS} ,

$$EVM_{DMRS} = \sqrt{\frac{1}{6} \sum_{j=1}^{6} \overline{EVM}_{DMRS,j}^{2}}$$

The PRACH EVM, EVM_{PRACH} , is averaged over 2 preamble sequence measurements for long preamble formats as defined in table 6.3.3.1-1 in [9] and averaged over 10 preamble sequence measurements for short preamble formats as defined in table 6.3.3.1-2 in [9]..

The EVM requirements shall be tested against the maximum of the RMS average at the window *W* extremities of the EVM measurements:

Thus $\overline{\text{EVM}}_{\text{PRACH,}}$ is calculated using $\Delta \widetilde{t} = \Delta \widetilde{t}_l$ and $\overline{\text{EVM}}_{\text{PRACH,}}$ is calculated using $\Delta \widetilde{t} = \Delta \widetilde{t}_h$.

Thus we get:

$$EVM_{PRACH} = \max(\overline{EVM_{PRACHI}}, \overline{EVM_{PRACHI}})$$

F.7 Spectrum Flatness

The data shall be taken from FFT coded data symbols and the demodulation reference symbols of the allocated resource block.

F.8 Reserved

F.9 Reserved

F.10 EVM for dual transmit polarizations

F.10.1 General

A zero-forcing (ZF) MIMO receiver architecture is used so that transmissions by the UE, which are received by the test equipment on two polarizations, can be demodulated by the test equipment receiver.

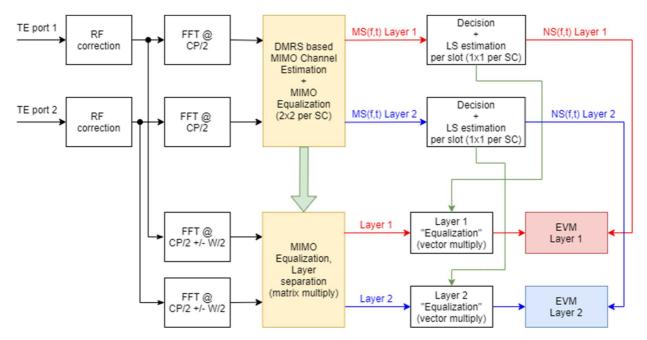


Figure F.10.1-1: EVM calculation block diagram for 2-Layer UL MIMO

The TE receives signals from 2 different ports on two antenna polarizations in the test system.

For UL MIMO measurements a MIMO equalization step as described in section F.10.2 is performed to separate the layers.

For single layer transmissions received on two polarizations the MIMO equalization step as described in section F.10.2 is replaced by a maximum ratio combining step as described in section F.10.3.

Each layer is then processed as described in section F.10.4 to receive the measurement results for each individual layer.

F.10.2 MIMO Equalization (UL MIMO transmission)

The MIMO equalization is based only on reference signals (DMRS) without using any data symbols. In order to obtain comparable EVM results independent of the number of DMRS symbols per slot, only the first DMRS symbol in each slot is used.

The effective 2x2 channel matrix is estimated using reference signals of different subcarriers, e.g. in case of DMRS antenna ports 0 and 2. In case that same subcarriers are used, e.g. DMRS antenna ports 0 and 1, a channel decomposition is necessary taking advantage of the orthogonal codes w_f and w_t and assuming identical channel coefficients for adjacent subcarriers of same CDM group.

Effective channel including the precoding matrix P is:

$$\widetilde{H} = HP = \begin{bmatrix} \widetilde{h}_{0,0} & \widetilde{h}_{0,1} \\ \widetilde{h}_{1,0} & \widetilde{h}_{1,1} \end{bmatrix}$$

with

$$\tilde{h}_{n,\nu} = \frac{y_n r_\nu^*}{|r_\nu|^2}$$

where y denotes the received symbol on port index n and r the reference signal for layer index v.

Since reference signals of a specific layer are transmitted only on subcarriers of one CDM group channel, interpolation is needed in order to obtain channel coefficients for all subcarriers. Channel interpolation is done using the channel coefficients of active CDM group in all other CDM groups.

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The channel coefficients used to calculate the equalizer coefficients are obtained after channel smoothing in frequency domain by computing the moving average of interpolated channel coefficients. The moving average window size is 7. For subcarriers at or near the edge of allocation the window size is reduced accordingly.

The ZF equalizer coefficients are calculated as the inverse of the effective channel matrix, in general:

$$G_{ZF} = \widetilde{H}^{-1}$$

F.10.3 Maximum Ratio combining (Tx diversity transmission)

The maximum ratio combining is based only on reference signals (DMRS) without using any data symbols. In order to obtain comparable EVM results independent of the number of DMRS symbols per slot, only the first DMRS symbol in each slot is used.

The effective 2x1 channel matrix is estimated using reference signals of different subcarriers. In case of transmit diversity, the effective channel includes the precoding matrix P:

$$\widetilde{H} = HP = \begin{bmatrix} \widetilde{h}_0 \\ \widetilde{h}_1 \end{bmatrix}$$

with

$$\tilde{h}_n = \frac{y_n r^*}{|r|^2}$$

where y denotes the received symbol on port index n and r the reference signal.

Since reference signals are transmitted only on subcarriers of one CDM group, channel interpolation is needed in order to obtain channel coefficients for all subcarriers. Channel interpolation is done using the channel coefficients of active CDM group in all other CDM groups.

The channel coefficients used to calculate the equalizer coefficients are obtained after channel smoothing in frequency domain by computing the moving average of interpolated channel coefficients. The moving average window size is 7. For subcarriers at or near the edge of allocation the window size is reduced accordingly.

The ZF equalizer coefficients for maximum ratio combining are calculated as pseudo inverse of effective channel, in general:

$$G_{ZF} = \widetilde{H}^+ = (\widetilde{H}^H \widetilde{H})^{-1} \widetilde{H}^H$$

F.10.4 Layer processing

After performing either the MIMO equalization or maximum ratio combining as described in section F.10.2 or F.10.3 respectively, each layer is processed using the existing procedure as defined in Annex E of TS 38.521-2 [5].

Since the channel estimation is calculated only on first DMRS symbol an averaging including all 14 symbols of one slot, i.e. data and reference signals, is needed in order to minimize EVM. The averaging is achieved by the least square (LS) equalization method described for single layer in Annex E.3. of TS 38.521-2 [5].

MS(f,t) and NS(f,t) are processed with a LS estimator, to derive one equalizer coefficient per time slot and per allocated subcarrier. EC(f) is defined for each layer as:

$$EC_{\nu}(f) = \frac{\sum_{t=0}^{13} NS_{\nu}(f,t)^* NS_{\nu}(f,t)}{\sum_{t=0}^{13} MS_{\nu}(f,t)^* NS_{\nu}(f,t)}$$

With * denoting complex conjugation. EC(f) are used to equalize layer data symbols.

EVM equalizer spectral flatness is derived from equalizer coefficients for each layer as follows:

$$c_{\nu} = |EC_{\nu}(f)| \sqrt{|g_{\nu,0}|^2 + |g_{\nu,1}|^2}$$

Annex G(normative): Difference of relative phase and power errors

G.0 General

This annex gives further information needed for understanding and implementing 6.4D.4. The following terms should be understood as follows:

- Relative phase error: refers to the phase difference between signals at different antenna ports, which should be ideally 0. It should be understood as for a slot i.e. (slot) relative phase. It is calculated based on DMRS symbols of that slot or on SRS symbols.
- Difference of relative phase error: refers to the difference between the relative phase error determined per slot and the relative phase error determined based on the SRS transmitted.

G.1 Measurement Point

Figure G.1-1 shows the measurement point for the difference of relative phase and power errors. To separate signals from the two transmitters, it is necessary for the test equipment to perform joint demodulation by inverting the 2x2 composite channel ('HGW') resulting from DUT precoding 'W' and antenna virtualization 'G' and OTA channel between DUT and test equipment 'H'. Post processing refers to the calculation of the phase/power errors, the averaging of phase and power errors per RB per slot per channel port and the calculation of difference between relative phases.

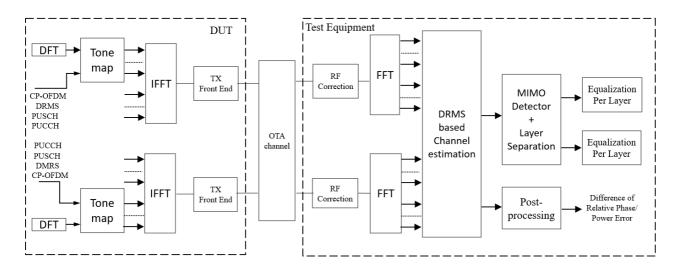


Figure G.1-1 - Measurement point for difference of relative phase/power error for UL coherent MIMO

G.2 Relative Phase Error Measurement

Here are listed the different aspects that may lead to different interpretations.

G.2.1 Symbols and subcarriers used

Phase error is determined based on DMRS REs (DMRS mapping type A with DMRS symbols per slot, the REs corresponding to the odd subcarriers and DMRS symbols are non-allocated for data or DMRS) and SRS REs (with 4 SRS symbols in the SRS slot, same SRS resource mapping is used for non-codebook-based and codebook-based precoding).

For the DMRS and SRS to occupy identical SCs and maximimize their frequency density, DMRS configuration type 1 and SRS comb2 configuration are used.

UL RMC described in Annex A.2 is used.

G.2.2 CFO (carrier frequency offset) correction

The TE performs a CFO correction on a slot-by-slot basis using a common frequency correction at the two uplink layers.

G.2.3 Steps of the measurement method

Below are detailed the steps necessary to obtain the maximum difference of relative phase error during the 20ms time window.

1 Determination for each subcarrier and at each antenna port, the SRS relative phase error based on the last SRS transmitted on Ant1 and Ant2, that relative phase error serves as a reference for the calculation of the difference of relative phase error for each slot inside the 20 ms time window.

The output is the "SRS relative phase error" vector for the last SRS transmitted: $[1 \times number_of_subcarriers]$.

2 Calculation for the last SRS transmitted, for each RB of the SRS relative phase errors based on the arithmetic mean of the subcarrier SRS relative phase errors determined in previous step.

The output is the "SRS relative phase error" vector for the last SRS transmitted: $[1 \times number_of_RBs]$.

- 3 CFO correction on slot-by-slot basis using a common frequency correction for both antenna ports.
- 4 Determination for each subcarrier and at each antenna port, the phase over the slot being analyzed. The phase is extracted from the channel estimate derived from the 3 DMRS symbols of the slot using the LSE technique.

The output is one vector of dimension $[1 \times number_of_subcarriers]$ for each antenna port.

5 Calculation for a slot for each subcarrier of the relative phase error (difference between the vectors determined in the previous step).

The output is subcarrier relative phase errors of a slot: $[1 \times number_of_subcarriers]$.

6 Calculation for a slot, for each RB of the relative phase errors based on the arithmetic mean of the subcarrier relative phase errors determined in previous step.

The output is a "slot relative phase error" vector for a slot: $[1 \times number_of_RBs]$.

7 Calculation for a slot of the difference of relative phase errors based on the "SRS relative phase error" (reference) determined in step 2 and the "slot relative phase error" determined in previous step.

The output is a "difference of relative phase error" vector for a slot: $[1 \times number_of_RBs]$.

8 Calculation for a slot of the arithmetic mean value of the "difference of relative phase error" vector determined in previous step, this value corresponds to an RB.

The output is a "difference of relative phase error" value for a slot: $[1 \times 1]$.

9 Perform for each slot of the 20ms time window, steps 3 to 8.

The output is a "difference of relative phase error" vector: $[1 \times number_of_slots]$.

10 Calculation of the maximum value of the "difference of relative phase error".

The output is the "difference of relative phase error" that should be verified as complying with the 40° maximum allowable difference of relative phase error requirement: $[1 \times 1]$.

Annex H (Normative): Modified MPR behavior

H.1 Indication of modified MPR behavior

This annex contains the definitions of the bits in the field *modifiedMPR-Behavior* indicated per supported NR band in the IE *RF-Parameters* [13] by a UE supporting an MPR or A-MPR modified in a given version of this specification. A modified MPR or A-MPR behaviour can apply to a supported NR band in stand-alone operation (including CA and NN-DC operation) or in non-standalone operation with the said NR band as part of an EN-DC or NE-DC band combination. Moreover, the bits in the field can explicitly indicate NS value(s) supported by a UE.

NOTE 1: In the present release, the *modifiedMPR-Behavior* is indicated [13] by an 8-bit bitmap per supported NR band.

Table H.1-1: Definitions of the bits in the field modifiedMPRbehavior

NR Band	Index of field (bit number)	Definition (description of the supported functionality if indicator set to one)	Notes
n257	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n257
n258	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n258
	1	Void	
	2	- NS_203 as defined in clause 6.5.3.2.4 or both	- This bit shall be set to 1
		NS_203 and CA_NS_203 as defined in clause 6.5A.3.2.4 of 38.101-2 v15.11.0	by a UE supporting n258 or both n258 and CA_n258
n260	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n260
n261	0 (leftmost bit)	- FR2 power class 3 MPR as defined in clause 6.2.2.3 of 38.101-2 v16.2.0 onwards	- This bit may be set to 1 by a UE supporting n261

Annex I (informative): Void

Annex J (normative): UE coordinate system

J.1 Reference coordinate system

This annex defines the measurement coordinate system for the NR UE. The reference coordinate system as defined in IEEE Std 149 [15] is provided in Figure J.1-1 below while Figure J.1.-2 shows the DUT in the default alignment, i.e., the DUT and the reference coordinate systems are aligned with $\alpha=0^{\circ}$ and $\beta=0^{\circ}$ and $\gamma=0^{\circ}$ where α , β , and γ describe the relative angles between the two coordinate systems.

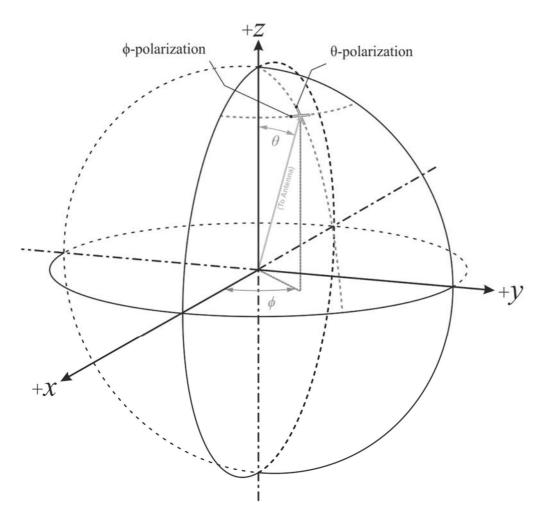


Figure J.1-1: Reference coordinate system

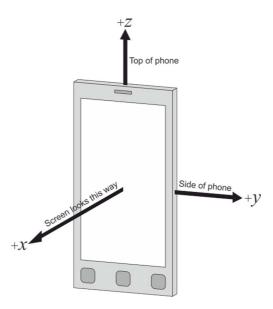


Figure J.1-2: DUT default alignment to coordinate system

The following aspects are necessary:

- A basic understanding of the top and bottom of the device is needed in order to define unambiguous DUT positioning requirements for the test, e.g., in the drawings used in this annex, the three buttons are on the bottom of the device (front) and the camera is on the top of the device (back).
- An understanding of the origin and alignment the coordinate system inside the test system i.e. the directions in which the x, y, z -axes points inside the test chamber is needed in order to define unambiguous DUT orientation, DUT beam, signal, interference, and measurement angles

J.2 Test conditions and angle definitions

Tables J.2-1 through J.2-3 below provides the test conditions and angle definitions for three permitted device alignment for the default test condition, DUT orientation 1, and two different options for each permitted device alignment to reposition the device for DUT Orientation 2 as outlined in Figures J.2-1 and J.2-3.

Table J.2-1: Test conditions and angle definitions for Alignment Option 1

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$\alpha = 0^{\circ};$ $\beta = 0^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link} ; φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_x(\alpha)$ Rotation Matrix $R_x(\alpha)$ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 - Option 1 (based on repositioning approach)	$\alpha = 180^{\circ};$ $\beta = 0^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link} ; φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_x(q)$ Rotation Matrix $R_x(q)$ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 - Option 2 (based on repositioning approach)	$\alpha = 0^{\circ};$ $\beta = 180^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link} ; φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_x(q)$ Rotation Matrix $R_x(q)$ Rotation Matrix $R_y(\beta)$

NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for each signal angle, link or interferer angle, and measurement angle.

NOTE 2: The combination of rotations is captured by matrix $M=R_z(\gamma) \bullet R_y(\beta) \bullet R_x(\alpha)$

Table J.2-2: Test conditions and angle definitions for Alignment Option 2

Test condition	DUT orientation	Link angle	Measurement angle	Diagram
Free space DUT Orientation 1 (default)	$\alpha = 0^{\circ};$ $\beta = -90^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link} ; φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation $Rotation \\ Rotation \\ Rotation \\ Matrix R_{x}(\gamma)$ $Rotation \\ Matrix R_{y}(\beta)$
Free space DUT Orientation 2 — Option 1 (based on repositioning approach)	$\alpha = 180^{\circ};$ $\beta = 90^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_z(\gamma)$ Rotation Matrix $R_y(\beta)$
Free space DUT Orientation 2 - Option 2 (based on repositioning approach)	$\alpha = 0^{\circ};$ $\beta = 90^{\circ};$ $\gamma = 0^{\circ}$	θ _{Link;} φ _{Link} with polarization reference Pol _{Link} = θ or φ	θ _{Meas;} φ _{Meas} with polarization reference Pol _{Meas} = θ or φ	Rotation Matrix $R_z(\gamma)$ Rotation Matrix $R_y(\beta)$

NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for each signal angle, link or interferer angle, and measurement angle.

NOTE 2: The combination of rotations is captured by matrix $M=R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$

DUT Test Link Measurement Diagram orientation condition angle angle $\alpha = 90^{\circ}$: θ_{Meas;} Free space θ_{Link} $\beta = 0^{\circ}$; DUT фмеаs **\$**Link Rotation Orientation 1 $\gamma = 0^{\circ}$ with . with Matrix $R_s(\gamma)$ polarization (default) polarization reference reference $Pol_{Link} = \theta$ or $Pol_{Meas} = \theta$ or φ φ Rotation Matrix $R_{\star}(\alpha)$ Rotation Matrix $R_{\nu}(\beta)$ Free space $\alpha = -90^{\circ}$: θ_{Link:} θ_{Meas:} DUT $\beta = 0^{\circ}$; **\$**Link фмеаs Rotation $\gamma = 0^{\circ}$ with Orientation 2 with Matrix $R_{-}(\gamma)$ polarization Option 1 polarization (based on rereference reference $Pol_{Link} = \theta$ or positioning $Pol_{Meas} = \theta$ or approach) φ φ Rotation Matrix $R_{\rm r}(\alpha)$ Rotation Matrix $R_{\nu}(\beta)$ Free space $a = 90^{\circ}$: θ_{Link}; θ_{Meas;} $\beta = 180^{\circ}$; DUT **\$**Link **\$**Meas Rotation Orientation 2 $y = 0^{\circ}$ with with Matrix $R_{a}(\gamma)$ polarization polarization Option 2 (based on rereference reference positioning $Pol_{Link} = \theta$ or $Pol_{Meas} = \theta$ or approach) φ φ Matrix $R_{r}(\alpha)$ Rotation Matrix $R_{,}(\beta)$

Table J.2-3: Test conditions and angle definitions for Alignment Option 3

NOTE 1: A polarization reference, as defined in relation to the reference coordinate system in J.1-1, is maintained for each signal angle, link or interferer angle, and measurement angle.

NOTE 2: The combination of rotations is captured by matrix $M=R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$

For each UE requirement and test case, each of the parameters in Table J.2-1 through J.2-3 need to be recorded, such that DUT positioning, DUT beam direction, and angles of the signal, link/interferer, and measurement are specified in terms of the fixed coordinate system.

Due to the non-commutative nature of rotations, the order of rotations is important and needs to be defined when multiple DUT orientations are tested.

The rotations around the x, y, and z axes can be defined with the following rotation matrices

$$R_{x}(\alpha) = \begin{bmatrix} 1 & 0 & 0 & 0 \\ 0 & \cos \alpha & -\sin \alpha & 0 \\ 0 & \sin \alpha & \cos \alpha & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

$$R_{y}(\beta) = \begin{bmatrix} \cos \beta & 0 & \sin \beta & 0 \\ 0 & 1 & 0 & 0 \\ -\sin \beta & 0 & \cos \beta & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

and

$$R_{z}(\gamma) = \begin{bmatrix} \cos \gamma & -\sin \gamma & 0 & 0 \\ \sin \gamma & \cos \gamma & 0 & 0 \\ 0 & 0 & 1 & 0 \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with the respective angles of rotation, α , β , γ , and

$$\begin{bmatrix} x' \\ y' \\ z' \\ 1 \end{bmatrix} = R \begin{bmatrix} x \\ y \\ z \\ 1 \end{bmatrix}$$

Additionally, any translation of the DUT can be defined with the translation matrix

$$T(t_x, t_y, t_z) = \begin{bmatrix} 1 & 0 & 0 & t_x \\ 0 & 1 & 0 & t_y \\ 0 & 0 & 1 & t_z \\ 0 & 0 & 0 & 1 \end{bmatrix}$$

with offsets tx, ty, tz in x, y, and z, respectively and with

$$\begin{bmatrix} x' \\ y' \\ z' \\ 1 \end{bmatrix} = T \begin{bmatrix} x \\ y \\ z \\ 1 \end{bmatrix}$$

The combination of rotations and translation is captured by the multiplication of rotation and translation matrices.

For instance, the matrix M

$$M = T(t_x, t_y, t_z) \cdot R_z(\gamma) \cdot R_y(\beta) \cdot R_x(\alpha)$$

describes an initial rotation of the DUT around the x axis with angle α , a subsequent rotation around the y axis with angle β , and a final rotation around the z axis with angle γ . After those rotations, the DUT is translated by t_x , t_y , t_z in x, y, and z, respectively.

J.3 DUT positioning guidelines

The centre of the reference coordinate system shall be aligned with the geometric centre of the DUT in order to minimize the offset between antenna arrays integrated at any position of the UE and the centre of the quiet zone.

Near-field coupling effects between the antenna and the pedestals/positioners/fixtures generally cause increased signal ripples. Re-positioning the DUT by directing the beam peak away from those areas can reduce the effect of signal ripple on EIRP/EIS measurements. Figure J.3-1 and J.3-2 illustrate how to reposition the DUT in distributed axes and combined axes system, when the beam peak is directed to the DUTs upper hemisphere (DUT orientation 1) or the DUTs lower hemisphere (DUT orientation 2). While these figures are examples of different positioning systems and other implementations are not precluded, the relative orientation of the coordinate system with respect to the antennas/reflectors and the axes of rotation shall apply to any measurement setup.

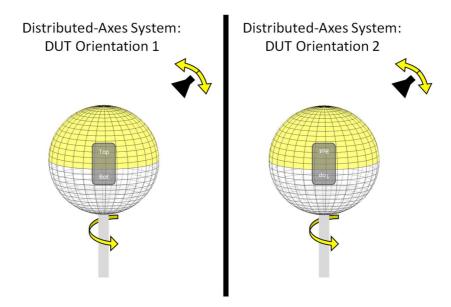


Figure J.3-1: DUT re-positioning for an example of distributed-axes system

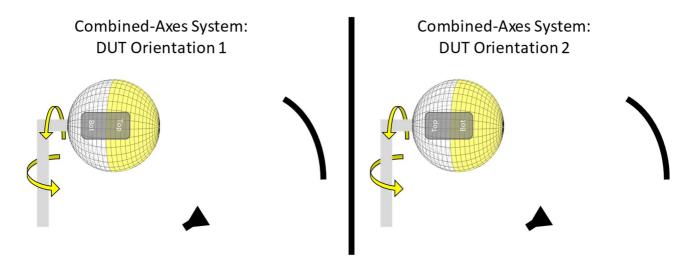


Figure J.3-2: DUT re-positioning for an example of combined-axes system

For EIRP/EIS measurements, re-positioning the DUT makes sure the pedestal is not obstructing the beam path and that the pedestal is not in closer proximity to the measurement antenna/reflector than the DUT. For TRP measurements, repositioning the DUT makes sure that the beam peak direction is not obstructed by the pedestal and the pedestal is in the measurement path only when measuring the back-hemisphere. No re-positioning during the TRP measurement is required.

Annex K (informative): Void

Annex L (informative): Change history

						Change history	
Date	Meeting	TDoc	CR	Rev	Cat	Subject/Comment	New versio
							n
2017-08	RAN4#84					Initial Skeleton	0.0.1
2017-10	RAN4#84 Bis	R4- 1711979				TPs from R4#84Bis by editors	0.1.0
2017-12	RAN4#85	R4- 1713806				Approved TPs from R4#85 R4-1714537, TP for TS 38.101-2: Channel Bandwidth Definition, Qualcomm Incorporated R4-1714115, TP for TS 38.101-2: Channel Arrangement,: Qualcomm Incorporated (Note: this TP was further discussed and edited in the reflector) R4-1713205, TP on general parts for 38.101-2 NR FR,: Ericsson R4-1712884, TP to TS38.101-2 on environmental conditions, Intel Corporation R4-1714018, TP to TS 38.101-2 for definition of UE RF terminologies, Anritsu Corporation R4-171447, TP on UE power class for FR2, Intel Corporation R4-1714372, TP to TS38.101-2 on EVM equalizer spectrum flatness requirements, Intel Corporation R4-1714330, TP to TR 38.101-02 v0.1.0: ON/OFF mask design for NR UE transmissions for FR2, Ericsson R4-1714364, TP to TR 38.101: NR UE transmit OFF power for FR2, CATT R4-1714347, TP to TS38.101-2 on spurious emissions requirements for FR2, Intel Corporation (Note: this TP was further discussed and edited in the reflector) R4-1714456, TP on REFSENS for FR2, Intel Corporation R4-1714337 TP to TS 38.101-2 IBB requirement for mmW (section 7.5), Qualcomm Incorporated R4-1714348, TP to TS 38.101-2 ibB requirement for mmW (section 7.6.1), Qualcomm Incorporated R4-1714348, TP to TS 38.101-2 on Rx spurious emissions for FR2, Intel Corporation Min power for EVM requirement according to R4-1711568, TP to TR 38.xxx - UE minimum transmit power for range 2, CATT Band list according to R4-1714542, List of bands and band combinations to be introduced into RAN4 NR core requirements by December 2017, RAN4 Chairmen	0.2.0
2017-12	RAN4#85	R4- 1714570				Further corrections and alignments with 38.104 after email review	0.3.0
2017-12		RP-172476				v1.0.0 submitted for plenary approval. Contents same as 0.3.0	1.0.0
2017-12	RAN#79	RP-180264	0004		F	Approved by plenary – Rel-15 spec under change control Implementation of endorsed CR on to 38.101-2 Endorsed draft CRs in RAN4-NR-AH#1801 F: R4-1800918, Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801097, Modification for TS38.101-2, CATT F: R4-1801098 Draft CR for TS38.101-2: On requirement metrics. Sumitomo Elec. Industries, Ltd F: R4-1800401, Editorial corections to 38.101-2, Qualcomm F: R4-1801122: Draft pCR for TS 38.101-2 version 15.0.0: Remaining ON/OFF masks for FR2 NR UE transmissions, Ericsson F: R4-1800418, Correction of NR SEM for FR2 table, vivo F: R4-1800316 Draft CR to 38.101-2: Tx spurious emission for NR FR2 (section 6.5.3), ZTE Corporation F: R4-1800918 Draft CR to 38.101-2 on channel bandwidth corrections (5.3.5), Nokia F: R4-1801013, Draft CR to 38.101-2: Clarifications to UE spectrum utilization section 5.3, Ericsson F: R4-1801229, Draft CR to 38.101-2: Channel spacing for CA for NR FR2(section 5.4.1.2), ZTE Corporation F: R4-1801232, Correction CR for channel spacing:38.101-2, Samsung	15.1.0

					F: R4-1801325, Draft CR to TS 38.101-2: Corrections on channel raster calculation in section 5.4.2, ZTE Corporation F: R4-1800860, Corrections of GSCN, Nokia	
					Endorsed draft CRs in RAN4#86	
					R4-1803054, Draft CR for new spec structure of 38.101-2, Ericsson	
					R4-1801446, Modification for NR UE time mask requirement for FR2, CATT	
					R4-1801729, Draft CR to 38.101-2: Corrections to In-band blocking requirements, Rohde & Schwarz	
					R4-1801967, CR on EVM spectrum flatness for FR2, Huawei R4-1802339, Draft CR to 38.101-2: Clarifications on peak directions	
					and REFSENS, ROHDE & SCHWARZ	
					R4-1802567, Draft CR to TS 38.101-2: Clarification of mixed numerology guardband size, Ericsson	
					R4-1803238, Draft CR for TS 38.101-2: ACLR requirement clarification, Huawei	
					R4-1803365, Draft CR to 38.101-2: Clarification on REFSENS Definition, ROHDE & SCHWARZ	
					R4-1803453, draft CR for introduction of completed band combinations from 37.865-01-01 into 38.101-2, Ericsson	
					R4-1803566, Draft CR for TS 38.101-2: Sync raster offset in re- farming bands (5.4.3), Ericsson	
2018-06	RAN#80	RP-181262	0010	F	CR to TS 38.101-2: Implementation of endorsed draft CRs from RAN4 #86bis and RAN4 #87	15.2.0
					Endorsed draft CRs from RAN4#86Bis	
					R4-1803736, Draft CR on channel raster entry of band n258 for TS 38.101-2, ZTE Wistron Telecom AB	
					R4-1804022, CR for modifications and clarifications for NR FR2 CA BW Classes, Nokia	
					R4-1804585, Draft CR to 38.101-2: IBE Section Update, Qualcomm,	
					R4-1804657, Introduction of UE to UE coexistence requirements	
					requirements for FR2, Qualcomm Incorporated R4-1804949, Corrections to 5.3.3 in TS 38.101-2, Nokia	
					R4-1805641, Corrections of BCS for n257 intraband contiguous CA in 38.101-2, Nokia	
					R4-1805685, Draft CR to TS38.101-2: Channel Raster to Resource Element Mapping (Section 5.4.2.2) and RB alignment with different	
					numerologies (Section 5.3.4), ZTE Corporation R4-1805704, Update of UE emission requirements for FR2,	
					Qualcomm Incorporated R4-1805705, Draft CR to 38.101-2: Update of section 7.1, Rohde &	
					Schwarz R4-1805757, Update of ACS requirement for FR2, Qualcomm	
					Incorporated R4-1805771, Update of IBB requirement for FR2, Qualcomm	
					Incorporated R4-1805775, draft CR for TS 38.101-2 on US 28 GHz band number,	
					Qualcomm Incorporated R4-1805949, Draft CR on minimum guardband of SCS 240 kHz SSB	
					for TS 38.101-2, ZTE Wistron Telecom AB R4-1805982, draft CR for 38.101-2: sync raster, Samsung	
					R4-1804878, draft CR introduction completed band combinations 37.865-01-01 -> 38.101-2, Ericsson	
					R4-1803628, pi/2 BPSK related CR, IITH	
					Endorsed draft CRs from RAN#87	
					R4-1806167, Draft CR on channel raster entry of band n261 for TS 38.101-2, ZTE Corporation	
					R4-1806169, Draft CR on SSB clarification for TS 38.101-2, ZTE Corporation	
					R4-1806383, Draft CR of clarifications on TRx RF test metrics for mmWave, Anritsu Corporation	
					R4-1806946, Draft CR for TS 38.101-2: Channel raster and NR-ARFCN clarification (5.4.2), Ericsson	
					R4-1807655, FR2 UE ACLR requirement for CA, Qualcomm R4-1807655, Further refinements for UE Rx requirements in FR2,	
					Qualcomm	
					R4-1807681, Draft CR on 38.101-2 on channel raster to achieve alignment of data and SSB subcarrier grids, Nokia	
					R4-1807853, Draft CR to TS 38.101-2: UE maximum output power for UL CA, Nokia	

R-1807955, Draft CR on 38.101-2: Transmit ON/OFF time mask for U. CA, Nokia RA-1807957, Draft CR to 38.101-2: Concepted 5W for UL CA, Nokia RA-1807957, Draft CR to 38.101-2: On EVM Averaging Length, Wording, Qualcomm Incorporated R-1808124, artist CR on ULE RF requirement for UEP p2 in FR2, Lic Searcronis R-1808125, Configured maximum output power for FR2, Ericsson R-1808126, Under CR on ULE RF requirement for UEP p2 in FR2, Lic Searcronis R-1808149, Under CR on ULE RF requirement for P2 in FR2, Lic Searcronis R-1808149, Under CR on ULE RF requirement for P2 in FR2, Lic Searcronis R-1808149, ULB Shaping Filter Requirement for P3 in FR2, 1808149, ULB Shaping Filter Requirement for P4 in Franciscon R-1808149, ULB Shaping Filter Requirement for P4 in Franciscon R-1808149, ULB Shaping Filter Requirement for FWA, Sammoung R-1808246, Draft CR for Finalizing ULB FR Requirement for FWA, Sammoung R-1808246, Draft CR for Finalizing ULB FR Requirement for FWA, Sammoung R-1808246, Draft CR for Sea 10.1-2: ERZ Type 1 ULB P0 were Control, Qualcomm R-1808206, Draft CR to 38.10-2: ERZ Type 1 ULB CA EIS update, R-1808296, Draft CR to 38.10-2: ERZ Type 1 ULB CA EIS update, R-1808291, Type 1 CR 1808246, Part CR to 38.10-2: ERZ Type 1 ULB CA EIS update, R-1808296, Draft CR to 38.10-2: ERZ Type 1 ULB CA EIS update, R-1808296, Draft CR to 38.10-2: ERZ Type 1 ULB CA EIS update, R-1808296, Draft CR to 10.10-2. Ercesson R-1809396, D							
R-1981957, Draft CR on 38.101-2: Cocupied BW for UL CA, Nokia R4-1980101, Ending-wording, Qualatorum Incorporated R4-1980105, Colingued maximum output power for FR2, Ericson BA, 1981-1981, Colingued maximum output power for FR2, Ericson BA, 1981-1981-198, Colingued maximum output power for FR2, Ericson BA, 1981-1981-1981, Draft CR on UE RF aquitement for UE type 3 in FR2, R4-1980147, Draft CR for TNR FR2 CA BW disas modifications, Neclasia R4-1980147, Draft CR for TNR FR2 CA BW disas modifications, Neclasia R4-1980149, Draft CR for TNR FR2 CA BW disas modifications, Neclasia R4-1980149, Draft CR for TNR FR2 CA BW disas modifications, Neclasia R4-1980149, Draft CR for TNR FR2 CA BW disas modifications, R4-1980149, Draft CR for TNR FR2 CA BW disas modifications, Neclasia R4-1980149, Draft CR for TNR FR2 CA BW disas modifications, R4-1980149, Draft CR for TnR FR2-1981149, Draft CR FR2-1981149							
Wording, Qualcomm Incorporated RR-1888105, Configured maximum output power for FR2, Ericsson RR-1888105, Configured maximum output power for FR2, Ericsson RR-1888105, Configured maximum output power for FR2, Ericsson RR-1808147, Draft CR for NS 38, 101-2: Minimum output and OFF Power, Nokia RR-1808147, Draft CR for NR FR2 CA BW class modifications, MediaTelk Inc. RR-1808148, EVM equaliser spectral flatness for FR2, Ericsson RR-1808148, EVM equaliser spectral flatness for FR2, Ericsson RR-1808148, EVM equaliser spectral flatness for FR2, Ericsson RR-1808148, Draft CR for TS 38,101-2: Channel and sync raster corrections (5.4), Ericsson RR-1808268, Draft CR for IR S8,101-2: Channel and sync raster corrections (5.4), Ericsson RR-1808268, Draft CR for IR S8,101-2: FR2 Type 1 UE Power Control, Qualcomm RR-1808269, Draft CR for 38,101-2: FR2 Type 1 UE Power Control, Qualcomm RR-1808269, Draft CR for 38,101-2: FR2 Type 1 UE A Eis update, Qualcomm RR-1808269, Draft CR for IR 38,101-2: UE ON/OFF masks, Ericsson RR-180712, draft CR introduction completed band combinations Provided RR-1809369, Draft CR for UR RNC for FR2 RF Tests, Qualcomm RR-1808269, Draft CR for IR RNR-RH-1807 RR-1809369, Draft CR for UR RNC for FR2 RF Tests, Qualcomm Incorporated RR-1809339, Draft CR on OR NR UR REFSENS SNR FRC for FR2, Intel Composition of the RNR-1809389, Draft CR on OR NR UR REFSENS SNR FRC for FR2, Intel Composition RR-1809369, Draft CR for IR RNR-1809380, Draft CR on OR RNR-1809369, Draft CR for IR RNR-1809380, Draft CR on OR RNR-1809369, Draft CR for IR RNR-1809360, Draft CR						R4-1807857, Draft CR on 38.101-2: Occupied BW for UL CA, Nokia	
RA-1808104, Karth Con tul ER Frequirement for Usy yea 2 in FR2, LG Electronics RA-18081024, Karth Con tul ER Frequirement for Usy yea 2 in FR2, LG Electronics RA-1808102, Draft CR to TS 38.101-2: Minimum output and OFF Power, Notice Power, Notice RA-1808149, EVM equaliser spectral flatness for FR2, Ericsson RA-1808149, EVM equaliser spectral flatness for FR2, Ericsson RA-1808149, EVM equaliser spectral flatness for FR2, Ericsson RA-1808164, EVM equaliser spectral flatness for FR2, Ericsson RA-1808160, Draft CR for Finalizing UE RF Requirement for FWA, Samsung) RA-1808165, Draft CR for TS 38.101-2: Channel and sync raster RA-1808165, Draft CR for TS 38.101-2: Channel and sync raster RA-1808165, Draft CR for S38.101-2: Channel and sync raster RA-1808165, Draft CR for S38.101-2: Channel and sync raster RA-1808169, Draft CR for S38.101-2: Channel and sync raster RA-1808191, TP to TS38.101-2: UE ON/OFF masks, Ericsson RA-180838, Draft CR on RA-MANR-RAH-1807 RA-180838, Draft CR on UR NRC for FR2 RF tests, Qualcomm Incorporated RA-180838, Draft CR on OR NR UE REFSENS SNR FRC for FR2, Intel Corporation RA-1809380, Draft CR on OR NR UE REFSENS SNR FRC for FR2, Intel Corporation RA-1809397, Draft CR on TS 38.101-2: Channel raster corrections RA-1810920, Draft CR for TS 38.101-2: UE ON-OFF mask clean up, RA-1810127, Draft CR for TS 38.101-2: UE ON-OFF mask clean up, RA-1810127, Draft CR for TS 38.101-2: UE ON-OFF mask clean up, RA-1810127, Draft CR for TS 38.101-2: Corrections on symbols and abtraviations in section 3, 2TE corporation RA-1810090, Draft CR for SR 30.101-2: Corporation on symbols and abtraviations in section 3, 2TE corpora							
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R4-1808206, Draft CR to 38.101-2: FR2 Type 1 UE Power Control, Qualcomm R4-1808208, Draft CR to 38.101-2: FR2 Type 1 UE CA EIS update, Qualcomm R4-1808191, TP to TS38.101-2: UE ON/OFF masks, Ericsson R4-1807102, draft CR introduction completed band combinations 37.865-01-01 - 38.101-2; Ericsson F Big CR for 38.101-2 Endorced draft CRs from RAN4#NR-AH-1807 R4-1809338, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809339, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Comporation R4-1809397, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Comporation R4-1809397, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2: On ON/OFF time mask, Intel Corporation R4-1809976, Draft CR of TS 38.101-2: Channel raster corrections (5.4.2); Ericsson R4-1810092, Draft CR TS 38.101-2: UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abreviations in section 3, ZTE Corporation R4-1810373, Draft CR to 38.101-2: Spurious emissions, Nokia R4-181086, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-181468, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181489, Draft CR to TS 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181489, Draft CR to TS 38.101-2: Carriect both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181489, Draft CR to TS 38.101-2: Carriect both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181489, Draft CR to TS 38.101-2: Carriect both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181489, Draft CR to TS 38.101-2: Carriect both Table 5.5A.2-1 and Table 5.5A.2-2. Verizon R4-181489, Draft CR to TS 38.101-2: C							
R4-1809208, Draft CR to 38.101-2: FR2 Type 1 UE CA EIS update, Qualcomm R4-1808191, TP to TS38.101-2: UE ON/OFF masks, Ericisson R4-1807102, draft CR introduction completed band combinations 37.865-01-01 >> 38.101-2, Ericsson F Big CR for 38.101-2 Enclosed Endorced draft CRs from RAN4#NR-AH-1807 R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809336, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809397, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809377, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809376, Draft CR on OCNC pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809376, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-18102976, Draft CR for TS 38.101-2: DN-OFF mask clean up, Ericsson R4-1810210, Draft CR for TS 38.101-2: DN-OFF mask clean up, Ericsson R4-1810210, Draft CR for TS 38.101-2: DN-OFF mask clean up, Ericsson R4-1810220, Draft CR for TS 38.101-2: Corporation start and outer RB allocations formula correction, Media Fek Inc. R4-1810220, Braft CR on UL-MIMIO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR for S 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810380, Draft CR to 38.101-2: Corporation semissions, Nokia R4-1810880, Draft CR for 38.101-2: Corporation framsmit Modulation Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Modulation Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: Ericsporated R4-18111406, Draft CR to 38.101-2: Carfect both Table 5.5A.2-1 and Table 5.5A.2-1 and Table 5.5A.2-1 and Table 5.5A.2-1 for to R4-181489, Draft CR to TS 38.101-2: Clarification on CONG, R4-1811489, Draft CR to TS 38.101-2: Clarification on CONG,						R4-1808206, Draft CR to 38.101-2: FR2 Type 1 UE Power Control,	
Qualcomm R4-1807192, draft CR introduction completed band combinations 37.865-01-01 - 38.101-2. Ericsson R4-1807102, draft CR introduction completed band combinations 37.865-01-01 - 38.101-2. Ericsson R4-180936, Draft CR or RAN4#NR-AH-1807 R4-1809336, Draft CR or UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809336, Draft CR or NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-180937, Draft CR or nn RN UE REFSENS SNR FRC for FR2, Intel Corporation R4-180937, Draft CR or nn RN UE REFSENS SNR FRC for FR2, Intel Corporation R4-180936, Draft CR or OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 or ON/OFF time mask, Intel Corporation R4-18109976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810992, Draft CR for TS 38.101-2: UE ON-OFF mask clean up, Ericsson R4-181092, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MMO requirement for Power Class 2 in FR2, LG Electronics Inc. R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810965, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810965, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810965, Draft CR to TS 38.101-2: ERZ UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements, Qualcomm Incorporated R4-1811460, Draft CR to 38.101-2: Carriccto both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181480, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-181499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated							
R4-1807102, draft CR introduction completed band combinations 37.865-01-01 -> 38.101-2, Encisson RAN#81 RP-181896 0015 F Big CR for 38.101-2 15.3.0 Endorced draft CRs from RAN4#NR-AH-1807 R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809336, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809337, Draft CR on measurement of receiver characteristics for FR2 RF Fests, Qualcomm Incorporated R4-180936, Draft CR on CNCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810992, Draft CR TS 38.101-2: LPC ON-OFF mask clean up, Enicsson R4-18110211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810213, Draft CR for NUL-MMO requirement for Power Class 2 in FR2, LG Electronics Inc. R4-1810330, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810965, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810965, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810965, Draft CR to TS 38.101-2: ERZ UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, Fr2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811140, Fr2 ULMIRO Updates and enhancements, Qualcomm Incorporated R4-1811140, Fr2 ULMIRO Updates and enhancements, Qualcomm Incorporated R4-1811439, Impelmentation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811499, Impelmentation of additional requiremen						Qualcomm	
37.865-01-01 -> 38.101-2, Ericsson F Big CR for 38.101-2 Endorsed draft CRs from RAN4#NR-AH-1807 R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809336, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809397, Draft CR on ORN gattern for FR2 REFSENS test, Qualcomm Incorporated R4-1809566, Draft CR on CNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorsed draft CRs from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-18099976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2) Ericsson R4-1810291, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810229, Traft CR for TS 38.101-2: EXPRENSION and abbreviations in section 3, ZTE Corporation R4-1810378, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: EXPRENSION Annual County Index (R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811130, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811480, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811490, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811490, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811490, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811490, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811490, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811490, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811490, Draft CR to 78.101-2: FR2 Power Cont						· · · · · · · · · · · · · · · · · · ·	
Endorced draft CRs from RAN4#NR-AH-1807 RA-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated RA-1809338, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation RA-1809339, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated RA-1809366, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated RA-1809366, Draft CR on CONG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 RA-1809317, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation RA-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson RA-18109976, Draft CR TS 38.101-2: WPR inner and outer RB allocations formula correction, MediaTek Inc. RA-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LB Electronics Inc RA-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation RA-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia RA-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia RA-1810805, Draft CR to 38.101-2: Expurious emissions, Nokia RA-1810805, Draft CR to 38.101-2: RF2 UE CA Transmit Signal Quality update, Qualcomm Incorporated RA-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated RA-1811149, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated RA-1811496, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2. Verizon RA-181480, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated RA-1811496, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated RA-1811496, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated RA-1811496, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated RA-1811496, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon RA-181489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated RA-1811496, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2 Verizon						,	
R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809378, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809397, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated R4-1809366, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810992, Draft CR for TS 38.101-2 · UE ON-OFF mask clean up, Ericsson R4-1810921, Draft CR for TS 38.101-2 · UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2 · MPR inner and outer RB allocations formula correction, Media Tek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810237, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, 2TE Corporation R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-18111456, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811460, Draft CR to 38.101-2: Crerct both Table 5.5A.2-1 and Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Dewer Control, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811151, Draft CR to 38.101-2: Calcingation on OCNG,	2018-09	RAN#81	RP-181896	0015	F	Big CR for 38.101-2	15.3.0
R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm Incorporated R4-1809378, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809397, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated R4-1809366, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810992, Draft CR for TS 38.101-2 · UE ON-OFF mask clean up, Ericsson R4-1810921, Draft CR for TS 38.101-2 · UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2 · MPR inner and outer RB allocations formula correction, Media Tek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810237, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, 2TE Corporation R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-18111456, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811460, Draft CR to 38.101-2: Crerct both Table 5.5A.2-1 and Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Dewer Control, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811151, Draft CR to 38.101-2: Calcingation on OCNG,						Endorced draft CRs from RAN4#NR-AH-1807	
R4-180933B, Draft CR on NR UE REFSENS SNR FRC for FR2, Intel Corporation R4-1809397, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated R4-1809866, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809866, Draft CR on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections ((5.4.2), Ericsson R4-181092, Draft CR TG 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810092, Draft CR TG 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810373, Draft CR to 18.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: FR2 UE CA Transmit Modulation Annex, Rohde & Schwarz R4-181104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2. Verizon R4-1811489, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2. Verizon R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated						R4-1809336, Draft CR on UL RMC for FR2 RF tests, Qualcomm	
Corporation R4-1809397, Draft CR on measurement of receiver characteristics for FR2 RF Tests, Qualcomm Incorporated R4-1809566, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810292, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810221, Draft CR for TS 38.101-2: Draft CR results of the second of t							
for FR2 RF Tests, Qualcomm Incorporated R4-1809566, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to TS 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811146, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-249CH2, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-249CH2, Qualcomm Incorporated						Corporation	
R4-1809566, Draft CR on OCNG pattern for FR2 REFSENS test, Qualcomm Incorporated Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-181092, Draft CR TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIMMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-18111322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-224(Prizon R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-224(Prizon							
Endorced draft CR s from RAN4#88 R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-181092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810092, Draft CR TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIM/O requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to TS 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, Finalization of SEM requirements, Qualcomm Incorporated R4-1811450, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811469, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,							
R4-1809817, TP to TS 38.101-2 on ON/OFF time mask, Intel Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810223, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-18108605, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-1811046, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-18111144, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-18111440, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811450, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811499, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Draft CR to 38.101-2: Clarification on OCNG,						Qualcomm Incorporated	
Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810803, Draft CR to 38.101-2: PR2 UE CA Transmit Modulation Annex, Rohde & Schwarz R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-18111140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-181132, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-181141515, Draft CR to TS 38.101-2: Clarification on OCNG,						Endorced draft CR s from RAN4#88	
Corporation R4-1809976, Draft CR for TS 38.101-2: Channel raster corrections (5.4.2), Ericsson R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810805, Draft CR to 38.101-2: Spurious emissions, Nokia R4-1810803, Draft CR to 38.101-2: PR2 UE CA Transmit Modulation Annex, Rohde & Schwarz R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-18111140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-181132, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-181141515, Draft CR to TS 38.101-2: Clarification on OCNG,						P4 1900917 TD to TS 29 101 2 on ON/OFF time mask Intol	
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R4-1810092, Draft CR TS 38.101-2 - UE ON-OFF mask clean up, Ericsson R4-1810211, Draft CR for TS 38.101-2: MPR inner and outer RB allocations formula correction, MediaTek Inc. R4-1810228, draft CR on UL-MIMO requirement for Power Class 2 in FR2, LG Electronics Inc. R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to TS 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-1811046, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811149, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated						l (= 4 a) = 1	
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R4-1810373, Draft CR to 38.101-2: Corrections on symbols and abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-18108063, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,						R4-1810228, draft CR on UL-MIMO requirement for Power Class 2	
abbreviations in section 3, ZTE Corporation R4-1810805, Draft CR to TS 38.101-2: Spurious emissions, Nokia R4-1810863, Draft CR to 38.101-2: Addition of Transmit Modulation Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,							
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Annex, Rohde & Schwarz R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal Quality update, Qualcomm Incorporated R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,							
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R4-1811104, Finalization of SEM requirements in FR2, Qualcomm Incorporated R4-1811140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,						R4-1811026, Draft CR to 38.101-2: FR2 UE CA Transmit Signal	
Incorporated R4-1811140, FR2 ULMIMO Updates and enhancements, Qualcomm Incorporated R4-1811322, Draft CR to 38.101-2: REFSENS of power class 1, Intel Corporation R4-1811456, Draft CR on DL Physical Channel for FR2 RF tests, Qualcomm Inc R4-1811460, Draft CR to 38.101-2: Correct both Table 5.5A.2-1 and Table 5.5A.2-2, Verizon R4-1811489, Draft CR to 38.101-2: FR2 Power Control, Qualcomm Incorporated R4-1811499, Implementation of additional requirement to protect passive EESS in 23.6-24GHz, Qualcomm Incorporated R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,							
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Keysight Technologies UK Ltd						R4-1811515, Draft CR to TS 38.101-2: Clarification on OCNG,	
						Keysight Technologies UK Ltd	

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						R4-1811517, Draft CR on NR DL FRCs for FR2 UE RF requirements, Intel Corporation	
						R4-1811519, Draft CR to 38.101-2: On FR2 MPR for single CC PC1	
						and PC3, Qualcomm	
						R4-1811520, Draft CR to 38.101-2: FR2 Max. Input Power, Qualcomm Incorporated	
						R4-1811524, Clearification of UL MIMO for FR2, OPPO	
						R4-1811551, Draft CR to TS 38.101-2 on channel bandwidth and spacing descriptions, Ericsson	
						R4-1811554, Draft CR to 38.101-2: Corrections on description of	
						channel raster entries, ZTE Corporation	
						R4-1811802, Draft CR to TS 38.101-2 update the Pumax tolerance table for configured transmitted power, Intel Corporation	
						R4-1811807, Draft CR to 38.101-2: FR2 UE Transmit Signal Quality	
						update, Qualcomm Incorporated R4-1811813, Correction on UE transmitter requirement for FR2,	
						CATT	
						R4-1811817, Updated ON/OFF mask for FR2, vivo	
						R4-1811800, DRAFT CR for PCmax FR2 correction, Qualcomm Incorporated	
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						R4-1812122, Draft CR for FR2 ACLR Measurement BW, Qualcomm	
						R4-1812134, CR on Out of Band Blocking for FR2, Intel Corporation R4-1812426, draft CR of MPR for Power Class 2 in FR2, LG	
						Electronics	
						R4-1812428, draft CR of transmit signal quality for Power Class 2 in FR2. LG Electronics	
						R4-1812453, Draft CR to TS 38.101-2 Adjust placement of 0dB MPR	
						reference waveform, Intel Corporation R4-1812495, Draft CR to 38.101-2: Corrections on channel raster &	
						SS raster, ZTE Corporation	
						R4-1813470, draftCR on applicability of TDD configuratiin for CA in	
						TS 38.101-2, Huawei R4-1813472, draftCR on CA spectrum Emission for TS 38.101-2,	
						Huawei	
						R4-1813473, draftCR on coherent UL MIMO for TS 38.101-2, Huawei	
						R4-1813527, Correction to FR2 spurious emission requirement,	
						Nokia R4-1813585, Draft CR to Specify UL Power for FR2 REFSENS Test	
						Cases, Keysight	
						R4-1813815, Draft CR to 38.101-2: Corrections on configurations for intra-band non-contiguous CA, ZTE Corporation	
						R4-1814149, Changes to FR2 UL MIMO, OPPO	
						R4-1814180, Draft CR to TS 38.101-2 on channel arrangement	
						descriptions, LG Electronics Inc. R4-1814181, Draft CR to 38.101-2: Corrections on the descriptions	
				_		of UE channel bandwidth for CA, ZTE Corporation	
				2		R4-1814163, draft CR of operating band for Power Class 2 in FR2, LG Electronics	
						R4-1813834, Draft CR to 38.101-2: Update of Annex F, Rohde &	
						Schwarz R4-1814164, draftCR on MPR for TS 38.101-2, Huawei	
						R4-1814165, Draft CR to 38.101-2: FR2 Power Control for CA,	
						Qualcomm Incorporated	
						R4-1814170, Draft CR to 38.101-2: FR2 UL Config for EIS Testing, Qualcomm Incorporated	
						·	
						Endorsed draft CR's from RAN4#89 R4-1815951, dCR on TS38.101-2 merging draft CRs from	
						RAN4#89, Qualcomm Incorporated	
						R4-1814497, Correction on UL MIMO requirement for PC1 UE, Samsung	
						R4-1814585, Draft CR to TS 38.101-2 UL CA power control in FR2,	
						Intel Corporation R4-1814698, Draft CR to TS38.101-2 updating references, Apple	
						Inc.	
						R4-1815623, Draft CR to 38.101-2: FR2 Max. Input Power UL	
						Configuration, Qualcomm Incorporated R4-1815801, draft CR editorial correction in 38.101-2, Ericsson	
						R4-1815810, draft Rel-15 CR to 38.101-2 to include n260 fallbacks	
						needed, Ericsson R4-1815942, dCR on P-MPR for FR2, Qualcomm Incorporated	
						R4-1815943, dCD Coherent UL MIMO parameters for FR2,	
						Qualcomm Incorporated R4-1816205, Draft CR to TS38.101-2 correcting the Pcmax	
						requirement, Apple Inc.	

R4-1816206, draft CR on Pcmax for ULCA and limitation on ma	x
aggregated ULCA BW, Qualcomm Incorporated	
R4-1816217, Draft CR to 38.101-2 on UE maximum output pow	er
with additional requirements, ZTE Corporation R4-1816218, Draft CR for Introducing missing requirement for p	ower
class 4 in FR2 for TS 38.101-2, NTT DOCOMO, INC.	OWCI
R4-1816219, draft CR of MPR for Power Class 2 in FR2, LG	
Electronics	
R4-1816220, Draft CR to 38.101-2: On FR2 CA MPR v2, Qualc	omm
Incorporated	
R4-1816239, Draft CR to 38.101-2: On FR2 EESS A-MPR for n	258,
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R4-1816257, Draft CR to TS38.101-2 to correct UL CA scope for	r l
FR2 in Rel-15, Apple Inc.	"
R4-1816605, TDD configuration for UE Tx test in FR2, Ericsson	
R4-1816664, Draft CR to 38.101-2 (5.3.4) RB alignment, Huaw	
R4-1816751, Draft CR for RF exposure compliance in TS38.10	l - 2,
LG Electronics France	
R4-1816626, Draft CR to TS 38.101-2: Introducing multi-band	
applicability for PC3, Apple Inc. R4-1816634, Draft CR to 38.101-2: FR2 EIS Spherical Coverage	ااا
Requirement, Qualcomm Incorporated	~
R4-1816639, Verification of beam correspondence, Ericsson, S	ony
R4-1816633, draft CR on UE type for Power Class 2 in FR2, LG	
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R4-1816644, Draft CR to TS 38.101-2: Temperature Condition	or
testing EIRP Spherical Coverage requirement, Apple Inc. 2019-03 RAN#83 RP-190747 0018 F CR to TS 38.101-2: Implementation of endorsed draft CRs from	15.5.0
RAN4#90 plus PC3 MPR changes to accommodate FR2 OBW	15.5.0
TO WAY WOO PLOUT OO WILL OF A COCCUMINATION OF A CO	
Endorced draft CRs from RAN4#90	
R4-1900049, Draft CR on UL RMC for FR2 UE RF Tests, Qualo	omm
Incorporated Programme Control of the Control of th	
R4-1900050, Draft CR on DL RMC for FR2 UE RF Tests, Quald	omm
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R4-1900254, Draft CR on clarification of maxUplinkDutyCycle in	1
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R4-1900386, CR to 38.101-2 on CA BW Classes fallback group	s
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R4-1900509, Draft CR to TS 38.101-2 on BCS definition for intr	a-
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R4-1900531, draft CR on A-MPR for power class 2 in FR2, LG	
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R4-1900535, draft CR on A-MPR for CA for power class 2 in FF	2,
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R4-1900677, Draft CR to 38.101-2: FR2 ULMIMO max. output power, Qualcomm Incorporated	
R4-1900674, Draft CR to 38.101-2: UL config for DL NC CA,	
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R4-1900678, Draft CR to 38.101-2: EVM Requirement for PRAG	CH,
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R4-1900679, Draft CR to 38.101-2: IBB requirement update,	
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R4-1900736, Draft CR on editorial error of TS38.101-2, LG	
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R4-1900755, Draft CR on spurious emission limit in 38.101-2,	
	e

					Incorporated R4-1902180, D between minim R4-1902345, di Skyworks Solut R4-1902474, D in REFSENS fo R4-1902490, di Huawei R4-1902491, D DOCOMO, INC R4-1902492, D	raft CR to 38.101-2: correction of multi-band aspects or PC3, Apple Inc. raftCR on maximum output power for TS 38.101-2, raft CR for Multi-band relaxation to TS 38.101-2, NTT	
2019-06	RAN#84	RP-191240	0021	F	Further change Changes in Sec Section 6.2.2.3 requirements	beam correspondence, Apple Inc s in RAN#83: ction 6.2.2.0 to modify the MPR=0dB waveform and to modify the MPR tables to accommodate the OBW 11-2: Implementation of endorsed draft CRs from	15.6.0
2019-06	RAN#84	RP-191240	0021	F	RAN4#90bis ar		15.6.0
						CRs from RAN4#90Bis: Draft CR to TS 38.101-2 Correction to Pcmax, Intel Corporation Draft CR on PRACH and PUCCH format description for EVM in FR2Anritsu corporation	
					R4-1903121	Draft CR on DL power allocation for TS 38.101-2	
					R4-1903242 R4-1903474	Intel Corporation Adding BCS definition in TS38.101-2 CATT draft CR of in-band emission for FR2 PC2 LG Electronics	
					R4-1903888	Draft CR: Alignment of FR2 DL scheduling of DL	
					R4-1904001	RMC with UL RMCEricsson Draft CR for TS 38.101-2 – UE coordinate system	
					R4-1904411	Rohde & Schwarz draft Rel-15 CR for editorial corrections in 38.101-2	
					R4-1904553	Ericsson Draft CR to 38.101-2: FR2 power dynamics DTX	
					R4-1904930	removal Qualcomm Incorporated Draft CR to 38.101-2: Updating MPR wording in	
					R4-1904931	ULMIMO section Qualcomm Incorporated Draft CR to clarify frequency of carrier leakage in	
					R4-1904932	RBs for FR2 Anritsu corporation Draft CR on editorial error of TS38.101-2 LG	
						Electronics France	
					R4-1904933	Draft CR on UE optional bandwidth for FR2 Huawei, HiSilicon	
					R4-1904956	Draft CR for TS 38.101-2: Corrections to configurations for intra-band non-contiguous CA	
					R4-1904961	MediaTek Inc. Draft CR for TR38.101-2 – Update to EVM	
					R4-1904962	averaging Rohde & Schwarz Draft CR to 38.101-2: FR2 ULMIMO EVM	
						Qualcomm Incorporated	
					R4-1904966	Draft CR to TS 38.101-2 CA maximum input level Intel Corporation	
					R4-1904986	Draft CR for TS 38.101-2: Corrections to EVM equalizer spectrum flatness requirements MediaTek Inc.	
					R4-1904994	draft CR to 38.101-2 Correction to ACS and In-band Blocking notes Intel Corporation	
					R4-1905003	Draft CR to 38.101-2: FR2 PC3 and PC1 MPR Qualcomm Incorporated	
					R4-1905005	Draft CR for 38.101-2 frequency separation class Huawei, HiSilicon	
						CRs from RAN4#91:	
					R4-1905504	Change description 4.2(d) in Applicability of minimum requirements for TS 38.101-2 vivo	
					R4-1905685	Draft CR to 38.101-2: FR2 Sensitivity Qualcomm Incorporated	
					R4-1905764	draft CR to 38.101-2 UE maximum output power reduction for UL-MIMOIntel Corporation	
					R4-1905765	draft CR to 38.101-2 UE maximum output power for UL-MIMO Intel Corporation	

							Correction to a description of PRB for in-band	
							emission in FR2 Anritsu Corporation Correction to power control in FR2 Anritsu	
							Corporation	
							draft CR of loosening EIS for FR2 PC2 LG	
							Electronics Inc.	
						R4-1907003	Draft CR for editorial corrections in TS 38.101-2 Google Inc.	
						R4-1907420	draft CR of simple application for FR2 PC2 and 4	
							requirements with PC3 same requirements LG	
							Electronics Inc.	
							Draft CR for TS 38.101-2 Correction of channel bandwidth set for NR CA Huawei, HiSilicon,	
							CMCC	
							Draft CR to 38.101-2: Insert definitions Qualcomm	
							Incorporated	
							Draft CR to TS38.101-2 Complete FR2 MPR/A-MPR Intel Corporation	
							Amendment of the relative power tolerance	
							requirement Ericsson, Qualcomm Incorporated	
						R4-1907446	Draft CR to 38.101-2: FR2 CA REFESNS	
						R4-1907447	Qualcomm Incorporated Draft CR to 38.101-2 on UL RMC slot patterns	
						1307447	Apple Inc.	
						R4-1907466	Draft CR to 38.101-2: FR2 CA MPR enhancement	
						D4 4007400	Qualcomm Incorporated	
						R4-1907468	Draft CR to 38.101-2: FR2 MPR Wording CleanUp Qualcomm Incorporated	
							Draft CR to TS38.101-2 on FR2 PC3 UE	
							maxUplinkDutyCycle Nokia, Nokia Shanghai Bell	
							Draft CR to TS 38.101-2 on configurations for intra-	
							band contiguous CA ZTE Corporation Correction to Pcmax and Pumax for CA Ericsson	
							Draft CR to TS38.101-2 on beam correspondence	
						D. / /	Samsung, Apple, Verizon	
						R4-1907688	Correction to CA carrier spacing Ericsson	
2019-06	RAN#84	RP-191241	0020		В	CR to REL-16 TS	S 38.101-2: Implementation of endorsed draft CRs	16.0.0
	5.4.1	55 (5)			_		ions and dual Connectivity combinations	1000
2019-06	RAN#84	RP-191241	0022	1	В		completed band combinations 38.716-01-01 ->	16.0.0
2019-06	RAN#84 RAN#85	RP-191241 RP-192049		1	В	CR introduction of 38.101-2 CR to TS 38.101	-2: Implementation of endorsed draft CRs from	16.0.0
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10	-2: Implementation of endorsed draft CRs from 6)	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10	-2: Implementation of endorsed draft CRs from	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10 - Mirrors changes	-2: Implementation of endorsed draft CRs from 6)	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-1) - Mirrors changes Endorsed draft C R4-1907999	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-1) - Mirrors changes Endorsed draft C R4-1907999 Verizon, Nok	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-1) - Mirrors changes Endorsed draft C R4-1907999 E Verizon, Nok R4-1908082 of	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft C R4-1907999 E Verizon, Nok R4-1908082 of Samsung, ZT	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft C R4-1907999 E Verizon, Nok R4-1908082 of Samsung, ZT R4-1908137 C SCHWARZ	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE &	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10 - Mirrors changes Endorsed draft C R4-1907999 E Verizon, Nok R4-1908082 C Samsung, ZT R4-1908137 C SCHWARZ R4-1908153 C	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & dCR to 38.101-2: Editorial corrections for 38.101-2	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10-Mirrors changes) Endorsed draft CR 4-1907999 EVerizon, Nok R4-1908082 CS Samsung, ZR 4-1908137 SCHWARZ R4-1908153 CQualcomm Ir	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CR to 38.101-2: Editorial corrections for 38.101-2 incorporated	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10-Mirrors changes) Endorsed draft CR-1907999 EVerizon, Nok R4-1908082 CSamsung, ZR-1908137 SCHWARZ R4-1908153 CQualcomm Ir R4-1908573 Erequirements for	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & dCR to 38.101-2: Editorial corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft C R4-1907999 E Verizon, Nok R4-1908082 of Samsung, ZT R4-1908137 C SCHWARZ R4-1908153 of Qualcomm In R4-1908573 E requirements for R4-1908633 E	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS trom RAN4#92 Draft CR to TS 38.101-2: Corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: Corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft CR4-1907999 Verizon, Nok R4-1908082 Samsung, ZTR4-1908137 SCHWARZ R4-1908153 Qualcomm In R4-1908573 Erequirements for R4-1908633 Window length (S	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration kia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to TS 38.101-2: corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11-Mirrors changes) Endorsed draft CR4-1907999 Verizon, Noke R4-1908082 CSamsung, ZR4-1908137 SCHWARZ R4-1908153 CQualcomm Ir R4-1908573 Erequirements for R4-1908633 Window length (SR4-1908708	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS trom RAN4#92 Draft CR to TS 38.101-2: Corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: Corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft CR 4-1907999 CVerizon, Nok R4-1908082 CS Amsung, ZT R4-1908137 CS CHWARZ R4-1908153 CQualcomm Ir R4-1908573 CR 4-1908633 CW 19080 LE R4-1908708 CS R4-1908708 CS Spurious emissio R4-1909117 CS CR TS - 1008 CS CR - 1008 CS	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to TS 38.101-2: corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: Corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft C R4-1907999 E Verizon, Nok R4-1908082 C Samsung, ZT R4-1908137 C R4-1908153 C Qualcomm Ir R4-1908573 E requirements for R4-1908633 E window length (S R4-1908708 E spurious emissio R4-1909117 E Huawei	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to TS 38.101-2: corrections for 38.101-2 necorporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5)ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR for 38.101-2 applicability for intra-band CA	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10-10-10-10-10-10-10-10-10-10-10-10-10-	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to TS 38.101-2: corrections for 38.101-2 corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5)ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10- Mirrors changes) Endorsed draft CR-1907999 EVerizon, Nok R4-1908082 CSamsung, ZTR-1908137 CSCHWARZ R4-1908153 CQualcomm Ir R4-1908573 Erequirements for R4-1908633 EWINDOWN LENGTH (SR4-1908708 ESPURIOUS emission R4-1909117 EWINDOWN LENGTH (SR4-1909117 EWINDOWN LENGTH (SR4-1909116 EVERTH (SR4-190916 EVERTH (SR4-190916 EVER	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to TS 38.101-2: corrections for 38.101-2 necorporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5)ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR for 38.101-2 applicability for intra-band CA	
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				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11 - Mirrors changes Endorsed draft CR4-1907999 Verizon, Nok R4-1908082 Samsung, ZR4-1908137 SCHWARZ R4-1908153 Qualcomm In R4-1908573 Erequirements for R4-1908633 Window length (SR4-1908708 Espurious emissio R4-1909117 Huawei R4-1909316 Corporation R4-1910235 Electronics Finlan R4-1910238	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration idia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS to TS 38.101-2: corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: Corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR to TS38.101-2 on symbols correction ZTE Draft CR to TS38.101-2 for Rx RF requirements LG and CR for Handling of fallbacks for combined	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11- Mirrors changes) Endorsed draft CR 4-1907999 Verizon, Nok R4-1908082 CS 38 SAN SAN SCHWARZ R4-1908153 CQ Walcomm Ir R4-1908573 CR 4-1908633 Window length (SR 4-1908708 SPURIOUS emission R4-1909117 Huawei R4-1909316 COrporation R4-1910235 CE lectronics Finlar R4-1910238 CC ontiguous and residence of the second	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS to TS 38.101-2: corrections for 38.101-2 on corporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR to TS38.101-2 on symbols correction ZTE Draft CR to TS 38.101-2 for Rx RF requirements LG and CR for Handling of fallbacks for combined non-contiguous CA in FR2 Apple	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-11-Mirrors changes) Endorsed draft CR 4-1907999 CVerizon, Nok R4-1908082 CS AMBURG R4-1908137 CS CHWARZ R4-1908153 CQualcomm Ir R4-1908573 CR 4-1908633 CM 1909117 CM 190911	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS 101-2: Editorial corrections for 38.101-2 nocrporated Draft CR to TS 38.101-2: Corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR for 38.101-2 applicability for intra-band CA Draft CR to TS38.101-2 on symbols correction ZTE Draft CR to TS38.101-2 for Rx RF requirements LG and CR for Handling of fallbacks for combined non-contiguous CA in FR2 Apple Draft CR to TS 38.101-2 on NR CA configurations poration	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10-10-10-10-10-10-10-10-10-10-10-10-10-	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS 101-2: Editorial corrections for 38.101-2 norporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR for 38.101-2 applicability for intra-band CA Draft CR to TS38.101-2 on symbols correction ZTE Draft CR to TS38.101-2 for Rx RF requirements LG and CR for Handling of fallbacks for combined con-contiguous CA in FR2 Apple Draft CR to TS 38.101-2 on NR CA configurations poration DCR for TS 38.101-2: Reference signal clarifications	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10-10-10-10-10-10-10-10-10-10-10-10-10-	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration dia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & dCR to 38.101-2: Editorial corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5)ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR for 38.101-2 applicability for intra-band CA Draft CR to TS38.101-2 on symbols correction ZTE Draft CR to TS38.101-2 for Rx RF requirements LG and CR for Handling of fallbacks for combined conon-contiguous CA in FR2 Apple Draft CR to TS 38.101-2: Reference signal clarifications incorporated	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-10-10-10-10-10-10-10-10-10-10-10-10-10-	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration dia, Ericsson, Qualcomm draft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS from RAN4#92 Draft CR to 38.101-2: Editorial corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: Corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR for 38.101-2 applicability for intra-band CA Draft CR to TS 38.101-2 on symbols correction ZTE Draft CR to TS 38.101-2 for Rx RF requirements LG and CR for Handling of fallbacks for combined con-contiguous CA in FR2 Apple Draft CR to TS 38.101-2 on NR CA configurations proration dCR to 38.101-2: Reference signal clarifications incorporated dCR to 38.101-2: FR2 AMPR updates, including	
				1		CR introduction of 38.101-2 CR to TS 38.101 RAN4#92 (Rel-1) - Mirrors changes Endorsed draft CR4-1907999 Verizon, Nok R4-1908082 Samsung, ZTR4-1908137 SCHWARZ R4-1908153 Qualcomm In R4-1908573 Irequirements for R4-1908573 Irequirements for R4-1908708 Spurious emissio R4-1909117 Huawei R4-1909316 Corporation R4-1910235 Electronics Finlan R4-1910236 Contiguous and r R4-1910241 If or FR2 ZTE Corp R4-1910259 Qualcomm In R4-1910261 CERC 74-01 chan	-2: Implementation of endorsed draft CRs from 6) s in R4-1910352 for Rel-15 TS 38.101-2 CRs from RAN4#92 Draft CR for NR non-contiguous CA configuration raft CR to TS 38.101-2 on channel spacing for CA TE Update to FR2 EVM definition ROHDE & CRS 10: AS 101-2: Editorial corrections for 38.101-2 incorporated Draft CR to TS 38.101-2: corrections on Rx intra-band CA ZTE Corporation Draft CR to TS38.101-2: Corrections on EVM Section F.5) ZTE Corporation Draft CR to TS38.101-2: corrections on the receiver on (section 7.9) ZTE Corporation Draft CR to TS38.101-2 applicability for intra-band CA Draft CR to TS 38.101-2 on symbols correction ZTE Draft CR to TS38.101-2 for Rx RF requirements LG and CR to TS 38.101-2 on NR CA configurations poration Draft CR to TS 38.101-2 on NR CA configurations poration Draft CR to TS 38.101-2: Reference signal clarifications incorporated dCR to 38.101-2: FR2 AMPR updates, including ages Qualcomm Incorporated dCR to 38.101-2: FR2 CA MPR refinement	

						R4-1910328 Draft CR to TS 38.101-2: Corrections for UL and DL	
						RMC for FR2 tests Intel Corporation	
						R4-1910333 Draft CR for 38.101-2 reference measurement channel for beam correspondence Huawei	
						R4-1910334 Draft CR for TS38.101-2, Editorial corrections	
						CATT	
						R4-1910412 Draft CR for 38.101-2 correction for channel raster	
						Huawei	
						R4-1910614 Draft CR for TS 38.101-2: Channel spacing for adjacent NR carriers ZTE	
						Conditional agreements for BC for PC1/2/4 from R4-1902252	
2019-09	RAN#85	RP-192027	0025		F	Minor corrections of intra-band non-contiguous CA operating bands	16.1.0
2010 00	10 11 11 00	102027	0020	1	•	in TS 38.101-2	10.1.0
2019-09	RAN#85	RP-192027	0026		D	Rel-16 CR for further simplification of 38.101-2 Table 5.5A.2-2	16.1.0
2019-12	RAN#86	RP-193030			Α	CR to 38.101-2: DMRS exceptions	16.2.0
2019-12	RAN#86	RP-193030			Α	Sync raster to SSB resource element mapping	16.2.0
2019-12	RAN#86	RP-193030	0039		Α	CR to 38.101-2 (Rel-16) to clarify measurement interval and	16.2.0
						observation window on frequency error	
2019-12	RAN#86	RP-193031	0041		Α	CR to TS 38.101-2 on beam correspondence side condition	16.2.0
2019-12	RAN#86	RP-193031	0044		Α	applicability CR to TS 38.101-2: Correctin on FInterferer (offset) for CA ACS	16.2.0
2019-12	RAN#86	RP-193031			A	CR for TS 38.101-2: Editorial correction on MPR for contiguous CA	16.2.0
2019-12	INAIN#00	KF-193030	0048			notation	10.2.0
2019-12	RAN#86	RP-193031	0050		Α	CR for TS 38.101-2: CA bandwidth class definition amendment	16.2.0
2019-12	RAN#86	RP-193030			Α	CR to TS 38.101-2 on corrections to channel raster entries for NR	16.2.0
				<u></u>		band (Rel-16)	
2019-12	RAN#86	RP-193030			Α	CR to transmit modulation quality in FR2	16.2.0
2019-12	RAN#86	RP-193030			Α	Frequency separation class clarification REL-16	16.2.0
2019-12	RAN#86	RP-193012	0064		В	CR introduction completed band combinations 38.716-01-01 ->	16.2.0
0040.40	DAN//00	DD 400044	0005		_	38.101-2	40.0.0
2019-12	RAN#86	RP-193011	0065	1	F	CR to 38.101-2-g10 Corrections to maximum output power reduction for power class 3	16.2.0
2019-12	RAN#86	RP-193030	0067		Α	CR for TS 38.101-2: power classes and maxUplinkDutyCycle-FR2	16.2.0
2019-12	RAN#86	RP-193031			A	CR for agreed MPR CA for FR2 intra-band contiguous	16.2.0
2019-12	RAN#86	RP-193031		1	A	CR for 38.101-2 on NS_202 band defintion	16.2.0
2019-12	RAN#86	RP-193031			Α	CR to TS 38.101-2: Correctin on CA NRACLR	16.2.0
2020-03	RAN#87	RP-200395			Α	Correction of the FR2 RMC slot patterns for MOP test cases	16.3.0
2020-03	RAN#87	RP-200395			Α	CR to 38.101-2 (Rel-16) MPR for CA	16.3.0
2020-03	RAN#87	RP-200395			F	CR FR2 CA tables REL16	16.3.0
2020-03	RAN#87	RP-200395	0108		Α	CR to TS 38.101-2 on corrections to intra-band contiguous CA for	16.3.0
						FR2 bands (Rel-16)	
2020-03	RAN#87	RP-200395	0110		Α	CR to 38.101-2: Align Rx CA requirements structure with TS38.101-	16.3.0
2020.02	RAN#87	RP-200395	0111		Α	The state of the s	16.3.0
2020-03	KAIN#01	RP-200395	0114		А	in Abbreviations section	16.3.0
2020-03	RAN#87	RP-200395	0118		Α	CR to TS 38.101-2: Correction on FRC table for FR2 DL 64QAM	16.3.0
2020-03	RAN#87	RP-200469		2	Α	CR for 38.101-2 side condition for BC_Rel16	16.3.0
2020-03	RAN#87	RP-200380		_	F	Editorial corrections	16.3.0
2020-03	RAN#87	RP-200378			F	Correction of Inner Allocation Definition for Powerclass 3	16.3.0
2020-03	RAN#87	RP-200395			Α	R16 CR to 38.101-2: TRS and SSB configurations in FR2	16.3.0
2020-04			0147		Α	Change history corrected	16.3.1
2020-06	RAN#88	RP-200985			F	CR on ACLR MBW definition in FR2	16.4.0
2020-06	RAN#88	RP-201046			Α	CR to 38.101-2: Revision to Multiband Relaxations	16.4.0
2020-06	RAN#88	RP-200985			Α	CR to 38.101-2 on correction of reference point for beam	16.4.0
						correspondence side conditions R16	15
2020-06	RAN#88	RP-200985			A	CR to 38.101-2 to correct Link and Meas Angles	16.4.0
2020-06	RAN#88	RP-200985			A	CR to 38.101-2: NS_202 update after changes to EU regulations	16.4.0
2020-06	RAN#88	RP-200985	0172		Α	CR for TS 38.101-2: Intra-band non-contiguous CA configuration	16.4.0
2020.06	DVVITOO	DD 200005	0174	1	٨	clarifications CR for TS 38.101-2: Correction for configured transmitted power for	16.4.0
2020-06	RAN#88	RP-200985	0174		Α	CA 15 38.101-2: Correction for configured transmitted power for CA	10.4.0
1	i		0175		F	CR for TS 38.101-2: Clarifications on transmitter power for receiver	16.4.0
2020-06	RAN#88	RP-200985		1	' '		10.4.0
2020-06	RAN#88	RP-200985	0170			requirements	
2020-06	RAN#88 RAN#88	RP-200985 RP-200959			Α	CR for TS 38.101-2: Intra-band non-contiguous CA configuration	16.4.0
	RAN#88	RP-200959	0181		Α	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications	
2020-06	RAN#88	RP-200959 RP-200985	0181 0183		Α	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs	16.4.0
2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88	RP-200959 RP-200985 RP-200985	0181 0183 0184		A F	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC	16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88	RP-200959 RP-200985 RP-200985 RP-200985	0181 0183 0184 0188		A F B	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs	16.4.0 16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200959 RP-200985 RP-200985 RP-200985 RP-200972	0181 0183 0184 0188 0193		A F B	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM	16.4.0 16.4.0 16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200959 RP-200985 RP-200985 RP-200985 RP-200972 RP-200985	0181 0183 0184 0188 0193 0198		A F B F A	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM ACS requirement correction	16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200959 RP-200985 RP-200985 RP-200985 RP-200972 RP-200985 RP-200985	0181 0183 0184 0188 0193 0198 0200		A F B F A	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM ACS requirement correction CR for intra-band CA DL Rx requirement-FR2_Rel-16	16.4.0 16.4.0 16.4.0 16.4.0 16.4.0
2020-06 2020-06 2020-06 2020-06 2020-06 2020-06	RAN#88 RAN#88 RAN#88 RAN#88 RAN#88 RAN#88	RP-200959 RP-200985 RP-200985 RP-200985 RP-200972 RP-200985	0181 0183 0184 0188 0193 0198 0200 0208	1	A F B F A	CR for TS 38.101-2: Intra-band non-contiguous CA configuration clarifications Update of CSI-RS definition for FR2 DL RMCs Correction to FR2 QPSK UL RMC Correction of Rel-16 UL RMCs CR to TS 38.101-2: Introduction of FR2 DL 256QAM ACS requirement correction	16.4.0 16.4.0 16.4.0 16.4.0 16.4.0

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2020-06	RAN#88	RP-200959	0209		Α	CR to 38.101-2: Introduce mmWave intra-band uplink CA configurations	16.4.0
2020-06	RAN#88	RP-200985	0161	1	В	CR to K1 value in Annex A.3.3 of 38.101-2	16.4.0
2020-06	RAN#88	RP-201046			A	CR to 38.101-2 on FR2 frequency separation class enhancement	16.4.0
2020-06	RAN#88	RP-200985		2	В	CR on Pcmax correction for CA	16.4.0
2020-06	RAN#88	RP-200978		1	В	CR to 38.101-2 for Introduction of band n259	16.4.0
2020-06	RAN#88	RP-201046			A	FR2 new MPR and modifiedmpr	16.4.0
2020-09	RAN#89	RP-201496		1	В	Introduction of MPE related P-MPR operation in sub-clause 6.2.4	16.5.0
2020-09	RAN#89	RP-201512			A	CR on Minimum output power and Off power MBW definition in FR2	16.5.0
2020-09	RAN#89	RP-201496		1	В	CR to 38.101-2 (Rel-16) intra-band non-cont. DL CA	16.5.0
2020-09	RAN#89	RP-201512		· ·	A	CR for R16 38.101-2: Correction of in-band emission tables	16.5.0
2020-09	RAN#89	RP-201512		1	F	Correction for REL16 FR2 contiguous intra-band CA configuration	16.5.0
=====		20.0.2	0220		•	table	. 0.0.0
2020-09	RAN#89	RP-201512	0230	1	F	modifiedMPR correction for FR2 REL16	16.5.0
2020-09	RAN#89	RP-201496		2	В	Beam correspondence enhancement	16.5.0
2020-09	RAN#89	RP-201512			Α	CR to TS 38.101-2 on corrections to operating bands for intra-band	16.5.0
						CA (Rel-16)	
2020-09	RAN#89	RP-201506	0235		F	Correction of ACS requiremet for n259	16.5.0
2020-09	RAN#89	RP-201496	0237	2	F	Introduction of FR2 inter-band DL CA	16.5.0
2020-09	RAN#89	RP-201512	0239		Α	CR for introduction of EESS protection for n257 into general	16.5.0
						spurious emission	
2020-09	RAN#89	RP-201512	0241		Α	CR to TS 38.101-2: Correction on the Aggregated Channel	16.5.0
						Bandwidth	
2020-09	RAN#89	RP-201512			Α	CR to TS 38.101-2: Correction on the PC3 MPR description	16.5.0
2020-09	RAN#89	RP-201512			Α	FR2 Minimum output power measurement period definition	16.5.0
2020-09	RAN#89	RP-201488	0249	2	F	CR to TS38.101-2 on ULFPTx and UE SRS port configuration	16.5.0
						clarification	
2020-09	RAN#89	RP-201496		1	F	CR to 38.101-2: DL CA BW Enhancement and CA REFSENS	16.5.0
2020-09	RAN#89	RP-201496		1	В	CR to 38.101-2: FR2 UE EIRP increase with IBE relaxation	16.5.0
2020-09	RAN#89	RP-201496		1	В	FR2 intra-band non-contiguous UL CA feature	16.5.0
2020-09	RAN#89	RP-201507			F	Correction of corrupted table	16.5.0
2020-12	RAN#90	RP-202485			Α	EESS protection related requirements for FR2 bands	16.6.0
2020-12	RAN#90	RP-202485			Α	CR to 38.101-2: ULCA clarifications	16.6.0
2020-12	RAN#90	RP-202485			Α	CR for TS38.101-2 Rel-16, Correction for definition of P-MPR	16.6.0
2020-12	RAN#90	RP-202443		1	F	REL16 eBC capability alingment with 38.306	16.6.0
2020-12	RAN#90	RP-202443		1	F	CR to 38.101-2 (Rel-16) inter-band DL CA	16.6.0
2020-12	RAN#90	RP-202443		1	F	Clarification of EIS spherical coverage for inter-band CA	16.6.0
2020-12	RAN#90	RP-202485			Α	Transmission gap for relative power tolerance in FR2	16.6.0
2020-12	RAN#90	RP-202485			Α	CR to TS38.101-2 on DC location correction	16.6.0
2020-12	RAN#90	RP-202485			Α	CR for TS 38.101-2: Clarification for NS_202	16.6.0
2020-12	RAN#90	RP-202509	0282	1	F	CR to TS 38.101-2 on fallback group for intra-band contiguous CA	16.6.0
						(Rel-16)	
2020-12	RAN#90	RP-202509		1	F	CR to TS 38.101-2 on simplification for inter-band CA configuration	16.6.0
2020-12	RAN#90	RP-202485			Α	Correction to Pcmax: total radiated power	16.6.0
2020-12	RAN#90				A	Correction to EIS definition	16.6.0
2020-12	RAN#90			1	F	CR for editorial corrections 38.101-2	16.6.0
2020-12	RAN#90	RP-202485			Α	Mirror CR for 38.101-2: IBB and ACS corrections	16.6.0
2020-12	RAN#90	RP-202485			Α	CR to DMRS position in UL RMC for FR2	16.6.0
2021-03	RAN#91	RP-210116			A	CR for 38.141-2: BS demodulation synchronization in test setup	16.7.0
2021-03	RAN#91	RP-210091	0318		F	CR to TS 38.101-2 on correction to intra-band non-contiguous CA	16.7.0
0004.00	DANUGA	DD 040000	0000		_	configurations (Rel-16)	4070
2021-03	RAN#91	RP-210083		1	F	P_cmax P_IBE wording refinement and terminology improvement	16.7.0
2021-03	RAN#91	RP-210117			F	CR to 38.101-2: correction on UL MIMO	16.7.0
2021-03	D 4 4		0000				16.7.0
2021-03 2021-03	RAN#91	RP-210117		_	A	CR to 38.101-2 on beam correspondence	
1 2021-03	RAN#91	RP-210117 RP-210191	0344	2	F	CR on FR2 inter-band DL CA CBM and IBM	16.7.0
	RAN#91 RAN#91	RP-210117 RP-210191 RP-210117	0344 0345	2	F A	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA	16.7.0
2021-06	RAN#91 RAN#91 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083	0344 0345 0352	2	F A A	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability	16.7.0 16.8.0
2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084	0344 0345 0352 0358	2	F A A	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables	16.7.0 16.8.0 16.8.0
2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104	0344 0345 0352 0358 0363		F A A A	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF	16.7.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117	0344 0345 0352 0358 0363 0365	2	F A A F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104	0344 0345 0352 0358 0363 0365		F A A A	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based	16.7.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117	0344 0345 0352 0358 0363 0365 0383	1	F A A F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16)	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117	0344 0345 0352 0358 0363 0365 0383		F A A F F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-211080 RP-211107	0344 0345 0352 0358 0363 0365 0383 0384 0386	1	F A A F F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-2111080 RP-211107 RP-211091	0344 0345 0352 0358 0363 0365 0383 0384 0386 0404	1	F A A A F F F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-211080 RP-211107 RP-211091	0344 0345 0352 0358 0363 0365 0383 0384 0386	1	F A A F F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-211080 RP-211107 RP-211091 RP-211091	0344 0345 0352 0358 0363 0365 0383 0384 0386 0404	1	F A A F F F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3 MPR	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06	RAN#91 RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#93	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-211107 RP-211091 RP-211091 RP-211091	0344 0345 0352 0358 0363 0365 0383 0384 0386 0404 0407	1	F A A F F A A F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3 MPR CR to 38.101-2 on handling of fallbacks for FR2 CA	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-09 2021-09	RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#93 RAN#93	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-211107 RP-211091 RP-211091 RP-211091 RP-211921 RP-211923	0344 0345 0352 0358 0363 0365 0383 0384 0386 0404 0407	1	F A A F A F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3 MPR CR to 38.101-2 on handling of fallbacks for FR2 CA Big CR for TS 38.101-2 Maintenance part1 (Rel-16)	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.9.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-09 2021-09 2021-09	RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#93 RAN#93 RAN#94	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211107 RP-211117 RP-211117 RP-211107 RP-211091 RP-211091 RP-211921 RP-211923 RP-212845	0344 0345 0352 0358 0363 0365 0383 0384 0386 0404 0407 0312 0422 0435	1	F A A F A F F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3 MPR CR to 38.101-2 on handling of fallbacks for FR2 CA Big CR for TS 38.101-2 Maintenance part1 (Rel-16) Big CR for TS 38.101-2 Maintenance (Rel-16)	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.9.0 16.9.0
2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-06 2021-09 2021-09	RAN#91 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#92 RAN#93 RAN#93	RP-210117 RP-210191 RP-210117 RP-211083 RP-211084 RP-211104 RP-211117 RP-211117 RP-211107 RP-211091 RP-211091 RP-211091 RP-211921 RP-211923	0344 0345 0352 0358 0363 0365 0383 0384 0386 0404 0407 0312 0422 0435	1	F A A F A F	CR on FR2 inter-band DL CA CBM and IBM CR on FR2 intra-band UL CA P_cmax fix for the CA applicability Update of FR2 UL RMC tables Removal of CA_n260(*) notation and IE fix R16 CATF Correction of the channel raster of n259 for TS 38.101-2 CR to 38.101-2 on side conditions for beam correspondence based on SSB and CSI-RS for n259 (Rel-16) CR for Rel-16 38.101-2 to correct some errors in Table 5.5A.2-2 CR to TS38.101-2: Some Corrections on for CA_n260-n261 CR to 38.101-2: CABW definition addition CR for 38.101-2-g70: Removing ambiguity on MPRnarrow for PC3 MPR CR to 38.101-2 on handling of fallbacks for FR2 CA Big CR for TS 38.101-2 Maintenance part1 (Rel-16)	16.7.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.8.0 16.9.0

2022-06	RAN#96	RP-221661	0465	F	CR for TS 38.101-2: update of simultaneous RxTx capability for band combinations	16.12.0
2022-06	RAN#96	RP-221655	0467	F	Big CR for TS 38.101-2 Maintenance (Rel-16)	16.12.0
2022-09	RAN#97	RP-222026	0495	F	Big CR for 38.101-2 maintenance (Rel-16)	16.13.0
2022-12	RAN#98-e	RP-223296	0507	F	CR R16 ModifiedMPR	16.14.0
2022-12	RAN#98-e	RP-223290	0509	Α	Annex G Clarifications on diagram related to measurement point for difference of relative phase/power error for UL coherent MIMO (Rel-16)	16.14.0
2022-12	RAN#98-e	RP-223290	0519	F	CR for Rel-16 38.101-2 to correct the side condition for SSB and CSI-RS based	16.14.0
2022-12	RAN#98-e	RP-223290	0520	F	CR for Rel-16 38.101-2 to correct the side condition for CSI-RS based	16.14.0
2022-12	RAN#98-e	RP-223296	0523	F	CR to 38.101-2 on removing ambiguity in CA MPR definition	16.14.0
2022-12	RAN#98-e	RP-223291	0527	F	Correction to DL RMC (Rel-16)	16.14.0
2023-03	RAN#99	RP-230501	0537	Α	Addition of FR2 UL MIMO EVM measurement description	16.15.0
2023-03	RAN#99	RP-230502	0551	Α	CR to F_loffset and F_Interferer (offset) adjustment in ACS and IBB	16.15.0
2023-03	RAN#99	RP-230502	0555	Α	CR on 'Annex G Difference of relative phase and power errors' for FR2 UL coherent MIMO	16.15.0
2023-03	RAN#99	RP-230502	0563	Α	On handheld UE and FWA UE definitions	16.15.0
2023-03	RAN#99	RP-230503	0580	F	CR for Rel-16 38.101-2 to correct the UL configuration for CA_n258C	16.15.0
2023-03	RAN#99	RP-230503	0589	Α	CR to TS 38.101-2 on humidity condition for normal temperature	16.15.0

History

	Document history							
V16.4.0	July 2020	Publication						
V16.5.0	November 2020	Publication						
V16.6.0	January 2021	Publication						
V16.7.0	April 2021	Publication						
V16.8.0	September 2021	Publication						
V16.9.0	October 2021	Publication						
V16.10.1	April 2022	Publication						
V16.11.0	April 2022	Publication						
V16.12.0	August 2022	Publication						
V16.13.0	October 2022	Publication						
V16.14.0	January 2023	Publication						
V16.15.0	April 2023	Publication						